# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

#### **General Description**

The MAX77654 provides highly-integrated battery charging and power supply solutions for low-power applications where size and efficiency are critical. The IC features a SIMO buck-boost regulator that provides three independently programmable power rails from a single inductor to minimize total solution size. Two 100mA LDOs provide ripple rejection for audio and other noise-sensitive applications. The LDOs can also be configured as load switches to manage power consumption by disconnecting external blocks when not required. A highly-configurable linear charger supports a wide range of Li+ battery capacities and includes battery temperature monitoring for additional safety (JEITA).

This device includes three GPIOs and an analog multiplexer that switches several internal voltage and current signals to an external node for monitoring with an external ADC. A bidirectional I<sup>2</sup>C serial interface allows for configuring and checking the status of the devices. An internal on/off controller provides a controlled startup sequence for the regulators and provides supervisory functionality while they are on. Numerous factory programmable options allow the device to be tailored for many applications, enabling faster time to market.

#### **Applications**

- Bluetooth Headphones, Hearables
- Wireless Speakers
- Fitness, Health, and Activity Monitors
- Wearables
- Safety and Security Monitors
- Sensor Nodes
- Portable Consumer Devices
- Internet of Things (IoT)

#### **Benefits and Features**

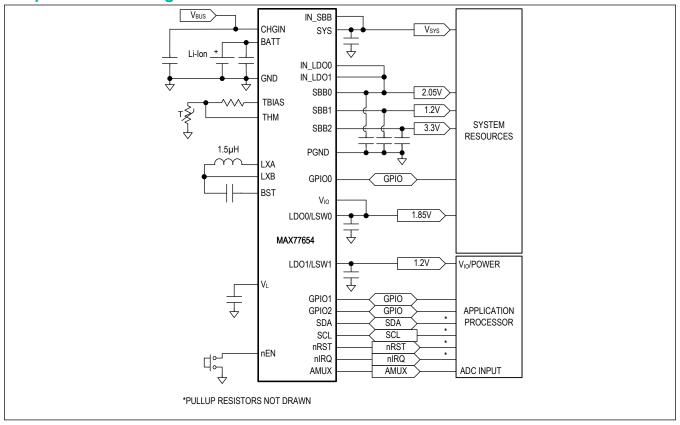
- Highly Integrated
  - 3x Output, Single-Inductor Multiple-Output (SIMO) Buck-Boost Regulator
    - Supports Wide Output Voltage Range from 0.8V to 5.5V for all SIMO Channels
  - 2x 100mA LDO/LSW
  - Smart Power Selector™ Li+/Li-Poly Charger
  - · 3x GPIO Resources
  - · Analog MUX Output for Power Monitoring
  - Factory Ship Mode (< 200nA I<sub>O</sub>)
  - Watchdog Timer
- Low Power
  - 0.3µA Shutdown Current
  - 6μA Operating Current (3 SIMO Channels + 2 LDOs)
- Charger Optimized for Small Battery Size
  - Programmable Fast-Charge Current from 7.5mA to 300mA
  - Programmable Battery Regulation Voltage from 3.6V to 4.6V
  - Programmable Termination Current from 0.375mA to 45mA
  - JEITA Battery Temperature Monitors Adjust Charge Current and Battery Regulation Voltage for Safe Charging
- Flexible and Configurable
  - I<sup>2</sup>C-Compatible Interface and GPIO
  - · Factory OTP Options Available
- Small Size
  - 6.52mm<sup>2</sup> Wafer-Level Package (WLP)
  - 30-Bump, 0.4mm Pitch, 6x5 Array

Ordering Information appears at end of data sheet.



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### **Simplified Block Diagram**



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#### **TABLE OF CONTENTS**

General Description	
Applications	1
Benefits and Features	1
Simplified Block Diagram	2
Absolute Maximum Ratings	9
Package Information	
Electrical Characteristics	10
Electrical Characteristics—Global Resources	10
Electrical Characteristics—Smart Power Selector Charger	13
Electrical Characteristics—Adjustable Thermistor Temperature Monitors	16
Electrical Characteristics—Analog Multiplexer	17
Electrical Characteristics—SIMO Buck-Boost	18
Electrical Characteristics—Low Dropout Linear Regulator (LDO)/Load Switch (LSW)	19
Electrical Characteristics—I <sup>2</sup> C Serial Communication	20
Typical Operating Characteristics	23
Pin Configurations	29
MAX77654xENV	29
MAX77654xENVN	30
Pin Description	30
Detailed Description	33
Part Number Decoding	33
Support Material	36
Top-Level Interconnect Simplified Diagram	36
Detailed Description—Global Resources	
Features and Benefits	
Voltage Monitors	38
SYS POR Comparator	
SYS Undervoltage-Lockout Comparator	38
SYS Overvoltage-Lockout Comparator	39
Chip Identification	39
nEN Enable Input	39
nEN Manual Reset	39
nEN Dual-Functionality: Push-Button vs. Slide-Switch	39
nEN Internal Pullup Resistors to V <sub>CCINT</sub>	40
Interrupts (nIRQ)	40
Reset Output (nRST)	41
General-Purpose Input Output (GPIO)	41
Alternate Mode	42

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### TABLE OF CONTENTS (CONTINUED)

171212 01 001111110 (00111111012)	
On/Off Controller	43
Top Level On/Off Controller	44
On/Off Controller Transition Table	44
Internal Wake-Up Flags	45
Reset and Off Sequences	46
Power-Up/Down Sequence	47
Flexible Power Sequencer (FPS)	48
Startup Timing Diagram Due to nEN	49
Startup Timing Diagram Due to Charge Source Insertion	50
Force Enabled/Disabled Channels	50
Factory-Ship Mode State	51
Debounced Inputs (nEN, GPI, CHGIN)	51
Watchdog Timer (WDT)	52
Detailed Description—Smart Power Selector Charger	53
Charger Symbol Reference Guide	53
Smart Power Selector	54
Input Current Limiter	54
Minimum Input Voltage Regulation	55
Minimum System Voltage Regulation	56
Die Temperature Regulation	56
Charger State Machine	57
Charger-Off State	58
Prequalification State	58
Fast-Charge States	58
Top-Off State	58
Done State	59
Prequalification Timer Fault State	59
Fast-Charge Timer Fault State	59
Battery Temperature Fault State	59
JEITA-Modified States	59
Typical Charge Profile	60
Charger Applications Information	60
Configuring a Valid System Voltage	60
CHGIN/SYS/BATT Capacitor Selection	60
Detailed Description—Adjustable Thermistor Temperature Monitors	61
Thermistor Bias	62
Configurable Temperature Thresholds	63
Applications Information	
Using Different Thermistor β	64

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### TABLE OF CONTENTS (CONTINUED)

NTC Thermistor Selection	65
Detailed Description—Analog Multiplexer	65
Measuring Battery Current	66
Method for Measuring Discharge Current	66
Method for Measuring Charge Current	67
Detailed Description—SIMO Buck-Boost	67
SIMO Features and Benefits	67
SIMO Detailed Block Diagram	68
SIMO Control Scheme	68
Drive Strength	69
SIMO Soft-Start	69
SIMO Registers	70
SIMO Active Discharge Resistance	70
SIMO Buck Mode	70
Applications Information	71
SIMO Available Output Current	71
Inductor Selection	71
Input Capacitor Selection	72
Boost Capacitor Selection	72
Output Capacitor Selection	72
Example Component Selection	73
Inductor, Peak Current Limit, and Input Capacitor	73
Output Capacitors	74
Summary	75
SIMO Switching Frequency	76
Unused Outputs	76
PCB Layout Guide	77
Capacitors	77
Input Capacitor at IN_SBB	77
Output Capacitors at SBBx	77
Inductor	77
Ground Connections	77
Example PCB Layout	78
Detailed Description—Low Dropout Linear Regulator (LDO)/Load Switch (LSW)	
Features and Benefits	
LDO/LSW Simplified Block Diagram	79
LDO/LSW Active-Discharge Resistor	79
LDO/LSW Soft-Start	80
Load Switch Configuration	80

### TABLE OF CONTENTS (CONTINUED)

· · · · · · · · · · · · · · · · · · ·	
Applications Information	81
Input Capacitor Selection	81
Output Capacitor Selection	81
Detailed Description—I <sup>2</sup> C Serial Communication	82
General Description	82
Features	82
I <sup>2</sup> C Simplified Block Diagram	82
I <sup>2</sup> C System Configuration	83
I <sup>2</sup> C Interface Power	84
I <sup>2</sup> C Data Transfer	84
I <sup>2</sup> C Start and Stop Conditions	84
I <sup>2</sup> C Acknowledge Bit	84
I <sup>2</sup> C Slave Address	85
I <sup>2</sup> C Clock Stretching	85
I <sup>2</sup> C General Call Address	86
I <sup>2</sup> C Device ID	86
I <sup>2</sup> C Communication Speed	86
I <sup>2</sup> C Communication Protocols	87
Writing to a Single Register	87
Writing Multiple Bytes to Sequential Registers	88
Reading from a Single Register	90
Reading from Sequential Registers	91
Engaging HS-Mode for Operation up to 3.4MHz	92
Register Map	93
MAX77654	93
Register Details	94
Typical Application Circuits	117
Typical Applications Circuit	117
Ordering Information	118
Revision History	119

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

#### LIST OF FIGURES

Figure 1. Part Number Decode	33
Figure 2. Top-Level Interconnect Simplified Diagram	37
Figure 3. nEN Usage Timing Diagram	39
Figure 4. nEN Pullup Resistor Configuration	40
Figure 5. GPIOx Block Diagram	42
Figure 6. Top Level On/Off Controller State Diagram	44
Figure 7. On/Off Controller Reset and Off-Action Sequences	46
Figure 8. Power-Up/Down Sequence	47
Figure 9. Flexible Power Sequencer Basic Timing Diagram	48
Figure 10. Startup Timing Diagram Due to nEN	49
Figure 11. Startup Timing Diagram Due to Charge Source Insertion	50
Figure 12. Debounced Inputs	51
Figure 13. Watchdog Timer State Machine	52
Figure 14. Charger Simplified Control Loops	54
Figure 15. Charger State Diagram	57
Figure 16. Example Battery Charge Profile	60
Figure 17. Safe-Charging Profile Example	62
Figure 18. Thermistor Bias State Diagram	63
Figure 19. Thermistor Circuit with Adjusting Series and Parallel Resistors	64
Figure 20. SIMO Detailed Block Diagram	68
Figure 21. Component Selection—High Utilization	73
Figure 22. Component Selection—Final Current Peak Limits	74
Figure 23. Component Selection—Expected Ripple	75
Figure 24. PCB Top-Layer and Component Placement Example	78
Figure 25. LDO Simplified Block Diagram	79
Figure 26. LDO to LSW Transition Waveform	80
Figure 27. I <sup>2</sup> C Simplified Block Diagram	83
Figure 28. I <sup>2</sup> C System Configuration	83
Figure 29. I <sup>2</sup> C Start and Stop Conditions	84
Figure 30. Acknowledge Bit	85
Figure 31. Slave Address Example	85
Figure 32. Writing to a Single Register with the Write Byte Protocol	87
Figure 33. Writing to Sequential Registers X to N	89
Figure 34. Reading from a Single Register with the Read Byte Protocol	90
Figure 35. Reading Continuously from Sequential Registers X to N	91
Figure 36. Engaging HS Mode	92

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

#### **LIST OF TABLES**

Table 1. Regulator Summary	33
Table 2. Variants Table	34
Table 3. OTP Options Table	34
Table 4. GPIO Mode	42
Table 5. Enabling/Disabling SBB2 while GPIO1 is in Alternate Mode	42
Table 6. On/Off Controller Transition/State	44
Table 7. Watchdog Timer Factory-Programmed Safety Options	52
Table 8. Charger Quick Symbol Reference Guide	53
Table 9. Input Current Limit Factory Options	55
Table 10. Trip Temperatures vs. Trip Voltages for Different NTC β	63
Table 11. Example R <sub>S</sub> and R <sub>P</sub> Correcting Values for NTC β Above 3380K	64
Table 12. NTC Thermistors	65
Table 13. AMUX Signal Transfer Functions	65
Table 14. Battery Current Direction Decode	
Table 15. SIMO Available Output Current for Common Applications	71
Table 16. Design Requirements	73
Table 17. Summary of Design for Component Selection Example	
Table 18. Summary of Design with Lower Input Voltage	
Table 19. Switching Frequency Control	
Table 20. I <sup>2</sup> C Slave Address Options	

#### **Absolute Maximum Ratings**

nIRQ, nRST to GND0.3V to V <sub>SYS</sub> + 0.3V	IN_SBB to PGND0.3V to +6.0V
nEN to GND ( <i>Note 1</i> )0.3V to V <sub>CCINT</sub> + 0.3V	LXA Continuous Current (Note 3)
SCL, SDA, GPIO to GND0.3V to V <sub>IO</sub> + 0.3V	LXB Continuous Current (Note 3)
CHGIN to GND0.3V to +30.0V	SBB0, SBB1, SBB2 to PGND0.3V to +6.0V
SYS, BATT to GND0.3V to +6.0V	BST to IN_SBB0.3V to +6.0V
SYS to IN_SBB0.3V to +0.3V	BST to LXB0.3V to +6.0V
VL to GND0.3V to +6.0V	SBB0, SBB1, SBB2 Short-Circuit DurationContinuous
AMUX, THM, TBIAS to GND	PGND to GND0.3V to +0.3V
nIRQ, nRST, SDA, AMUX, GPIO Continous Current ±20mA	Operating Temperature Range40°C to +85°C
CHGIN Continuous Current1.2A <sub>RMS</sub>	Junction Temperature+150°C
SYS Continuous Current	Storage Temperature Range65°C to +150°C
BATT Continuous Current ( <u>Note 2</u> )1.2A <sub>RMS</sub>	Soldering Temperature (reflow)+260°C
LDO0, LDO1 to GND0.3V to V <sub>IN LDO</sub> + 0.3V	Continuous Power Dissipation (Multilayer Board, $T_A = +70$ °C,
IN_LDO0, IN_LDO1, $V_{IO}$ to GND0.3V to $\overline{V}_{SYS}$ + 0.3V	derate 20.4mW/°C above +70°C)1632mW

- Note 1:  $V_{CCINT}$  is internally connected to either BATT or  $V_L$ . See the <u>nEN Internal Pullup Resistors to  $V_{CCINT}$  section for more details.</u>
- Note 2: Do not repeatedly hot-plug a source to the BATT terminal at a rate greater than 10Hz. Hot plugging low impedance sources results in an ~8A momentary (~2µs) current spike.
- Note 3: Do not externally bias LXA or LXB. LXA has internal clamping diodes to PGND and IN\_SBB. LXB has an internal low-side clamping diode to PGND and an internal high-side clamping diode that dynamically connects to a selected SIMO output. It is normal for these diodes to briefly conduct during switching events. When the SIMO regulator is disabled, the LXB to PGND absolute maximum voltage is -0.3V to V<sub>SBB0</sub> + 0.3V.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **Package Information**

#### **WLP**

Package Code	N302C2+1
Outline Number	<u>21-100307</u>
Land Pattern Number	Refer to Application Note 1891
Thermal Resistance, Four-Layer Board:	
Junction to Ambient (θ <sub>JA</sub> )	49°C/W (2s2p board)

For the latest package outline information and land patterns (footprints), go to <a href="https://www.maximintegrated.com/packages">www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <a href="https://www.maximintegrated.com/thermal-tutorial">www.maximintegrated.com/thermal-tutorial</a>.

#### **Electrical Characteristics**

 $(V_{CHGIN} = 0V, V_{SYS} = V_{BATT} = V_{IN\_SBB} = V_{IN\_LDO_X} = 3.7V, V_{IO} = 1.8V$ , limits are 100% production tested at  $T_A = +25^{\circ}C$ . Limits over the operating temperature range  $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C)$  are guaranteed by design and characterization, unless otherwise noted.)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
Operating Voltage Range	V <sub>SYS</sub>			2.7		5.5	V
					0.3	1	
Shutdown Supply Current ISHDN	Current measured into BATT and SYS and IN_SBB and IN_LDOx, all resources are off (LDO0, LDO1, SBB0, SBB1, SBB2), T <sub>A</sub> = +25°C	Main bias is on in low-power mode (CNFG_GLBL. SBIA_EN = 1, CNFG_GLBL. SBIA_LPM = 1)		1		μΑ	
		Main bias is on in normal-power mode (CNFG_GLBL. SBIA_EN = 1, CNFG_GLBL. SBIA_LPM = 0)		28			
Main Bias Quiescent Current	IQ	Main bias is in normal-power mode (CNFG_GLBL.SBIA_LPM = 0)			28		μA
Quiescent Supply Current	IQ	Current measured into BATT and SYS and IN_SBB and IN_LDOx; LDO0, LDO1, SBB0, SBB1, SBB2 are enabled with no load watchdog timer disabled	Main bias is in low- power mode (CNFG_GLBL. SBIA_LPM = 1)		6	13	μА
BATT Factory-Ship Mode Current	I <sub>BATT-FSM</sub>	Factory-ship mode (I open), T <sub>A</sub> = +25°C, V = V <sub>INLDO0</sub> = V <sub>INLDO</sub>	$V_{BATT}$ = 3.7V, $V_{SYS}$		0.2	1	μА

#### **Electrical Characteristics—Global Resources**

 $(V_{SYS} = 3.7V)$ , limits are 100% production tested at  $T_A = +25$ °C, limits over the operating temperature range  $(T_A = -40$ °C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
GENERAL CHARACTER	ISTICS						
Main Bias Enable Time	tsbias_en			0.5		ms	
VOLTAGE MONITORS /	VOLTAGE MONITORS / POWER-ON RESET (POR)						
POR Threshold	V <sub>POR</sub>	V <sub>SYS</sub> falling	1.6	1.9	2.1	V	
POR Threshold Hysteresis				100		mV	

#### **Electrical Characteristics—Global Resources (continued)**

 $(V_{SYS} = 3.7V, limits are 100\% production tested at T_A = +25^{\circ}C, limits over the operating temperature range (T_A = -40^{\circ}C to +85^{\circ}C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
VOLTAGE MONITORS /	UNDERVOLTAG	E LOCKOUT (UVLO)					
LIV/I O Throubold		V <sub>SYS</sub> falling, UVLO_	F[3:0] = 0xA (Note 5)	2.5	2.6	2.7	
UVLO Threshold	V <sub>SYSUVLO</sub>	V <sub>SYS</sub> falling, UVLO_	F[3:0] = 0xF ( <u>Note 5</u> )	2.75	2.85	2.95	V
UVLO Threshold Hysteresis	V <sub>SYSUVLO_HY</sub> S	UVLO_H[3:0] = 0x5		300		mV	
<b>VOLTAGE MONITORS /</b>	OVERVOLTAGE	LOCKOUT (OVLO)					
OVLO Threshold	V <sub>SYSOVLO</sub>	V <sub>SYS</sub> rising		5.70	5.85	6.00	V
THERMAL MONITORS							
Overtemperature- Lockout Threshold	T <sub>OTLO</sub>	T <sub>J</sub> rising			165		°C
Thermal Alarm Temperature 1	T <sub>JAL1</sub>	T <sub>J</sub> rising			80		°C
Thermal Alarm Temperature 2	T <sub>JAL2</sub>	T <sub>J</sub> rising			100		°C
Thermal Alarm Temperature Hysteresis					15		°C
ENABLE INPUT (nEN)							
nEN Input Leakage	1 511 1110	V <sub>nEN</sub> = V <sub>SYS</sub> =	T <sub>A</sub> = +25°C	-1	±0.001	+1	μА
Current	I <sub>nEN_LKG</sub>	5.5V	T <sub>A</sub> = +85°C		±0.01		
nEN Input Falling Threshold	V <sub>TH_nEN_</sub> F	nEN Falling		V <sub>CCINT</sub> - 1.4	V <sub>CCINT</sub> - 1.0		V
nEN Input Rising Threshold	V <sub>TH_nEN_R</sub>	nEN Rising			V <sub>CCINT</sub> - 0.9	V <sub>CCINT</sub> - 0.6	V
			V <sub>CHGIN</sub> = 0V, battery is present (V <sub>BATT</sub> is valid)		V <sub>BATT</sub>		
V <sub>CC</sub> Internal	VCCINT	( <u>Note 4</u> )	V <sub>CHGIN</sub> = 5V, not suspended (CNFG_CHG_G.U SBS = 0)		$V_{L}$		V
Dohounoo Timo	4	CNFG_GLBL.DBEN	_nEN = 0		500		μs
Debounce Time	<sup>t</sup> DBNC_nEN	CNFG_GLBL.DBEN	_nEN = 1		30		ms
Manual Reset Time	4	CNFG_GLBL.T_MR	T = 1	14	16	20	
ivianuai Reset Hime	t <sub>MRST</sub>	CNFG_GLBL.T_MR	T = 0	7	8	10.5	S
nEN Internal Pullus	D	Pullup to V <sub>CCINT</sub>	PU_DIS = 0		200		kΩ
nEN Internal Pullup	R <sub>nEN-PU</sub>	Laugh to ACCINT	PU_DIS = 1		10000		
OPEN-DRAIN INTERRU	PT OUTPUT (nIR	Q)					
Output Voltage Low	V <sub>OL</sub>	I <sub>SINK</sub> = 2mA				0.4	V
Output Falling Edge Time	t <sub>f_nIRQ</sub>	C <sub>IRQ</sub> = 25pF			2		ns

#### **Electrical Characteristics—Global Resources (continued)**

 $(V_{SYS} = 3.7V, limits are 100\% production tested at T_A = +25^{\circ}C, limits over the operating temperature range (T_A = -40^{\circ}C to +85^{\circ}C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
		$V_{SYS} = V_{IO} = 5.5V$	T <sub>A</sub> = +25°C	-1	±0.001	+1	
Leakage Current	l <sub>nIRQ_LKG</sub>	nIRQ is high impedance (no interrupts)  V <sub>nIRQ</sub> = 0V and 5.5V  VIRQ = 0V and 5.5V		±0.01		μΑ	
OPEN-DRAIN RESET OU	ITPUT (nRST)		•	•			
Output Voltage Low	V <sub>OL</sub>	I <sub>SINK</sub> = 2mA				0.4	V
Output Falling Edge Time	t <sub>f_nRST</sub>	C <sub>RST</sub> = 25pF			2		ns
nRST Deassert Delay Time	<sup>t</sup> RSTODD	See Figure 10 and Finformation	igure 11 for more		5.12		ms
nRST Assert Delay Time	<sup>t</sup> RSTOAD				10.24		ms
		$V_{SYS} = V_{IO} = 5.5V$	T <sub>A</sub> = +25°C	-1	±0.001	+1	
Leakage Current	I <sub>nRST_LKG</sub>	nRST is high impedance (no reset) V <sub>nRST</sub> = 0V and 5.5V	T <sub>A</sub> = +85°C		±0.01		μΑ
GENERAL PURPOSE INI	PUT/OUTPUT (G	SPIO)		•			
Input Voltage Low	V <sub>IL</sub>	V <sub>IO</sub> = 1.8V				0.3 x V <sub>IO</sub>	V
Input Voltage High	$V_{IH}$	V <sub>IO</sub> = 1.8V		0.7 x V <sub>IO</sub>			V
Input Leakage Current	<sup>l</sup> gpi_lkg	CNFG_GPIOx.DIR = 1 V <sub>IO</sub> = 5.5V V <sub>GPIO</sub> = 0V and 5.5V	T <sub>A</sub> = +25°C	-1	±0.001	+1	μΑ
Output Voltage Low	V <sub>OL</sub>	I <sub>SINK</sub> = 2mA	1			0.4	V
Output Voltage High	V <sub>OH</sub>	I <sub>SOURCE</sub> = 1mA		0.8 x V <sub>IO</sub>			V
Input Debounce Time	t <sub>DBNC_GPI</sub>	CNFG_GPIOx.DBEN	N_GPI = 1		30		ms
Output Falling Edge Time	t <sub>f_</sub> GPIO	C <sub>GPIO</sub> = 25pF			3		ns
Output Rising Edge Time	t <sub>r_</sub> GPIO	C <sub>GPIO</sub> = 25pF			3		ns
FLEXIBLE POWER SEQU	JENCER			·			
FPS Startup Delay	t <sub>FPS_DLY</sub>				1.43		ms
Power-Up Event Periods	t <sub>EN</sub>	See <u>Figure 9</u>			1.28		ms
Power-Down Event Periods	t <sub>DIS</sub>	See Figure 9			2.56		ms

Note 4: See the  $\underline{nEN\ Internal\ Pullup\ Resistors\ to\ V_{CCINT}}$  section for more details.

Note 5: Programmed at Maxim's factory.

#### **Electrical Characteristics—Smart Power Selector Charger**

 $(V_{CHGIN} = 5.0V, V_{SYS} = 4.5V, V_{BATT} = 4.2V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DC INPUT						•
CHGIN Valid Voltage Range	V <sub>CHGIN</sub>	Initial CHGIN voltage before enabling charging	4.10		7.25	V
CHGIN Standoff Voltage Range	V <sub>STANDOFF</sub>	DC rising		28		V
CHGIN Overvoltage Threshold	V <sub>CHGIN_OVP</sub>	DC rising	7.25	7.50	7.75	V
CHGIN Overvoltage Hysteresis				100		mV
CHGIN Undervoltage Lockout	V <sub>CHGIN_UVLO</sub>	DC rising	3.9	4.0	4.1	V
CHGIN Undervoltage- Lockout Hysteresis				500		mV
Input Current-Limit Range	I <sub>CHGIN-LIM</sub>	V <sub>SYS</sub> = V <sub>SYS-REG</sub> - 100mV, programmable in 95mA steps	95		475	mA
Input Current-Limit		I <sub>CHGIN-LIM</sub> = 95mA, V <sub>SYS</sub> = V <sub>SYS-REG</sub> - 100mV	90	95	100	m A
Accuracy		I <sub>CHGIN-LIM</sub> = 475mA, V <sub>SYS</sub> = V <sub>SYS-REG</sub> - 100mV		475	500	- mA
Minimum Input Voltage Regulation Range	V <sub>CHGIN-MIN</sub>	V <sub>CHGIN</sub> falling due to loading conditions and/or high-impedance charge source, programmable in 100mV increments with CNFG_CHG_B.VCHGIN_MIN[2:0]	4.0		4.7	V
Minimum Input Voltage Regulation Accuracy		V <sub>CHGIN-MIN</sub> = 4.5V (CNFG_CHG_B.VCHGIN_MIN[2:0] = 0b101), I <sub>CHGIN</sub> reduced by 10%	4.32	4.50	4.68	V
Charger Input Debounce Timer	<sup>t</sup> CHGIN-DB	V <sub>CHGIN</sub> = 5V, time before CHGIN is allowed to deliver current to SYS or BATT	100	120	140	ms
SUPPLY AND QUIESCE	NT CURRENTS					_
CHGIN Supply Current	I <sub>CHGIN</sub>	V <sub>CHGIN</sub> = 5V, charger is not in USB suspend (CNFG_CHG_G.USBS = 0), charging is finished (STAT_CHG_B.CHG_DTLS[3:0] indicates done), I <sub>SYS</sub> = 0mA		1.0	1.8	mA
		$V_{CHGIN}$ = 0V to 1V, $V_{BATT}$ = 3.3V, $I_{SYS}$ = 0mA			50	μA
CHGIN Suspend Supply Current	I <sub>CHGIN-SUS</sub>	V <sub>CHGIN</sub> = 5V, charger in USB suspend (CNFG_CHG_G.USBS = 1)			50	μA
BATT Bias Current	I <sub>BATT-BIAS</sub>	V <sub>CHGIN</sub> = 5V, charger is not in USB suspend (CNFG_CHG_G.USBS = 0), charging is finished (STAT_CHG_B.CHG_DTLS[3:0] indicates done), I <sub>SYS</sub> = 0mA		5		μА
PREQUALIFICATION						
Charge Current Soft- Start Slew Time		Zero to full-scale		1		ms

#### **Electrical Characteristics—Smart Power Selector Charger (continued)**

 $(V_{CHGIN} = 5.0V, V_{SYS} = 4.5V, V_{BATT} = 4.2V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
Prequalification Voltage Threshold Range	V <sub>PQ</sub>	Programmable in 10 CNFG_CHG_C.CHC		2.3		3.0	V
Prequalification Voltage Threshold Accuracy		V <sub>PQ</sub> = 3.0V		-3		+3	%
Prequalification Mode		$V_{BATT} = 2.5V$ $V_{PQ} = 3.0V$	CNFG_CHG_B.I_P Q = 0		10		
Charge Current	I <sub>PQ</sub>	Expressed as a percentage of FAST-CHG	CNFG_CHG_B.I_P Q = 1		20		%
Prequalification Safety Timer	t <sub>PQ</sub>	$V_{BATT} < V_{PQ} = 3.0V$		27	30	33	minutes
FAST-CHARGE							
Fast-Charge Voltage Range	V <sub>FAST-CHG</sub>		I <sub>BATT</sub> = 0mA, programmable in 25mV steps with CNFG_CHG_G.CHG_CV[5:0]			4.6	V
Fast-Charge Voltage	st-Charge Voltage		V <sub>FAST-CHG</sub> = 4.3V, V <sub>SYS</sub> = 4.5V, T <sub>A</sub> = +25°C	-0.5		+0.5	- %
Accuracy		I <sub>BATT</sub> = 0mA	V <sub>FAST-CHG</sub> = 3.6V to 4.6V, V <sub>SYS</sub> = 4.8V			1.0	70
Fast-Charge Current Range	I <sub>FAST-CHG</sub>		Programmable in 7.5mA steps with CNFG_CHG_E.CHG_CC[5:0]			300	mA
Fast-Charge Current		T <sub>A</sub> = +25°C, V <sub>BATT</sub>	I <sub>FAST-CHG</sub> = 15mA	-1.5		+1.5	
Accuracy		= V <sub>FAST-CHG</sub> - 300mV	I <sub>FAST-CHG</sub> = 300mA	-2.0		+2.0	%
Fast-Charge Current Accuracy over Temperature		Across all current se VFAST-CHG - 300mV +85°C		-10		+10	%
Fast-Charge Safety Timer Range	t <sub>FC</sub>	Programmable in 2 h disabled with CNFG_CHG_E.T_F measured from preq fault	AST_CHG[1:0], time	3		7	hours
Fast-Charge Safety Timer Accuracy		t <sub>FC</sub> = 3 hours		-10		+10	%
Fast-Charge Safety Timer Suspend Threshold		Fast-charge CC mode, fast-charge safety timer paused when charge current drops below this threshold, expressed as a percentage of I <sub>FAST-CHG</sub>			20		%
Junction Temperature Regulation Setting Range	T <sub>J-REG</sub>	Programmable in 10 CNFG_CHG_D.TJ_I		60		100	°C
Junction Temperature Regulation Loop Gain	G <sub>TJ-REG</sub>	Rate at which I <sub>FAST</sub> to maintain T <sub>J-REG</sub> , percentage of I <sub>FAST</sub> centigrade rise			-5.4		%/°C

#### **Electrical Characteristics—Smart Power Selector Charger (continued)**

 $(V_{CHGIN} = 5.0V, V_{SYS} = 4.5V, V_{BATT} = 4.2V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS	
TERMINATION AND TOP	P-OFF		,				'	
		CNFG_CHG_C.I_TE expressed as a perc	ERM[1:0] = 0b00 entage of I <sub>FAST-CHG</sub>		5			
End-of-Charge	<b>I</b>	CNFG_CHG_C.I_TE expressed as a perc	ERM[1:0] = 0b01 entage of I <sub>FAST-CHG</sub>		7.5		%	
Termination Current	ITERM	CNFG_CHG_C.I_TE expressed as a perc	ERM[1:0] = 0b10 entage of I <sub>FAST-CHG</sub>	8.5	10	11.5		
		CNFG_CHG_C.I_TE expressed as a perc	RM[1:0] = 0b11 entage of I <sub>FAST-CHG</sub>		15			
Top-Off Timer Range	t <sub>TO</sub>	I <sub>BATT</sub> < I <sub>TERM</sub> , prog minute steps with CNFG_CHG_C.T_T	0		35	minutes		
Top-Off Timer Accuracy		t <sub>TO</sub> = 10 minutes		-10		+10	%	
Charge Restart Threshold	V <sub>RESTART</sub>	Charging is finished (STAT_CHG_B.CHG indicates done) Charging resumes w CHG - VRESTART	S_DTLS[3:0] then V <sub>BATT</sub> < V <sub>FAST</sub>	65	150		mV	
End-of-Charge Termination Current Accuracy		I <sub>FAST-CHG</sub> = 15mA, of I <sub>FAST-CHG</sub> ), T <sub>A</sub> =	I <sub>TERM</sub> = 1.5mA (10% +25°C	1.35	1.5	1.65	- mA	
		I <sub>FAST-CHG</sub> = 300mA (10% of I <sub>FAST-CHG</sub> ),	, I <sub>TERM</sub> = 30mA T <sub>A</sub> = +25°C	27	30	33	IIIA	
End-of-Charge Termination Current Glitch Filter					60		μs	
DEVICE ON-RESISTANC	E AND LEAKA	GE						
BATT to SYS On- Resistance		V <sub>BATT</sub> = 3.7V, I <sub>BATT</sub> 0V, battery is discha	= 300mA, V <sub>CHGIN</sub> = rging to SYS		100	150	mΩ	
Charger FET Leakage		$V_{SYS} = 4.5V$ ,	T <sub>A</sub> = +25°C		0.1	1.0		
Current		V <sub>BATT</sub> = 0V, charger disabled	T <sub>A</sub> = +85°C		1		μΑ	
CHGIN to SYS On- Resistance		V <sub>CHGIN</sub> = 4.65V, I <sub>Ch</sub>	<sub>IGIN</sub> = 400mA		600		mΩ	
		V <sub>CHGIN</sub> = 0V,	T <sub>A</sub> = +25°C		0.1	1.0		
Input FET Leakage Current		V <sub>SYS</sub> = 4.2V, body- switched diode reverse biased	T <sub>A</sub> = +85°C		1		μA	
SYSTEM NODE		•					•	
System Voltage Regulation Range	V <sub>SYS-REG</sub>	Programmable in 25 CNFG_CHG_D.VSY		4.1		4.8	V	
System Voltage	$T_{A} = +25^{\circ}C$	T <sub>A</sub> = +25°C	4.41	4.50	4.59			
System Voltage Regulation Accuracy	V <sub>SYS</sub>	$V_{SYS-REG} = 4.5V$ , $I_{SYS} = 1mA$	T <sub>A</sub> = -40°C to +85°C	4.365	4.5	4.635	V	

#### **Electrical Characteristics—Smart Power Selector Charger (continued)**

 $(V_{CHGIN} = 5.0V, V_{SYS} = 4.5V, V_{BATT} = 4.2V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Minimum System Voltage Regulation Loop Setpoint	Vsys-min	VCHGIN = 5V, VSYS-REG = 4.5V, VSYS < VSYS-REG due to ICHGIN = ICHGIN-LIM (input in current limit), battery charging, IBATT reduced to 50% of IFAST-CHG (minimum system voltage regulation active)	4.34	4.4	4.45	V
Supplement Mode System Voltage Regulation		I <sub>SYS</sub> = 150mA		V <sub>BATT</sub> - 0.15V		V

#### **Electrical Characteristics—Adjustable Thermistor Temperature Monitors**

 $(V_{CHGIN} = 5.0V, V_{SYS} = 4.5V, V_{BATT} = 4.2V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
JEITA TEMPERATURE	MONITORS		1			
TBIAS Voltage	V <sub>TBIAS</sub>	CNFG_CHG_F.THM_EN = 1, V <sub>CHGIN</sub> = 5V		1.25		V
JEITA Cold Threshold Range	V <sub>COLD</sub>	Voltage rising threshold, programmable with CNFG_CHG_A.THM_COLD[1:0] in 5°C increments when using an NTC $\beta$ = 3380K	0.867		1.024	V
JEITA Cool Threshold Range	VcooL	Voltage rising threshold, programmable with CNFG_CHG_A.THM_COOL[1:0] in 5°C increments when using an NTC $\beta$ = 3380K	0.747		0.923	V
JEITA Warm Threshold Range	Vwarm	Voltage falling threshold, programmable with CNFG_CHG_A.THM_WARM[1:0] in 5°C increments when using an NTC $\beta$ = 3380K	0.367		0.511	V
JEITA Hot Threshold Range	V <sub>HOT</sub>	Voltage falling threshold, programmable with CNFG_CHG_A.THM_HOT[1:0] in 5°C increments when using an NTC $\beta$ = 3380K	0.291		0.411	V
Temperature Threshold Accuracy		Voltage threshold accuracy expressed as temperature for an NTC β = 3380K		±3		°C
Temperature Threshold Hysteresis		Temperature hysteresis set on each voltage threshold for an NTC $\beta$ = 3380K		3		°C
JEITA Modified Fast- Charge Voltage Range	V <sub>FAST</sub> - CHG_JEITA	I <sub>BATT</sub> = 0mA, programmable in 25mV steps, battery is either cool or warm	3.6		4.6	V
JEITA Modified Fast- Charge Current Range	I <sub>FAST</sub> - CHG_JEITA	Programmable in 7.5mA steps, battery is either cool or warm	7.5		300	mA

### **Electrical Characteristics—Analog Multiplexer**

 $(V_{CHGIN} = 5.0V, V_{SYS} = 4.5V, V_{BATT} = 4.2V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONI	DITIONS	MIN	TYP	MAX	UNITS	
ANALOG MULTIPLEXER	<u> </u>							
Full-Scale Voltage	V <sub>FS</sub>				1.25		V	
Channel Switching Time					0.3		μs	
		V <sub>AMUX</sub> = 0V,	T <sub>A</sub> = +25°C		1	500	nA	
Off Leakage Current		AMUX is high impedance	T <sub>A</sub> = +85°C		1		μA	
CHGIN POWER MEASUR	REMENT							
CHGIN Current Monitor Gain	G <sub>ICHGIN</sub>	V <sub>FS</sub> corresponds to setting	maximum I <sub>CHGIN-LIM</sub>		2.632		V/A	
CHGIN Voltage Monitor Gain	G <sub>VCHGIN</sub>	V <sub>FS</sub> corresponds to	V <sub>FS</sub> corresponds to V <sub>CHGIN_OVP</sub>				V/V	
BATT AND SYS POWER	MEASUREMEN	T						
Battery Charge Current Monitor Gain	G <sub>IBATT-CHG</sub>	V <sub>FS</sub> corresponds to setting (CNFG_CH0	100% of I <sub>FAST-CHG</sub> G_E.CHG_CC[5:0])		12.5		mV/%	
Charge Current Monitor		I <sub>FAST-CHG</sub> = 15mA = V <sub>FAST-CHG</sub> - 300	, T <sub>A</sub> = +25°C, V <sub>BATT</sub> mV	-3.5		+3.5	- %	
Accuracy		I <sub>FAST-CHG</sub> = 300m/ = V <sub>FAST-CHG</sub> - 300	A, T <sub>A</sub> = +25°C, V <sub>BATT</sub> mV	-3.5		+3.5	/0	
Charge Current Monitor Accuracy over Temperature			Across all current settings, V <sub>BATT</sub> = V <sub>FAST-CHG</sub> - 300mV			+10	%	
Battery Discharge Monitor Full-Scale Current Range	I <sub>DISCHG</sub> - SCALE	Programmable with CNFG_CHG_I.IMO SCALE[3:0]		8.2		300	mA	
Battery Discharge Current Monitor Accuracy		15mA to 300mA bar current, I <sub>DISCHG-SC</sub>		-15		+15	%	
Battery Discharge Current Monitor Offset		I <sub>BATT</sub> = 0mA		-0.5		+0.8	mA	
Battery-Voltage Monitor Gain	G <sub>VBATT</sub>	V <sub>FS</sub> corresponds to CHG setting	maximum V <sub>FAST</sub> -		0.272		V/V	
SYS Voltage Monitor Gain	G <sub>VSYS</sub>	V <sub>FS</sub> corresponds to maximum V <sub>SYS-REG</sub> setting			0.26		V/V	
THM AND TBIAS VOLTA	GE MEASUREN	IENT						
THM Voltage Monitor Gain	G <sub>VTHM</sub>				1		V/V	
TBIAS Voltage Monitor Gain	G <sub>VTBIAS</sub>				1		V/V	

#### **Electrical Characteristics—SIMO Buck-Boost**

 $(V_{SYS} = 3.7V, V_{IN\_SBB} = 3.7V, C_{SBBx} = 10\mu F, L = 1.5\mu H$ , limits are 100% production tested at  $T_A = +25^{\circ}C$ , limits over the operating temperature range  $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C)$  are guaranteed by design and characterization, unless otherwise noted.)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
GENERAL CHARACTER	RISTICS / OUTPL	T VOLTAGE RANGE	(SBB0)	•			
Programmable Output Voltage Range				0.8		5.5	V
Output DAC Bits					7		bits
Output DAC LSB Size					50		mV
GENERAL CHARACTER	RISTICS / OUTPL	T VOLTAGE RANGE	(SBB1)	•			
Programmable Output Voltage Range				0.8		5.5	V
Output DAC Bits					7		bits
Output DAC LSB Size					50		mV
GENERAL CHARACTER	RISTICS / OUTPL	IT VOLTAGE RANGE	(SBB2)				
Programmable Output Voltage Range				0.8		5.5	V
Output DAC Bits					7		bits
Output DAC LSB Size					50		mV
OUTPUT VOLTAGE ACC	CURACY						
Output Voltage Accuracy		V <sub>SBBx</sub> falling, threshold where LXA switches high; specified as a percentage of target output	T <sub>A</sub> = +25°C  T <sub>A</sub> = -40°C to +85°C	-3.0 -4.55		+3.0	%
TIMING CHARACTERIS	TICS	voltage					
Enable Delay		Delay time from the signal to switch in order to ser	when it begins to		60		μs
Soft-Start Slew Rate	dV/dt <sub>SS</sub>			3.3	5.0	6.6	mV/μs
POWER STAGE CHARA	CTERISTICS						
LXA Leakage Current		SBB0, SBB1, SBB2 are disabled,	T <sub>A</sub> = +25°C	-1.0	±0.1	+1.0	μA
EXV Leakage ourient		V <sub>IN_SBB</sub> = 5.5V, V <sub>LXA</sub> = 0V, or 5.5V	T <sub>A</sub> = +85°C		±1.0		μπ
		SBB0, SBB1,	T <sub>A</sub> = +25°C	-1.0	±0.1	+1.0	μΑ
LXB Leakage Current		SBB2 are disabled, $V_{IN\_SBB} = 5.5V$ , $V_{LXA} = 0V$ or 5.5V, all $V_{SBBx} = 5.5V$	T <sub>A</sub> = +85°C		±1.0		
		V <sub>IN_SBB</sub> = 5.5V,	T <sub>A</sub> = +25°C		+0.01	+1.0	
BST Leakage Current		V <sub>LXB</sub> = 5.5V, V <sub>BST</sub> = 11V,	T <sub>A</sub> = +85°C		+0.1		μA

#### **Electrical Characteristics—SIMO Buck-Boost (continued)**

 $(V_{SYS} = 3.7V, V_{IN\_SBB} = 3.7V, C_{SBBX} = 10\mu F, L = 1.5\mu H$ , limits are 100% production tested at  $T_A = +25^{\circ}C$ , limits over the operating temperature range  $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C)$  are guaranteed by design and characterization, unless otherwise noted.)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
		SBB0, SBB1,	T <sub>A</sub> = +25°C		+0.1	+1.0	
Disabled Output Leakage Current		SBB2 are disabled, active-discharge disabled (ADE_SBBx = 0), V <sub>SBBx</sub> = 5.5V, V <sub>LXB</sub> = 0V, V <sub>SYS</sub> = V <sub>IN</sub> SBB = V <sub>BST</sub> = 5.5V,	T <sub>A</sub> = +85°C		+0.2		μА
Active Discharge Resistance	R <sub>AD_SBBx</sub>	SBB0, SBB1, SBB2 discharge enabled (CNFG_SBBx_B.AD	80	140	260	Ω	
CONTROL SCHEME							
		CNFG_SBBx_B.IP_S	SBBx[1:0] = 0b11	-18%	0.335	+18%	
Peak Current Limit	I <sub>P_SBB</sub> ( <u>Note</u>	CNFG_SBBx_B.IP_S	SBBx[1:0] = 0b10	-14%	0.500	+14%	A
		CNFG_SBBx_B.IP_S	SBBx[1:0] = 0b01	-8%	0.750	+8%	] ^
		CNFG_SBBx_B.IP_S	SBBx[1:0] = 0b00	-7%	1.000	+7%	

Note 6: Typical values align with bench observations using the stated conditions with an inductor. Minimum and maximum values are tested in production with DC currents without an inductor. See the *Typical Operating Characteristics* SIMO switching waveforms to gain more insight on this specification.

#### Electrical Characteristics—Low Dropout Linear Regulator (LDO)/Load Switch (LSW)

 $(V_{SYS} = 3.7V)$ , limits are 100% production tested at  $T_A = +25$ °C, limits over the operating temperature range  $(T_A = -40$ °C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
LDO0/1	•					•
Input Voltage Pange	V	LDO mode	1.71		5.5	V
Input Voltage Range	V <sub>IN_LDOx</sub>	Switch mode	1.3		5.5	V
Quiescent Supply	l	I <sub>OUT_LDOx</sub> = 0		1.4	2.1	
Current	IN_LDOx	I <sub>OUT_LDOx</sub> = 0, switch mode		0.5	1	μA
Quiescent Supply Current In Dropout	I <sub>IN_DRP_LDOx</sub>	$I_{OUT\_LDOx} = 0$ , $V_{IN\_LDOx} = 2.9V$ , $V_{LDOx} = 3V$		2.1	4.6	μA
Maximum Output	1	V <sub>IN_LDOx</sub> > 1.8V	100			mΛ
Current	IOUT_LDOx	V <sub>IN_LDOx</sub> = 1.8V or lower	50			mA mA
Output Voltage	V <sub>OUT_LDOx</sub>		8.0		3.975	V
Output Accuracy		$V_{IN\_LDOx}$ = ( $V_{OUT\_LDOx}$ + 0.5V) or higher, $I_{OUT\_LDOx}$ = 1mA	-3.1		+3.1	%
Dropout Voltage	V <sub>DRP_LDOx</sub>	$V_{IN\_LDOx}$ = 3V, LDOx programmed to 3V, $I_{OUT\_LDOx}$ = 100mA			100	mV
Line Regulation		$V_{IN\_LDO_X} = (V_{OUT\_LDO_X} + 0.5 \text{ V}) \text{ to } 5.5 \text{ V}$	-0.5	<u> </u>	+0.5	%/V
Load Regulation		$V_{IN\_LDOx}$ = 1.8V or higher, $I_{OUT\_LDOx}$ = 100 $\mu$ A to 100 $\mu$ A		0.001	0.005	%/mA

# Electrical Characteristics—Low Dropout Linear Regulator (LDO)/Load Switch (LSW) (continued)

 $(V_{SYS} = 3.7V, limits are 100\% production tested at T_A = +25^{\circ}C, limits over the operating temperature range (T_A = -40^{\circ}C to +85^{\circ}C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Line Transient		V <sub>IN_LDOx</sub> = 4V to 5V, 200ns rise time		± 35		mV	
Line Transient		V <sub>IN_LDOx</sub> = 4V to 5V, 1µs rise time		± 25		IIIV	
Load Transient		I <sub>OUT_LDOx</sub> = 100μA to 10mA, 200ns rise time		100		- mV	
Load Transient		I <sub>OUT_LDOx</sub> = 100μA to 100mA, 200ns rise time		200			
Active Discharge Resistance	R <sub>AD_LDOX</sub>		42	80	200	Ω	
		V <sub>IN_LDOx</sub> = 2.7V, I <sub>OUT_LDOx</sub> = 100mA			0.8		
Switch Mode On- Resistance	R <sub>ON_LDOx</sub>	V <sub>IN_LDOx</sub> = 1.8V, I <sub>OUT_LDOx</sub> = 50mA			1	Ω	
recolotarios		$V_{IN\_LDOx}$ = 1.3V, $I_{OUT\_LDOx}$ = 5mA			3		
Slew Rate		I <sub>OUT_LDOx</sub> = 0mA, time from 10% to 90% of final register value		1.4		- V/ms	
Siew Rate		I <sub>OUT_LDOx</sub> = 0mA, time from 10% to 90% of final register value, switch mode		1.4		V/IIIS	
Short Circuit Current		$V_{IN\_LDOx} = 2.7V, V_{OUT\_LDOx} = GND$	170	380	620		
Limit		$V_{IN\_LDOx}$ = 2.7V, $V_{OUT\_LDOx}$ = 2.55V, switch mode	170	370		mA	
		10Hz to 100kHz, V <sub>IN_LDOx</sub> = 5V, V <sub>OUT_LDOx</sub> = 3.3V		150			
Output Noise		10Hz to 100kHz, V <sub>IN_LDOx</sub> = 5V, V <sub>OUT_LDOx</sub> = 2.5V		125		/	
		10Hz to 100kHz, V <sub>IN_LDOx</sub> = 5V, V <sub>OUT_LDOx</sub> = 1.2V				μV <sub>RMS</sub>	
		10Hz to 100kHz, V <sub>IN_LDOx</sub> = 5V, V <sub>OUT_LDOx</sub> = 0.9V		80			
Output DAC Bits				7		bits	
Output DAC LSB Size				25		mV	

## Electrical Characteristics—I<sup>2</sup>C Serial Communication

 $(V_{SYS} = 3.7V, V_{IO} = 1.8V, limits are 100\% production tested at T_A = +25^{\circ}C, limits over the operating temperature range (T_A = -40^{\circ}C to +85^{\circ}C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY	•					
V <sub>IO</sub> Voltage Range	V <sub>IO</sub>		1.7	1.8	3.6	V
V <sub>IO</sub> Bias Current		$V_{IO}$ = 3.6V, $V_{SDA}$ = $V_{SCL}$ = 0V or 3.6V, $T_A$ = +25°C	-1	0	+1	μA
		V <sub>IO</sub> = 1.7V, V <sub>SDA</sub> = V <sub>SCL</sub> = 0V or 1.7V	-1	0	+1	]
SDA AND SCL I/O STAG	E					
SCL, SDA Input High Voltage	V <sub>IH</sub>	V <sub>IO</sub> = 1.7V to 3.6V	0.7 x V <sub>IO</sub>			V

# Electrical Characteristics—I<sup>2</sup>C Serial Communication (continued)

 $(V_{SYS} = 3.7V, V_{IO} = 1.8V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
SCL, SDA Input Low Voltage	V <sub>IL</sub>	V <sub>IO</sub> = 1.7V to 3.6V			0.3 x V <sub>IO</sub>	V
SCL, SDA Input Hysteresis	V <sub>HYS</sub>			0.05 x V <sub>IO</sub>		V
SCL, SDA Input Leakage Current	Н	$V_{IO}$ = 3.6V, $V_{SCL}$ = $V_{SDA}$ = 0V and 3.6V	-10		+10	μΑ
SDA Output Low Voltage	V <sub>OL</sub>	Sinking 20mA			0.4	V
SCL, SDA Pin Capacitance	Cl			10		pF
Output Fall Time from V <sub>IH</sub> to V <sub>IL</sub>	t <sub>OF</sub> ( <u>Note 7</u> )				120	ns
I <sup>2</sup> C-COMPATIBLE INTER	RFACE TIMING (	STANDARD, FAST, AND FAST-MODE PLU	JS) ( <u>Note 7</u>	)		
Clock Frequency	f <sub>SCL</sub>		0		1000	kHz
Hold Time REPEATED START Condition	t <sub>HD_STA</sub>		0.26			μs
SCL Low Period	t <sub>LOW</sub>		0.5			μs
SCL High Period	tHIGH		0.26			μs
Setup Time REPEATED START Condition	tsu_sta		0.26			μs
Data Hold Time	t <sub>HD_DAT</sub>		0			μs
Data Setup Time	t <sub>SU_DAT</sub>		50			ns
Setup Time for STOP Condition	tsu_sto		0.26			μs
Bus Free Time between STOP and START Condition	t <sub>BUF</sub>		0.5			μs
Pulse Width of Suppressed Spikes	t <sub>SP</sub>	Maximum pulse width of spikes that must be suppressed by the input filter		50		ns
I <sup>2</sup> C-COMPATIBLE INTER	RFACE TIMING (	HIGH-SPEED MODE, C <sub>B</sub> = 100pF) ( <u>Note 7</u> )				
Clock Frequency	f <sub>SCL</sub>				3.4	MHz
Setup Time REPEATED START Condition	t <sub>SU_STA</sub>		160			ns
Hold Time REPEATED START Condition	t <sub>HD_STA</sub>		160			ns
SCL Low Period	t <sub>LOW</sub>		160			ns
SCL High Period	tHIGH		60			ns
Data Setup Time	tsu dat		10			ns
Data Hold Time	t <sub>HD_DAT</sub>		0		70	ns
SCL Rise Time	t <sub>rCL</sub>	T <sub>A</sub> = +25°C	10		40	ns

# Electrical Characteristics—I<sup>2</sup>C Serial Communication (continued)

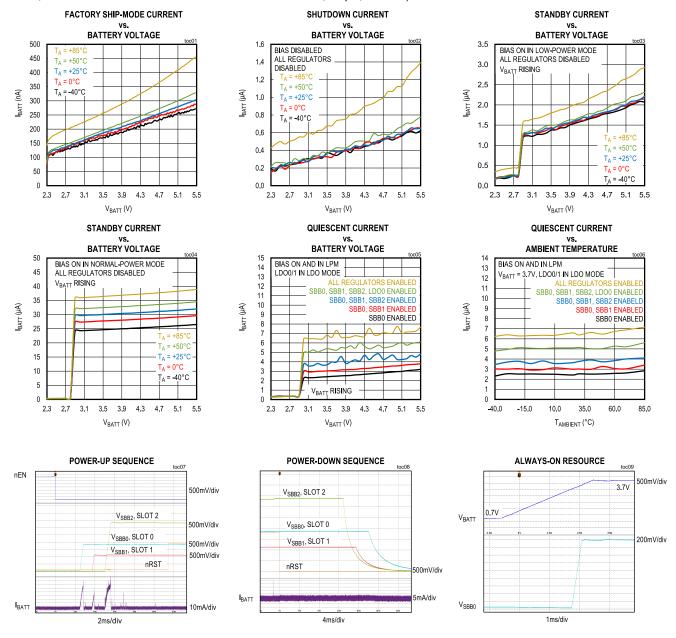
 $(V_{SYS} = 3.7V, V_{IO} = 1.8V, limits are 100\% production tested at T_A = +25°C, limits over the operating temperature range (T_A = -40°C to +85°C) are guaranteed by design and characterization, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Rise Time of SCL Signal after REPEATED START Condition and after Acknowledge Bit	t <sub>rCL1</sub>	T <sub>A</sub> = +25°C	10		80	ns
SCL Fall Time	$t_fCL$	T <sub>A</sub> = +25°C	10		40	ns
SDA Rise Time	$t_{rDA}$	T <sub>A</sub> = +25°C	10		80	ns
SDA Fall Time	t <sub>fDA</sub>	T <sub>A</sub> = +25°C	10		80	ns
Setup Time for STOP Condition	tsu_sto		160			ns
Bus Capacitance	C <sub>B</sub>				100	pF
Pulse Width of Suppressed Spikes	t <sub>SP</sub>	Maximum pulse width of spikes that must be suppressed by the input filter		10		ns
I <sup>2</sup> C-COMPATIBLE INTER	RFACE TIMING (	HIGH-SPEED MODE, C <sub>B</sub> = 400pF) ( <u>Note 7</u> )				
Clock Frequency	f <sub>SCL</sub>				1.7	MHz
Setup Time REPEATED START Condition	tsu_sta		160			ns
Hold Time REPEATED START Condition	t <sub>HD_STA</sub>		160			ns
SCL Low Period	t <sub>LOW</sub>		320			ns
SCL High Period	tHIGH		120			ns
Data Setup Time	tsu_dat		10			ns
Data Hold Time	t <sub>HD_DAT</sub>		0		150	ns
SCL Rise Time	t <sub>RCL</sub>	T <sub>A</sub> = +25°C	20		80	ns
Rise Time of SCL Signal after REPEATED START Condition and after Acknowledge Bit	<sup>t</sup> RCL1	T <sub>A</sub> = +25°C	20		80	ns
SCL Fall Time	t <sub>FCL</sub>	T <sub>A</sub> = +25°C	20		80	ns
SDA Rise Time	t <sub>RDA</sub>	T <sub>A</sub> = +25°C	20		160	ns
SDA Fall Time	t <sub>FDA</sub>	T <sub>A</sub> = +25°C	20		160	ns
Setup Time for STOP Condition	tsu_sto		160			ns
Bus Capacitance	C <sub>B</sub>				400	pF
Pulse Width of Suppressed Spikes	t <sub>SP</sub>	Maximum pulse width of spikes that must be suppressed by the input filter		10		ns

Note 7: Design guidance only. Not production tested.

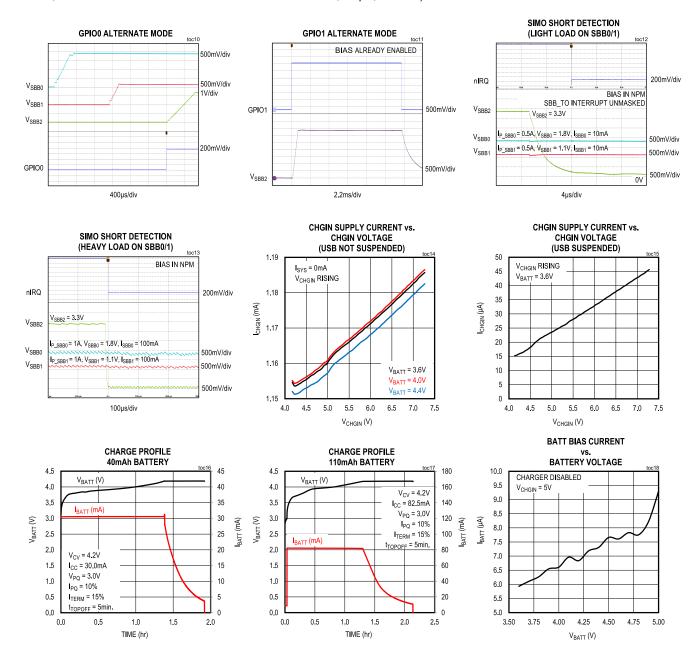
#### **Typical Operating Characteristics**

(Typical Applications Circuit.  $V_{CHGIN}$  = 0V,  $V_{SYS}$  =  $V_{IN\_SBB}$  =  $V_{BATT}$  = 3.7V,  $V_{IO}$  = 1.8V,  $T_{A}$  = +25°C,  $V_{SBB0}$  = 1.8V,  $I_{P\_SBB0}$  = 0.5A, SBB0 in Buck mode,  $V_{SBB1}$  = 1.1V,  $I_{P\_SBB1}$  = 0.5A, SBB1 in Buck mode,  $V_{SBB2}$  = 3.3V,  $I_{P\_SBB2}$  = 1A peak, SBB2 in Buck-Boost mode, unless otherwise noted. Inductor = DFE201612E-2R2M, 2.2 $\mu$ H, 116 $m\Omega$ .)



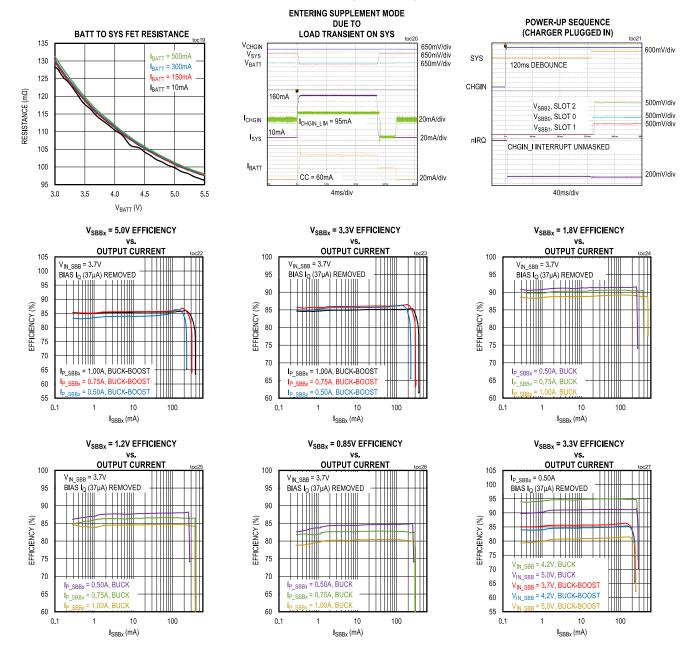
#### **Typical Operating Characteristics (continued)**

(Typical Applications Circuit.  $V_{CHGIN}$  = 0V,  $V_{SYS}$  =  $V_{IN\_SBB}$  =  $V_{BATT}$  = 3.7V,  $V_{IO}$  = 1.8V,  $T_{A}$  = +25°C,  $V_{SBB0}$  = 1.8V,  $I_{P\_SBB0}$  = 0.5A, SBB0 in Buck mode,  $V_{SBB1}$  = 1.1V,  $I_{P\_SBB1}$  = 0.5A, SBB1 in Buck mode,  $V_{SBB2}$  = 3.3V,  $I_{P\_SBB2}$  = 1A peak, SBB2 in Buck-Boost mode, unless otherwise noted. Inductor = DFE201612E-2R2M, 2.2 $\mu$ H, 116 $m\Omega$ .)



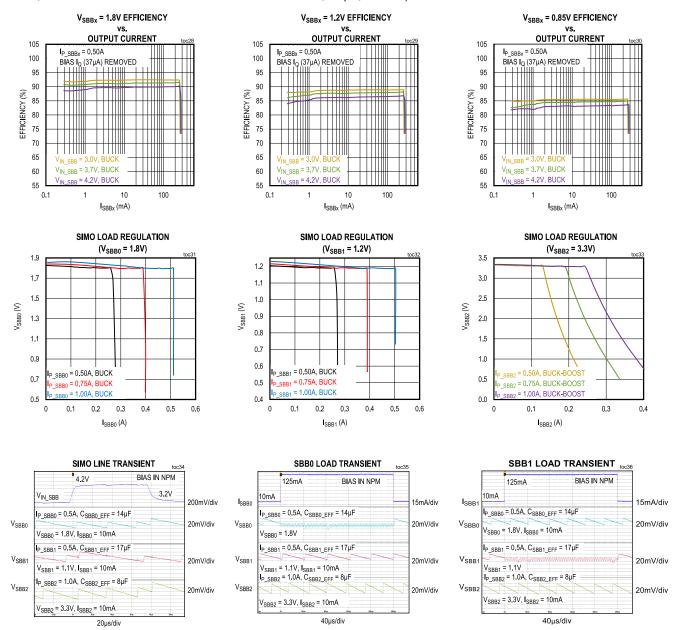
#### **Typical Operating Characteristics (continued)**

(Typical Applications Circuit.  $V_{CHGIN}$  = 0V,  $V_{SYS}$  =  $V_{IN\_SBB}$  =  $V_{BATT}$  = 3.7V,  $V_{IO}$  = 1.8V,  $T_{A}$  = +25°C,  $V_{SBB0}$  = 1.8V,  $I_{P\_SBB0}$  = 0.5A, SBB0 in Buck mode,  $V_{SBB1}$  = 1.1V,  $I_{P\_SBB1}$  = 0.5A, SBB1 in Buck mode,  $V_{SBB2}$  = 3.3V,  $I_{P\_SBB2}$  = 1A peak, SBB2 in Buck-Boost mode, unless otherwise noted. Inductor = DFE201612E-2R2M, 2.2 $\mu$ H, 116 $m\Omega$ .)



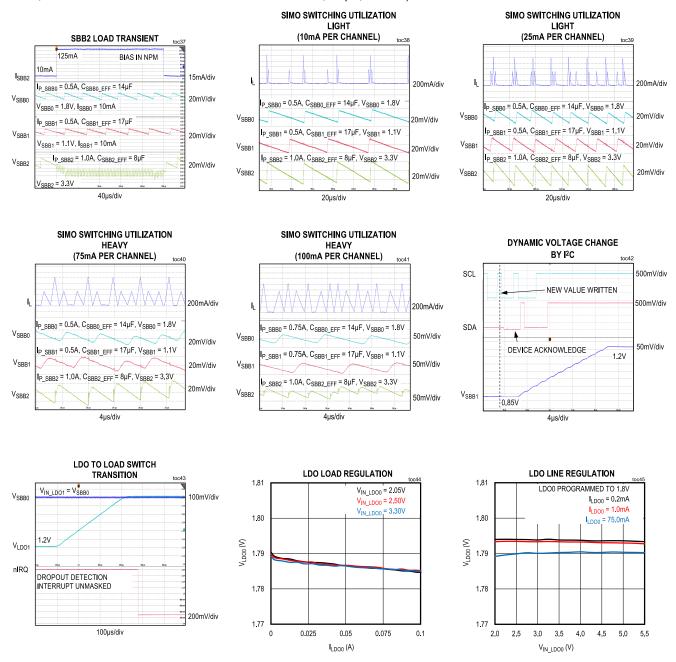
#### **Typical Operating Characteristics (continued)**

(Typical Applications Circuit.  $V_{CHGIN}$  = 0V,  $V_{SYS}$  =  $V_{IN\_SBB}$  =  $V_{BATT}$  = 3.7V,  $V_{IO}$  = 1.8V,  $T_{A}$  = +25°C,  $V_{SBB0}$  = 1.8V,  $I_{P\_SBB0}$  = 0.5A, SBB0 in Buck mode,  $V_{SBB1}$  = 1.1V,  $I_{P\_SBB1}$  = 0.5A, SBB1 in Buck mode,  $V_{SBB2}$  = 3.3V,  $I_{P\_SBB2}$  = 1A peak, SBB2 in Buck-Boost mode, unless otherwise noted. Inductor = DFE201612E-2R2M, 2.2 $\mu$ H, 116 $m\Omega$ .)



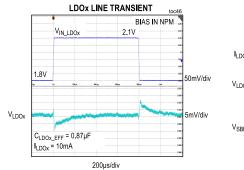
#### **Typical Operating Characteristics (continued)**

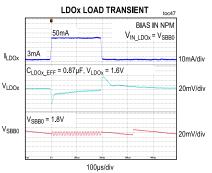
(Typical Applications Circuit.  $V_{CHGIN}$  = 0V,  $V_{SYS}$  =  $V_{IN\_SBB}$  =  $V_{BATT}$  = 3.7V,  $V_{IO}$  = 1.8V,  $T_{A}$  = +25°C,  $V_{SBB0}$  = 1.8V,  $I_{P\_SBB0}$  = 0.5A, SBB0 in Buck mode,  $V_{SBB1}$  = 1.1V,  $I_{P\_SBB1}$  = 0.5A, SBB1 in Buck mode,  $V_{SBB2}$  = 3.3V,  $I_{P\_SBB2}$  = 1A peak, SBB2 in Buck-Boost mode, unless otherwise noted. Inductor = DFE201612E-2R2M, 2.2 $\mu$ H, 116 $m\Omega$ .)

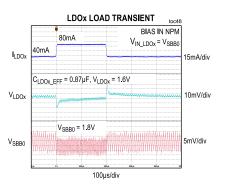


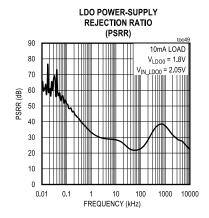
#### **Typical Operating Characteristics (continued)**

(Typical Applications Circuit.  $V_{CHGIN}$  = 0V,  $V_{SYS}$  =  $V_{IN\_SBB}$  =  $V_{BATT}$  = 3.7V,  $V_{IO}$  = 1.8V,  $T_{A}$  = +25°C,  $V_{SBB0}$  = 1.8V,  $I_{P\_SBB0}$  = 0.5A, SBB0 in Buck mode,  $V_{SBB1}$  = 1.1V,  $I_{P\_SBB1}$  = 0.5A, SBB1 in Buck mode,  $V_{SBB2}$  = 3.3V,  $I_{P\_SBB2}$  = 1A peak, SBB2 in Buck-Boost mode, unless otherwise noted. Inductor = DFE201612E-2R2M, 2.2 $\mu$ H, 116 $m\Omega$ .)



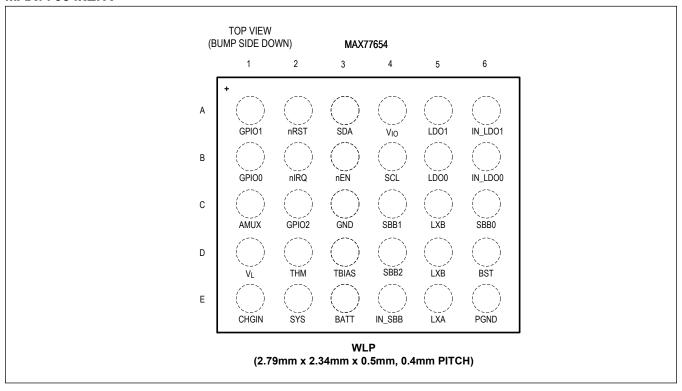




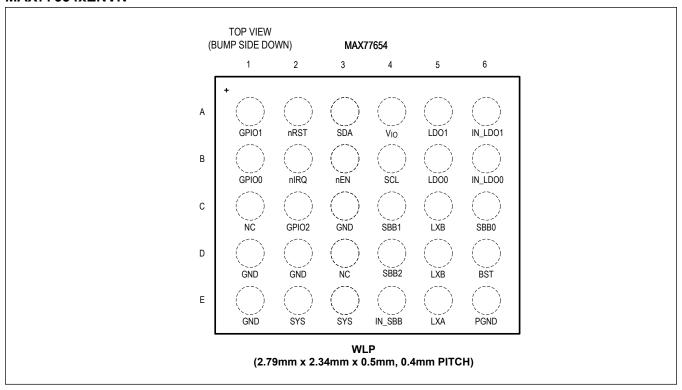


### **Pin Configurations**

#### MAX77654xENV



#### MAX77654xENVN



#### **Pin Description**

PIN				
MAX77654xE NV	MAX77654xE NVN	NAME	FUNCTION	TYPE
	C1, D3	NC	Not connected.	
TOP LEVEL				
A4	A4	V <sub>IO</sub>	I <sup>2</sup> C Interface and GPIO Driver Power	Power Input
В3	В3	nEN	Active-Low Enable Input. EN supports push-button or slide-switch configurations. If not used, connect EN to SYS and use the CNFG_SBBx_B.EN_SBBx[2:0] and CNFG_LDOx_B.EN_LDOx[2:0] bitfields to enable channels.  Pulled up internally to V <sub>CCINT</sub> .	Digital Input
B2	B2	nIRQ	Active-Low, Open-Drain Interrupt Output. Connect a $100k\Omega$ pullup resistor between $\overline{IRQ}$ and a voltage equal to or less than $V_{SYS}$ .	Digital Output
A2	A2	nRST	Active-Low, Open-Drain Reset Output. Connect a $100k\Omega$ pullup resistor between $\overline{RST}$ and a voltage equal to or less than $V_{SYS}$ .	Digital Output
C2	C2	GPIO2	General Purpose Input/Output. The GPIO I/O stage is internally biased with V <sub>IO</sub>	Digital I/O
A1	A1	GPIO1	General Purpose Input/Output. The GPIO I/O stage is internally biased with V <sub>IO</sub> .	Digital I/O
B1	B1	GPIO0	General Purpose Input/Output. The GPIO I/O stage is internally biased with V <sub>IO</sub> .	Digital I/O
B4	B4	SCL	I <sup>2</sup> C Clock	Digital Input

# **Pin Description (continued)**

PIN				
MAX77654xE NV	MAX77654xE NVN	NAME	FUNCTION	TYPE
A3	A3	SDA	I <sup>2</sup> C Data	Digital I/O
C3	C3, D1, D2, E1	GND	Quiet Ground. Connect GND to PGND, and the low-impedance ground plane of the PCB.	Ground
CHARGER				,
E1	_	CHGIN	Charger Input. Connect to a DC charging source. Bypass to GND with a $4.7\mu F$ ceramic capacitor.	Power Input
E2	E2, E3	SYS	System Power Output. SYS provides power to the system resources as well as the control logic of the device. Connect to IN_SBB and bypass to GND with a 22µF ceramic capacitor.	Power Output
E3	_	BATT	Li+ Battery Connection. Connect to positive battery terminal. Bypass to GND with a 4.7µF ceramic capacitor.	Power I/O
D1	_	VL	Internal Charger 3V Logic Supply Powered from CHGIN. Bypass to GND with a 1 $\mu$ F ceramic capacitor. Do not load V <sub>L</sub> externally.	Power Output
D3	_	TBIAS	Thermistor Bias Supply. Connect a resistor equal to the NTCs room temperature resistance between TBIAS and THM. Do not load TBIAS with any other external circuitry. If not used, leave the pin disconnected.	Analog
D2	_	THM	Thermistor Monitor. Thermally couple an NTC to the battery and connect between THM and GND. If not used, connect THM directly to ground.	Analog Input
C1	_	AMUX	Analog Multiplexer Output. Connect to system ADC to perform conversions on charger power signals.	Analog Output
SIMO BUCK-E	OOST			
E4	E4	IN_SBB	SIMO Power Input. Connect IN_SBB to SYS and bypass to PGND with a minimum of 10µF ceramic capacitor as close as possible to the IN_SBB pin.	Power Input
C6	C6	SBB0	SIMO Buck-Boost Output 0. SBB0 is the power output for channel 0 of the SIMO buck-boost. Bypass SBB0 to PGND with a $10\mu$ F ceramic capacitor. If not used, see the <u>Unused Outputs</u> section.	Power Output
C4	C4	SBB1	SIMO Buck-Boost Output 1. SBB1 is the power output for channel 1 of the SIMO buck-boost. Bypass SBB1 to PGND with a 10µF ceramic capacitor. If not used, see the <i>Unused Outputs</i> section.	Power Output
D4	D4	SBB2	SIMO Buck-Boost Output 2. SBB2 is the power output for channel 2 of the SIMO buck-boost. Bypass SBB0 to PGND with a 10µF ceramic capacitor. If not used, see the <i>Unused Outputs</i> section.	Power Output
D6	D6	BST	SIMO Power Input for the High-Side Output NMOS Drivers. Connect a 3300pF ceramic capacitor between BST and LXB.	Power Input
D5, C5	D5, C5	LXB	Switching Node B. LXB is driven between PGND and SBBx when SBBx is enabled. LXB is driven to PGND when all SIMO channels are disabled. Connect a 1.5µH inductor between LXA and LXB.	Power Input
E5	E5	LXA	Switching Node A. LXA is driven between PGND and IN_SBB when any SIMO channel is enabled. LXA is driven to PGND when all SIMO channels are disabled. Connect a 1.5µH inductor between LXA and LXB.	Power I/O
E6	E6	PGND	Power ground for the SIMO low-side FETs. Connect PGND to GND, and the low-impedance ground plane of the PCB.	Ground

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

# **Pin Description (continued)**

Pi	IN			
MAX77654xE NV	MAX77654xE NVN	NAME	FUNCTION	TYPE
LDO				
В6	В6	IN_LDO0	Linear Regulator Input. If connected to a SIMO output with a short trace, IN_LDO0 can share the output's capacitor. Otherwise, bypass with a 2.2µF ceramic capacitor to ground. If not used, connect to ground or leave unconnected.	Power Input
A6	A6	IN_LDO1	Linear Regulator Input. If connected to a SIMO output with a short trace, IN_LDO1 can share the output's capacitor. Otherwise, bypass with a 2.2µF ceramic capacitor to ground. If not used, connect to ground or leave unconnected.	Power Input
B5	B5	LDO0	Linear Regulator Output 0. Bypass with a 1.0µF ceramic capacitor to GND. If not used, disable LDO0 and connect this pin to ground or leave unconnected.	Power Output
A5	A5	LDO1	Linear Regulator Output 1. Bypass with a 1.0µF ceramic capacitor to GND. If not used, disable LDO1 and connect this pin to ground or leave unconnected.	Power Output

#### **Detailed Description**

The MAX77654 provides a highly-integrated battery charging and power management solution for low-power applications. The linear charger can charge various Li+ batteries with a wide range of charge current and charger termination voltage options. Temperature monitoring and JEITA compliance settings add additional functionality and safety to the charger.

Five regulators are integrated within this device (see <u>Table 1</u>). A single-inductor, multiple output (SIMO) buck-boost regulator efficiently provides three independently programmable power rails. Two 100mA low-dropout linear regulators (LDOs) provide ripple rejection for audio and other noise sensitive applications.

This device includes other features such as an analog multiplexer that switches several internal voltage and current signals to an external node for monitoring with an external ADC. A bidirectional I<sup>2</sup>C serial interface allows for configuring and checking the status of the device. An internal on/off controller provides regulator sequencing and supervisory functionality for the device.

**Table 1. Regulator Summary** 

REGULATOR NAME	REGULATOR TOPOLOGY	MAXIMUM I <sub>OUT</sub> (mA)	V <sub>IN</sub> RANGE	MAX77654 V <sub>OUT</sub> RANGE/ RESOLUTION
SBB0	SIMO	Up to 500*	2.7 to 5.5V	0.8 to 5.5V in 50mV steps
SBB1	SIMO	Up to 500*	2.7 to 5.5V	0.8 to 5.5V in 50mV steps
SBB2	SIMO	Up to 500*	2.7 to 5.5V	0.8 to 5.5V in 50mV steps
LDO0/1	PMOS LDOs	100	1.7 to 5.5V	0.8 to 3.975V in 25mV steps

<sup>\*</sup>Shared capacity with other SBBx channels. See the SIMO Available Output Current section for more information.

#### **Part Number Decoding**

The MAX77654 has different one-time programmable (OTP) options and variants to support a variety of applications. OTP options set default settings such as output voltage or CHGIN current limit. Variants are versions of MAX77654 with different features. See <a href="Figure 1">Figure 1</a> for how to identify these. <a href="Table 2">Table 2</a> and <a href="Table 3">Table 3</a> list all available OTP options and variants. Refer to <a href="Maxim Integrated naming convention">Maxim Integrated naming convention</a> for more details.

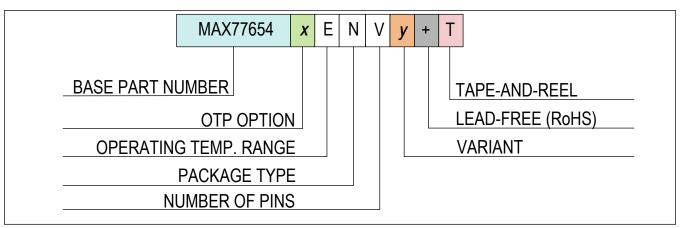


Figure 1. Part Number Decode

**Table 2. Variants Table** 

VARIANT LETTER	NONE	N
Supports Charger, Analog Multiplexer, and Thermistor?	Yes	
Supports SIMO Buck-Boost Regulator?	Yes	Yes
Supports LDO/LSW?	Yes	Yes
Supports I <sup>2</sup> C Serial Communication?	Yes	Yes

### **Table 3. OTP Options Table**

		OTP LETTER AND SETTINGS							
	VARIANT				NONE			,	N
Block	Bit Field Name	Α	В	C*	D	F	M	N	Α
	SBIA_LPM (Bias Power Mode)	NPM	NPM	NPM	NPM	NPM	NPM	LPM	NPM
	DBEN_nEN (nEN Debounce time)	500µs	500µs	30ms	500µs	30ms	500µs	500us	500µs
	nEN_MODE	Push- Button	Push- Button	Push- Button	Push- Button	Push- Button	Push- Button	Push- Button	Slide- Switch
	T_MRST (Manual Reset Time)	8s	8s	8s	8s	16s	8s	8s	8s
	ALT_GPIO0 (GPIO0 Mode)	GPIO	Alt.	GPIO	GPIO	GPIO	GPIO	GPIO	GPIO
Global	ALT_GPIO1 (GPIO1 Mode)	GPIO	Alt.	GPIO	GPIO	GPIO	Alt.	GPIO	GPIO
Global	ALT_GPIO2 (GPIO2 Mode)	GPIO	Alt.	GPIO	GPIO	GPIO	Alt.	GPIO	GPIO
	ADDR (I <sup>2</sup> C Address (7-bit))	0x48	0x48	0x48	0x48	0x48	0x48	0x48	0x48
	UVLO_F[3:0] (SYSUVLO Falling)	2.60V	2.60V	2.85V	2.60V	2.60V	2.60V	2.60V	2.60V
	UVLO_H[3:0] (SYSUVLO Hysteresis)	0.30V	0.30V	0.30V	0.30V	0.15V	0.30V	0.30V	0.30V
	DIDM (Metal Option ID)	0b0	0b0	0b0	0b0	0b0	0b0	0b0	0b0
	CID[4:0] (Chip ID)	0x6	0x2	0x9	0xC	0x12	0xA	0x11	0x7
Watchdog	WDT_LOCK (Watchdog Timer Disable Lock)	Unlocked	Unlocked	Unlocked	Unlocked	Unlocked	Unlocked	Unlocked	Unlocked
	WDT_EN (Watchdog Timer Enable)	Disabled	Disabled	Disabled	Disabled	Disabled	Disabled	Disabled	Disabled
	TV_SBB0[6:0] (SBB0 V <sub>OUT</sub> )	1.800V	3.000V	4.000V	2.050V	0.800V	1.800V	2.050V	1.350V
SIMO	IP_SBB0[1:0] (SBB0 Inductor Current Peak Limit)	0.500A	1.000A	0.500A	0.500A	0.333A	0.500A	0.500A	1.000A
	OP_MODE (SBB0) (SBB0 Operating Mode)	Buck	Buck	Buck- Boost	Buck	Buck	Buck	Buck	Buck

**Table 3. OTP Options Table (continued)** 

	<u>-</u>			ОТІ	LETTER A	AND SETTI	NGS		
	VARIANT				NONE				N
Block	Bit Field Name	Α	В	C*	D	F	М	N	Α
	ADE_SBB0 (Active-Discharge Resistor Enable)	Enabled	Enabled	Enabled	Enabled	Disabled	Enabled	Enabled	Disabled
	EN_SBB0[2:0] (SBB0 Enable Control)	Off	Off	Off	FPS Slot 0	Off	On	FPS Slot 0	Off
	TV_SBB1[6:0] (SBB1 V <sub>OUT</sub> )	1.800V	1.800V	1.800V	1.200V	1.850V	1.100V	3.300V	1.800V
	IP_SBB1[1:0] (SBB1 Inductor Current Peak Limit)	0.500A	1.000A	0.333A	0.500A	0.333A	0.500A	0.500A	1.000A
	OP_MODE (SBB1) (SBB1 Operating Mode)	Buck	Buck	Buck	Buck	Buck	Buck	Buck- Boost	Buck
	ADE_SBB1 (Active-Discharge Resistor Enable)	Enabled	Enabled	Enabled	Enabled	Disabled	Enabled	Enabled	Disabled
	EN_SBB1[2:0] (SBB1 Enable Control)	FPS Slot	On	FPS Slot	FPS Slot 3	On	On	FPS Slot 0	FPS Slot 0
	TV_SBB2[6:0] (SBB2 V <sub>OUT</sub> )	3.500V	3.500V	4.000V	3.300V	0.800V	3.300V	3.300V	3.300V
	IP_SBB2[1:0] (SBB2 Inductor Current Peak Limit)	0.333A	1.000A	0.333A	0.500A	0.333A	1.000A	0.500A	1.000A
	OP_MODE (SBB2) (SBB2 Operating Mode)	Buck- Boost	Buck- Boost	Buck- Boost	Buck- Boost	Buck	Buck- Boost	Buck- Boost	Buck- Boost
	ADE_SBB2 (Active-Discharge Resistor Enable)	Enabled	Enabled	Disabled	Enabled	Disabled	Enabled	Enabled	Enabled
	EN_SBB2[2:0] (SBB2 Enable Control)	Off	Off	Off	FPS Slot 0	Off	On	FPS Slot 0	FPS Slot
	TV_LDO0[6:0] (LDO0 V <sub>OUT</sub> )	1.800V	1.800V	1.800V	1.850V	0.800V	1.600V	1.850V	1.200V
	LDO0_MD (LDO or LSW Mode)	LDO	LDO	LDO	LDO	LDO	LDO	LDO	LDO
	ADE_LDO0 (Active-Discharge Resistor Enable)	Enabled	Enabled	Enabled	Enabled	Disabled	Enabled	Enabled	Enabled
100	EN_LDO0[2:0] (LDO0 Enable Control)	FPS Slot	Off	Off	FPS Slot 1	Off	FPS Slot	FPS Slot 1	FPS Slot 1
LDO	TV_LDO1[6:0] (LDO1 V <sub>OUT</sub> )	3.000V	Don't Care	3.000V	Don't Care	0.800V	Don't Care	1.850V	1.350V
	LDO1_MD (LDO or LSW Mode)	LDO	LSW	LDO	LSW	LDO	LSW	LDO	LDO
	ADE_LDO1 (Active-Discharge Resistor Enable)	Enabled	Enabled	Enabled	Disabled	Disabled	Enabled	Enabled	Disabled
	EN_LDO1[2:0] (LDO1 Enable Control)	Off	Off	Off	Off	Off	FPS Slot 2	FPS Slot 1	Off

#### **Table 3. OTP Options Table (continued)**

			OTP LETTER AND SETTINGS						
	VARIANT	NONE						N	
Block	Bit Field Name	Α	В	C*	D	F	М	N	Α
	CHG_EN (Charger Enable)	Enabled	Enabled	Enabled	Disabled	Enabled	Enabled	Enabled	
Charger	ICHGIN_LIM_DEF (Default Charger Input Current Limit)	95mA	95mA	95mA	475mA	475mA	475mA	95mA	

<sup>\*</sup>Future OTP option. Contact Maxim Integrated for availability.

#### **Support Material**

The following support materials are available for this device:

- MAX77654 <u>Register Map</u>: Full table of registers that can be read from or written to by I<sup>2</sup>C.
- MAX77654 *Programmer's Guide*: Basic software implementation guidance.
- MAX77654 <u>SIMO Calculator</u>: Tool to estimate supported maximum current and ripple for specified conditions.

#### **Top-Level Interconnect Simplified Diagram**

<u>Figure 2</u> shows the same major blocks as the <u>Typical Applications Circuit</u> with an increased emphasis on the routing between each block. This diagram is intended to familiarize the user with the landscape of the device. Many of the details associated with these signals are discussed throughout the data sheet. At this stage of the data sheet, note the addition of the main bias and clock block that are not shown in the <u>Typical Applications Circuit</u> section. The main bias and clock block provides voltage, current, and clock references for other blocks as well as many resources for the top-level digital control.

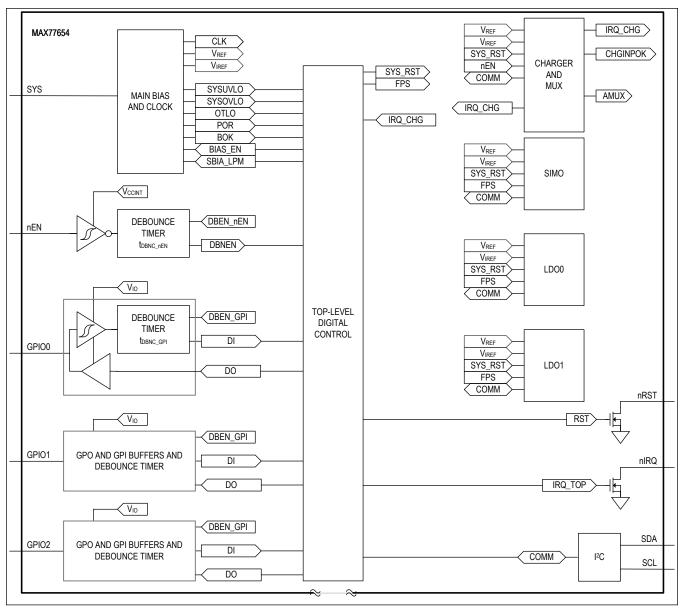


Figure 2. Top-Level Interconnect Simplified Diagram

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

## **Detailed Description—Global Resources**

The global resources encompass a set of circuits that serve the entire device and ensure safe, consistent, and reliable operation.

#### **Features and Benefits**

- Voltage Monitors
  - SYS POR (power-on-reset) comparator generates a reset signal upon power-up.
  - SYS undervoltage ensures repeatable behavior when power is applied to and removed from the device.
  - SYS overvoltage monitor inhibits operation with overvoltage power sources to ensure reliability in faulty environments.
- Thermal Monitors
  - +165°C junction temperature shutdown
- Manual Reset
  - · 8s or 16s period
- Wake-up Events
  - · Charger insertion (with 120ms debounce)
  - · nEN input assertion
- Interrupt Handler
  - Interrupt output (nIRQ)
  - · All interrupts are maskable
- Push-Button/Slide-Switch On-key (nEN)
  - Configurable push-button/slide-switch functionality
  - 500µs or 30ms debounce timer interfaces directly with mechanical switches
- On/Off Controller
  - · Startup/shut-down sequencing
  - · Programmable sequencing delay
- GPIO, RST Digital I/Os

#### **Voltage Monitors**

The device monitors the system voltage ( $V_{SYS}$ ) to ensure proper operation using three comparators (POR, UVLO, and OVLO). These comparators include hysteresis to prevent their outputs from toggling between states during noisy system transitions.

#### **SYS POR Comparator**

The SYS POR comparator monitors  $V_{SYS}$  and generates a power-on reset signal (POR). When  $V_{SYS}$  is below  $V_{POR}$ , the device is held in reset (SYSRST = 1). When  $V_{SYS}$  rises above  $V_{POR}$ , internal signals and on-chip memory stabilize and the device is released from reset (SYSRST = 0).

#### **SYS Undervoltage-Lockout Comparator**

The SYS undervoltage-lockout (UVLO) comparator monitors  $V_{SYS}$  and generates a SYSUVLO signal when the  $V_{SYS}$  falls below UVLO threshold. The SYSUVLO signal is provided to the top-level digital controller. See <u>Figure 6</u> and <u>Table 6</u> for additional information regarding the UVLO comparator:

- When the device is in the STANDBY state, the UVLO comparator is disabled.
- When transitioning out of the STANDBY state, the UVLO comparator is enabled allowing the device to check for sufficient input voltage. If the device has sufficient input voltage, it can transition to the RESOURCE ON state; if there is insufficient input voltage, the device transitions back to the STANDBY state.

#### SYS Overvoltage-Lockout Comparator

The device is rated for 5.5V maximum operating voltage ( $V_{SYS}$ ) with an absolute maximum input voltage of 6.0V. An overvoltage-lockout monitor increases the robustness of the device by inhibiting operation when the supply voltage is greater than  $V_{SYSOVIO}$ . See Figure 6 and Table 6 for additional information regarding the OVLO comparator:

• When the device is in the STANDBY state, the OVLO comparator is disabled.

### **Chip Identification**

The MAX77654 offers different one-time-programmable (OTP) options to, for example, set the default output voltages. These options are identified by the chip identification number, which can be read in the CID register.

### **nEN Enable Input**

nEN is an active-low internally debounced digital input that typically comes from the system's on-key. The debounce time is programmable with CNFG\_GLBL.DBEN\_nEN. The primary purpose of this input is to generate a wake-up signal for the PMIC that turns on the regulators. Maskable rising/falling interrupts are available for nEN (INT\_GLBL0.nEN\_R and INT\_GLBL0.nEN\_F) for alternate functionality.

The nEN input can be configured to work either with a push-button (CNFG\_GLBL.nEN\_MODE = 0) or a slide-switch (CNFG\_GLBL.nEN\_MODE = 1). See <u>Figure 3</u> for more information. In both push-button mode and slide-switch mode, the on/off controller looks for a falling edge on the nEN input to initiate a power-up sequence.

#### nEN Manual Reset

nEN works as a manual reset input when the on/off controller is in the "Resource-On" state. The manual reset function is useful for forcing a power-down in case communication with the processor fails. When nEN is configured for push-button mode and the input is asserted (nEN = LOW) for an extended period (t<sub>MRST</sub>), the on/off controller initiates a power-down sequence and goes to standby mode. When nEN is configured for slide-switch mode and the input is deasserted (nEN = HIGH) for an extended period (t<sub>MRST</sub>), the on/off controller initiates a power-down sequence and goes to standby mode.

### nEN Dual-Functionality: Push-Button vs. Slide-Switch

The nEN digital input can be configured to work with a push-button or a slide-switch. The timing diagram below shows nENs dual functionality for power-on sequencing and manual reset. The default configuration of the device is push-button mode (CNFG\_GLBL.nEN\_MODE = 0) and no additional programming is necessary. Applications that use a slide-switch on-key configuration must set CNFG\_GLBL.nEN\_MODE = 1 within t<sub>MRST</sub>.

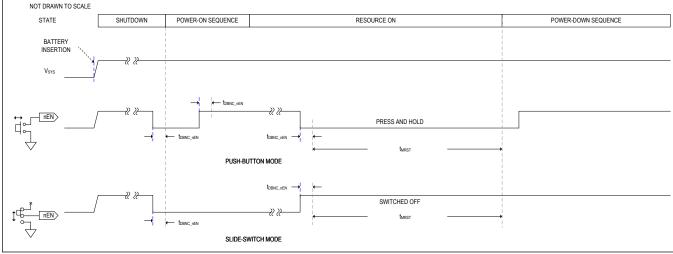


Figure 3. nEN Usage Timing Diagram

## nEN Internal Pullup Resistors to V<sub>CCINT</sub>

The nEN logic thresholds are referenced to  $V_{CCINT}$ , an always-on internal voltage domain. There are internal pullup resistors between nEN and  $V_{CCINT}$  ( $R_{nEN\_PU}$ ), which can be configured with the CNFG\_GLBL\_A.PU\_DIS bit. See Figure 4. While PU\_DIS = 0, the pullup value is approximately 200k $\Omega$ . While PU\_DIS = 1, the pullup value is 10M $\Omega$ .

V<sub>CCINT</sub> defined by the following conditions:

- V<sub>CCINT</sub> = V<sub>L</sub> (3V typ.) if CHGIN is valid (STAT\_CHG\_B.CHGIN\_DTLS[1:0] = 0b11) and not USB suspended (CNFG\_CHG\_G.USBS = 0).
- V<sub>CCINT</sub> = V<sub>BATT</sub> if CHGIN is invalid (STAT\_CHG\_B.CHGIN\_DTLS[1:0] ≠ 0b11) or CHGIN is valid but USB suspended (CNFG\_CHG\_G.USBS = 1).

Applications using a slide-switch on-key or push-pull digital output connected to nEN can reduce quiescent current consumption by changing pullup strength to  $10M\Omega$ . Applications using normally-open, momentary, and push-button on-keys (as shown in Figure 4) do not create this leakage path and should use the stronger  $200k\Omega$  pullup option.

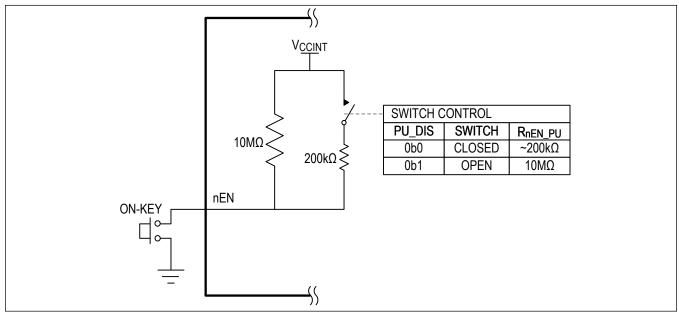


Figure 4. nEN Pullup Resistor Configuration

### Interrupts (nIRQ)

nIRQ is an active-low, open-drain output that is typically routed to the host processor's interrupt input to signal an important change in device status. See the <u>Register Map</u> section for a comprehensive list of all interrupt bits and status registers.

A pullup resistor to a voltage less than or equal to  $V_{SYS}$  is required for this node. nIRQ is the logical NOR of all unmasked interrupt bits in the register map.

All interrupts are masked by default. Masked interrupt bits do not cause the nIRQ pin to change. Unmask the interrupt bits to allow nIRQ to assert.

## Reset Output (nRST)

nRST is an open-drain, active-low output that is typically used to hold the processor in a reset state when the device is powered down. During a power-up sequence, the nRST deasserts after the last regulator in the power-up chain is enabled (t<sub>RSTODD</sub>). During a power-down sequence, the nRST output asserts before any regulator is powered down (t<sub>RSTOAD</sub>). See <u>Figure 10</u> for nRST timing.

A pullup resistor to a voltage less than or equal to V<sub>SYS</sub> is required for this node.

### **General-Purpose Input Output (GPIO)**

The provided general-purpose input/output (GPIO) pins increase system flexibility. See Figure 5 for more details.

Clear CNFG\_GPIOx.DIR to configure GPIO as a general-purpose output (GPO). The GPO can either be in push-pull mode (CNFG\_GPIOx.DRV = 1) or open-drain mode (CNFG\_GPIOx.DRV = 0).

- The push-pull output mode is ideal for applications that need fast (~2ns) edges and low power consumption.
- The open-drain mode requires an external pullup resistor (typically 10kΩ–100kΩ). Connect the external pullup resistor to a bias voltage that is less than or equal to V<sub>IO</sub>.
  - The open-drain mode can be used to communicate to different logic domains. For example, to send a signal from the GPO on a 1.8V logic domain (V<sub>IO</sub> = 1.8V) to a device on a 1.2V logic domain, connect the external pullup resistor to 1.2V.
  - The open-drain mode can be used to connect several open-drain (or open-collector) devices together on the same bus to create wired logic (wired AND logic is positive-true; wired OR logic is negative-true).
- The general-purpose input (GPI) functions are still available while the pin is configured as a GPO. In other words, the CNFG\_GPIOx.DI (input status) bit still functions and does not collide with the state of the CNFG\_GPIOx.DIR bit.

Set CNFG\_GPIOx.DIR to have the GPIO function as a GPI. The GPI features a 30ms debounce timer (t<sub>DBNC\_GPI</sub>) that can be enabled or disabled with DBEN\_GPI.

- Enable the debounce timer (CNFG\_GPIOx.DBEN\_GPI = 1) if the GPI is connected to a device that can bounce or chatter, like a mechanical switch.
- If the GPI is connected to a circuit with clean logic transitions and no risk of bounce, disable the debounce timer (CNFG\_GPIOx.DBEN\_GPI = 0) to eliminate logic delays. With no debounce timer, the GPI input logic propagates to nIRQ in 10ns.

A dedicated internal oscillator is used to create the 30ms ( $t_{DBNC\_GPI}$ ) debounce timer. To obtain low  $V_{IO}$  supply current, ensure the GPIO voltage is either logic high or logic low. If the GPIO pin is unconnected (either as a GPI or an open-drain GPO) and  $V_{IO}$  is powered, the GPIO voltage trends towards the logic level gray area (0.3 x  $V_{IO}$  <  $V_{GPIO}$  < 0.7 x  $V_{IO}$ ). If  $V_{GPIO}$  is in the gray area,  $V_{IO}$  current can be more than  $10\mu A$ .

The GPI features edge detectors that feed into the top-level interrupt system of the chip. This allows software to use interrupts to service events associated with a GPI change instead of polling for these changes.

- If the application wants nIRQ to go low **only on a GPI rising edge**, then it should **clear** the GPI rising edge interrupt mask bit (INTM\_GLBL1.GPI\_RM = **0**) and **set** the GPI falling edge interrupt mask bit (INTM\_GLBL1.GPI\_FM = **1**).
- If the application wants nIRQ to go low **only on a GPI falling edge**, then it should **set** the GPI rising edge interrupt mask bit (INTM\_GLBL1.GPI\_RM = 1) and **clear** the GPI falling edge interrupt mask bit (INTM\_GLBL1.GPI\_FM = 0).
- If the application wants nIRQ to go low on both GPI falling and rising edges, then it should clear the GPI rising edge interrupt mask bit (INTM\_GLBL1.GPI\_RM = 0) and clear the GPI falling edge interrupt mask bit (INTM\_GLBL1.GPI\_FM = 0).

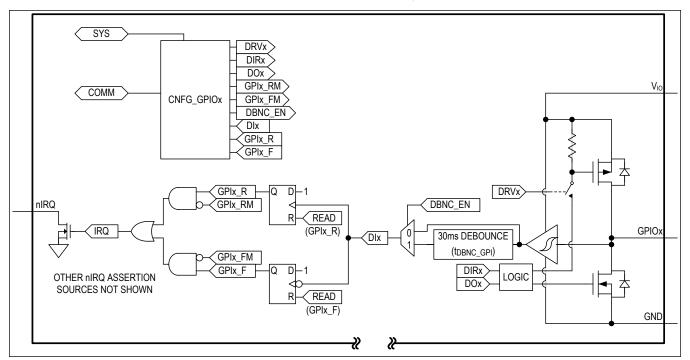


Figure 5. GPIOx Block Diagram

### **Alternate Mode**

Each GPIO in the MAX77654 can be configured to have a different function. Whether a particular GPIO is in GPIO mode or alternate mode can be checked by reading the CNFG\_GPIOx.ALT\_GPIOx bit. <u>Table 4</u> summarizes the alternate functions for each GPIO.

### **Table 4. GPIO Mode**

GPIOx	CNFG_GPIOx REGISTER				
	ALT_GPIOx = 0	ALT_GPIOx = 1			
GPIO0	Standard GPIO	Active-high output of SBB2s flexible power sequencer (FPS) slot.			
GPIO1	Standard GPIO	Active-high input, enable control for SBB2. SBB2 also still powers up and down according to the FPS.			
GPIO2	Standard GPIO	Active-high input, enable control for low-power mode.			

In particular, for GPIO1s alternate mode, SBB2 is enabled if GPIO1 = 1 OR the FPS enables SBB2. See the <u>Flexible Power Sequencer</u> section for more details. <u>Table 5</u> summarizes how to enable or disable SBB2 if GPIO1 is configured to be in its alternate mode.

The value of GPIO2 is OR'd with CNFG\_GLBL.SBIA\_LPM, so setting SBIA\_LPM = 1 or setting GPIO2 HIGH requests bias lower-power mode.

Table 5. Enabling/Disabling SBB2 while GPIO1 is in Alternate Mode

GPIO1	CNFG_SBB2.EN_SBB2[2:0]				
	0b000 - 0b011, 0b110, 0b111	0b100 to 0b0101			
GPIO1 = 0	SBB2 Enabled	SBB2 Disabled			
GPIO1 = 1	SBB2 Enabled	SBB2 Enabled			

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

### **On/Off Controller**

The on/off controller monitors multiple power-up (wake-up) and power-down (shutdown) conditions to enable or disable resources that are necessary for the system and its processor to move between its operating modes.

Many systems have one power management controller and one processor and rely on the on/off controller to be the master controller. In this case, the on/off controller receives wake-up events and enables some or all of the regulators to power-up a processor. That processor then manages the system. To conceptualize this master operation, see <u>Figure 6</u> and <u>Table 6</u>. A typical path through the on/off controller is:

- 1. Apply a battery and start in the shutdown state.
- 2. Press the system's on-key (nEN = LOW) and follow transitions 4 and 6 to the resource-on state. If any resources are on the FPS, transitions 7A and 7B are followed.
- 3. The device performs its desired functions in the resource-on state. when it is ready to turn off, a manual reset first drives the transition through transitions 8A and 8B to the standby state. Afterward, the device automatically follows transition 3 to the shutdown state.

Some systems have several power management blocks, a main processor, and subprocessors. These systems can use this device as a subpower management block for a peripheral portion of circuitry as long as there is an I<sup>2</sup>C port available from a higher level processor. To conceptualize this operation, see <u>Figure 6</u> and <u>Table 6</u>. A typical path through the on/ off controller used in this way is:

- 1. Apply a battery to the system and start in the shutdown state.
- 2. When the higher level processor wants to turn on this device's resources, it enables the main bias circuits through I<sup>2</sup>C (CNFG\_GLBL.SBIA\_EN = 1) to transition along path 6 to the resource-on state.
- 3. The higher level processor can now control this device's resources with I<sup>2</sup>C commands, e.g., turn on/off regulators.
- 4. When the higher level processor is ready to turn this device off, it turns off everything through I<sup>2</sup>C and then disables the main bias circuits through I<sup>2</sup>C (CNFG\_GLBL.SBIA\_EN = 0) to transition along path 5B to the standby state.

Note that in this style of operation, the CNFG\_GLBL\_SFT\_CTRL[1:0] bits should not be used to turn the device off. The CNFG\_GLBL\_SFT\_CTRL[1:0] bits establish directives to the on/off controller itself that does not make sense in this subpower management block operation. If the processor uses  $I^2C$  commands to enable the device's resources, the processor should also use  $I^2C$  commands to disable them.

### Top Level On/Off Controller

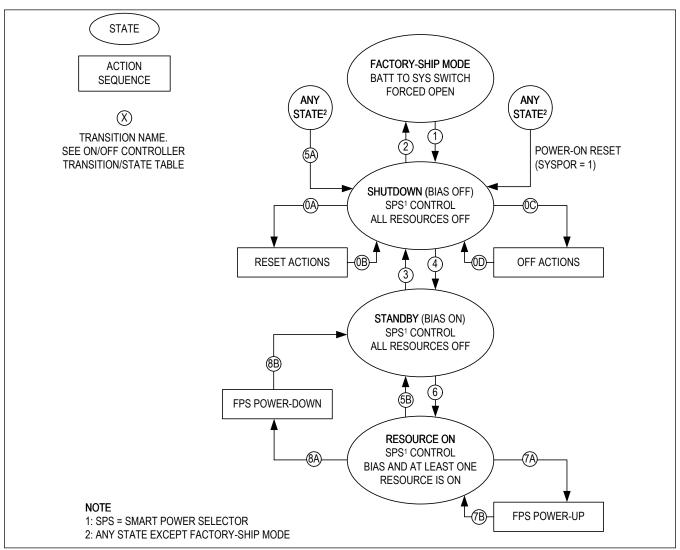


Figure 6. Top Level On/Off Controller State Diagram

## **On/Off Controller Transition Table**

## Table 6. On/Off Controller Transition/State

TRANSITION	CONDITION (TRANSITION HAPPENS WHEN)
0A	Software cold reset (CNFG_GLBL.SFT_CTRL[1:0] = 0b01) <b>OR</b> Watchdog timer expired and caused reset (ERCFLAG.WDT_RST = 1, CNFG_WDT.WDT_MODE = 1)
0B	Reset actions completed
0C	Software power-off (CNFG_GLBL.SFT_CTRL[1:0] = 0b10) <b>OR</b> Watchdog expired and caused power-off (ERCFLAG.WDT_OFF = 1, CNFG_WDT.WDT_MODE = 0) <b>OR</b> Chip over-temperature lockout ( $T_J > T_{OTLO}$ ) <b>OR</b> SYS undervoltage lockout ( $V_{SYS} < V_{SYSUVLO} + V_{SYSUVLO_HYS}$ ) <b>OR</b> SYS overvoltage lockout ( $V_{SYS} > V_{SYSOVLO}$ ) <b>OR</b> Manual reset occurred (ERCFLAG.MRST = 1)

**Table 6. On/Off Controller Transition/State (continued)** 

TRANSITION	CONDITION (TRANSITION HAPPENS WHEN)
0D	Off actions completed
1	CHGIN inserted and 120ms debounce valid (STAT_CHG_B.CHGIN_DTLS[1:0] = 0b11) <b>OR</b> nEN asserted and debounced ( $t_{FSM-DB}$ ) <b>OR</b> Power to the IC is removed ( $V_{BATT}$ < approx. 1.6V) and then reapplied ( $V_{BATT}$ > $V_{POR}$ )
2	Factory-ship mode requested (CNFG_GLBL.SFT_CTRL[1:0] = 0b11) <b>AND</b> nEN not asserted
3	NOT (Transition 4) Factory-ship mode requested (CNFG_GLBL.SFT_CTRL[1:0] = 0b11) OR Software cold reset (CNFG_GLBL.SFT_CTRL[1:0] = 0b01) OR Software power-off (CNFG_GLBL.SFT_CTRL[1:0] = 0b10) OR Watchdog timer expired OR Manual reset occurred (ERCFLAG.MRT = 1)
4	Main bias requested enabled through I <sup>2</sup> C (CNFG_GLBL.SBIA_EN = 1) <b>OR</b> Transition 6
5A	Chip over-temperature lockout (T <sub>J</sub> > T <sub>OTLO</sub> ) OR SYS undervoltage lockout (V <sub>SYS</sub> < V <sub>SYSUVLO</sub> + V <sub>SYSUVLO</sub> HYS) OR SYS overvoltage lockout (V <sub>SYS</sub> > V <sub>SYSOVLO</sub> )
5B	NOT (Transition 6) OR Factory-ship mode requested (CNFG_GLBL.SFT_CTRL[1:0] = 0b11) OR Software cold reset (CNFG_GLBL.SFT_CTRL[1:0] = 0b01) OR Software power-off (CNFG_GLBL.SFT_CTRL[1:0] = 0b10) OR Watchdog timer expired OR Manual reset occurred (ERCFLAG.MRT = 1)
6	AMUX is being used (CNFG_CHG_I.MUX_SEL[3:0] ≠ 0b0000) <b>OR</b> CHGIN inserted and debounced (STAT_CHG_B.CHGIN_DTLS[1:0] = 0b11) <b>OR</b> Any resources force enabled <b>OR</b> Internal wake-up flags are set (see the Internal Wake-Up Flags section)
7 <b>A</b>	FPS power-up sequence has not happened yet <b>AND</b> Resources are not forced off <b>AND</b> Internal wake-up flags are set (see the Internal Wake-Up Flags section)
7B	FPS power-up sequence done
8 <b>A</b>	FPS power-up sequence completed AND All resources are force disabled OR Factory-ship mode requested (CNFG_GLBL.SFT_CTRL[1:0] = 0b11) OR Software cold reset (CNFG_GLBL.SFT_CTRL[1:0] = 0b01) OR Software power-off (CNFG_GLBL.SFT_CTRL[1:0] = 0b10) OR Watchdog timer expired OR
	Manual reset occurred (ERCFLAG.MRT = 1)
8B	FPS power-down sequence finished

### Internal Wake-Up Flags

After transitioning to the shutdown state because of a reset, to allow the device to power-up again, internal wake-up flags are set to remember the wake-up request. In <u>Figure 6</u> and <u>Table 6</u>, these internal wake-up flags trigger transitions 6 and 7A. The internal wake-up flags are set when any of the following happen:

- nEN is debounced (see the <u>nEN Enable Input</u> section)
  - · For example, after a push-button is pressed or a slide-switch switched to HIGH.
- CHGIN is debounced and valid (STAT CHG B.CHGIN DTLS[1:0] = 0b11)
- Software cold reset command sent (CNFG GLBL.SFT CTRL[1:0] = 0b01)

### **Reset and Off Sequences**

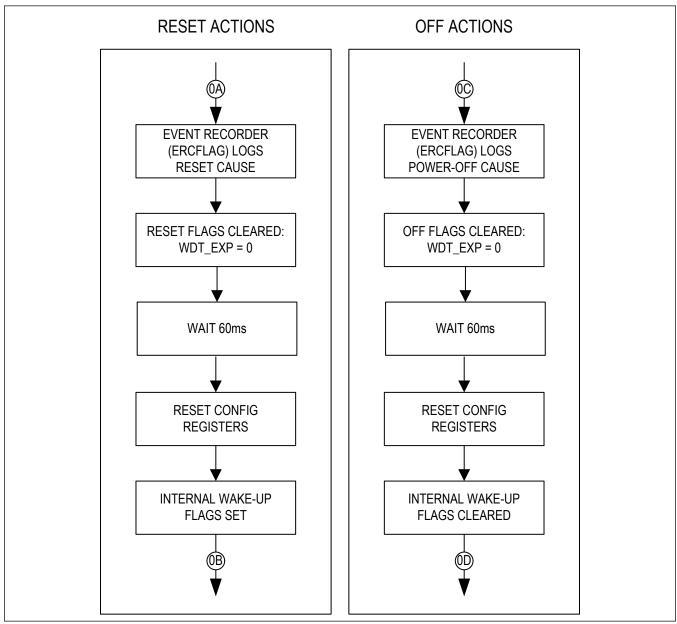


Figure 7. On/Off Controller Reset and Off-Action Sequences

## Power-Up/Down Sequence

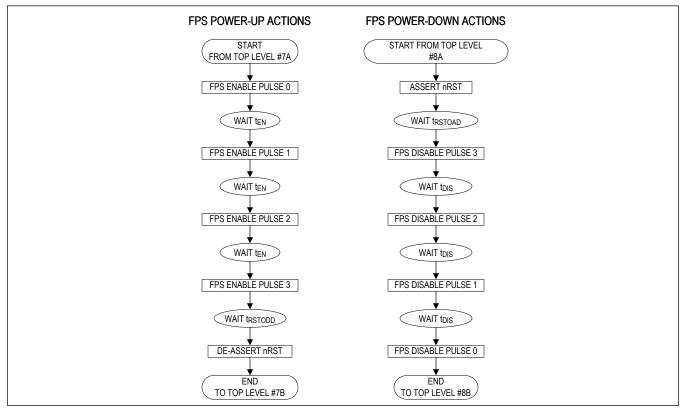


Figure 8. Power-Up/Down Sequence

### Flexible Power Sequencer (FPS)

The FPS allows resources to power up under hardware or software control. Additionally, each resource can power up independently or among a group of other regulators with adjustable power-up/down delays (sequencing). Figure 9 shows four resources powering up under the control of the flexible power sequencer.

The flexible sequencing structure consists of one master sequencing timer and four slave resources (SBB0, SBB1, SBB2 and LDO). When the FPS is enabled, a master timer generates four sequencing events for device power-up/down.

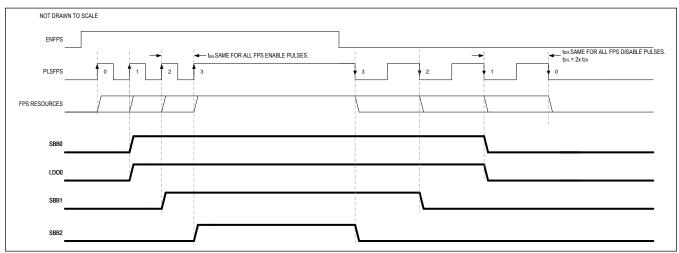


Figure 9. Flexible Power Sequencer Basic Timing Diagram

## Startup Timing Diagram Due to nEN

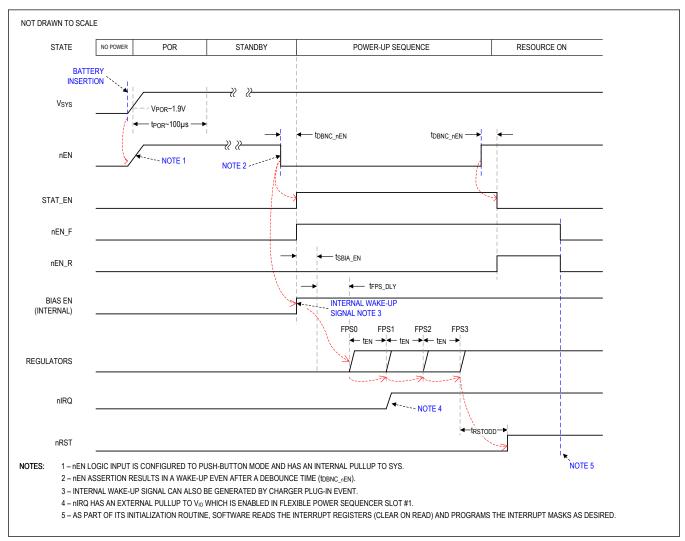


Figure 10. Startup Timing Diagram Due to nEN

## **Startup Timing Diagram Due to Charge Source Insertion**

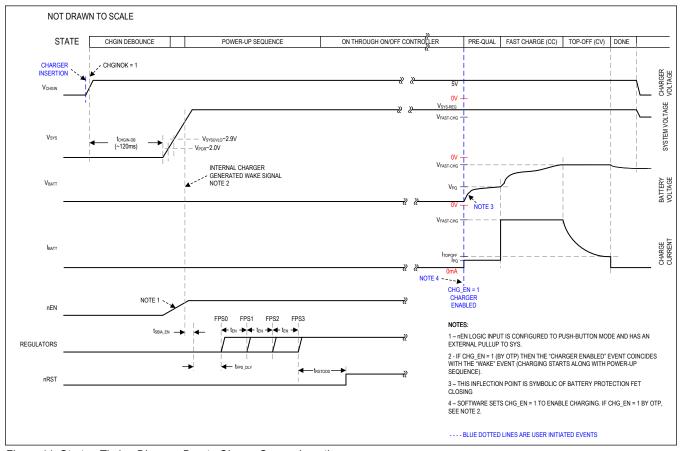


Figure 11. Startup Timing Diagram Due to Charge Source Insertion

#### Force Enabled/Disabled Channels

Force enable SIMO and LDO output channels by setting CNFG\_SBBx\_B.EN\_SBBx[2:0] (SIMO) or CNFG\_LDOx\_B.EN\_LDOx[2:0] (LDO) = 0x6. Depending on the OTP, output channels may already be force enabled by default. Output channels configured this way are independent of the flexible power sequence and start up as soon as SYS > UVLO rising. The main bias also automatically turns on.

Likewise, output channels can be force disabled by setting EN SBBx[2:0] or EN LDOx[2:0] = 0x4.

#### **Factory-Ship Mode State**

Factory-ship mode internally disconnects the battery (BATT) from the system (SYS). The battery does not power the system in this mode. Use this mode to preserve battery life if external circuits on SYS cause the battery to leak.

Write CNFG\_GLBL.SFT\_CTRL[1:0] = 0b11 using  $I^2C$  to enter factory-ship mode. The IC responds in two different ways depending on the state of the charger input (CHGIN):

- If CHGIN is valid (STAT\_CHG\_B.CHGIN\_DTLS[1:0] = 0b11) while CNFG\_GLBL.SFT\_CTRL[1:0] = 0b11, then the IC enters factory-ship mode (internally disconnects BATT from SYS) but SYS is still powered from CHGIN (regulating to V<sub>SYS-REG</sub>). SYS decays to 0V when CHGIN is disconnected.
- If CHGIN is invalid (STAT\_CHG\_B.CHG\_DTLS[1:0] ≠ 0b11) while CNFG\_GLBL.SFT\_CTRL[1:0] = 0b11, then the IC enters factory-ship mode and SYS decays to 0V.

Factory-ship mode causes many configuration registers to reset (SYSRST). See the <u>Register Map</u> section for details. I<sup>2</sup>C reads and writes cannot happen in factory-ship mode.

Factory-ship mode exits only after SYS decays below approximately 1.8V. Once this condition is met, there are two ways to exit factory-ship mode:

- Apply a valid DC source at CHGIN for t<sub>CHGIN-DB</sub> (120ms typical). Factory-ship mode is unlatched (exited) when the charger input becomes valid from a previously invalid state (STAT\_CHG\_B.CHGIN\_DTLS[1:0] = 0b00 → 0b11).
- Assert nEN for t<sub>FSM-EXDB</sub> (250ms typical) + t<sub>DBNC nEN</sub>.

Furthermore, this state is unlatched if power is removed from the IC (BATT voltage falls below approximately 1.8V). In all exit cases, the smart power selector controls the interaction between BATT and SYS until factory-ship mode is entered again (see the <u>Smart Power Selector</u> section).

## **Debounced Inputs (nEN, GPI, CHGIN)**

nEN, CHGIN, and GPIO (when operating as an input), are debounced on both rising and falling edges to reject undesired transitions. The input must be at a stable logic level for the entire debounce period for the output to change its logic state. Figure 12 shows an example timing diagram for the nEN debounce.

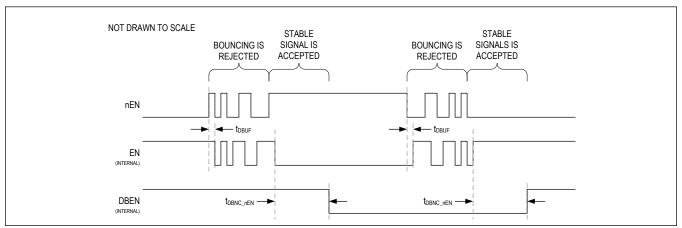


Figure 12. Debounced Inputs

### Watchdog Timer (WDT)

The IC features a watchdog timer function for operational safety. If this timer expires without being cleared, the on/off controller causes the IC to enter the shutdown state and resets configuration registers. See the <u>On/Off Controller</u> and <u>On/Off Controller Transition Table</u> sections (transitions 0A and 0C) for more details.

Write CNFG\_WDT.WDT\_EN = 1 through I $^2$ C to enable the timer. The watchdog timer period ( $t_{WD}$ ) is configurable from 16 to 128 seconds in 4 steps with CNFG\_WDT.WDT\_PER[1:0]. The default timer period is 128 seconds. While the watchdog timer is enabled, the CNFG\_WDT.WDT\_CLR bit must be set through I $^2$ C periodically (within  $t_{WD}$ ) to reset the timer and prevent shutdown. See the *Register Map* and Figure 13 for additional details.

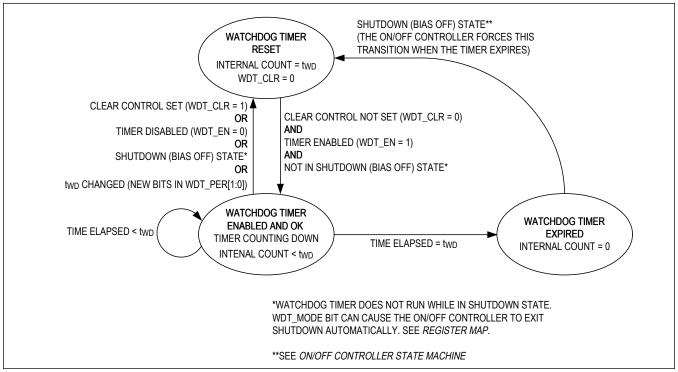


Figure 13. Watchdog Timer State Machine

The timer can be factory-programmed to be enabled by default, disabled by default, or locked from accidental disable. The CNFG\_WDT.WDT\_LOCK bit is read-only and must be configured at the factory. See <u>Table 7</u> for a full description.

**Table 7. Watchdog Timer Factory-Programmed Safety Options** 

WDT_LOCK	WDT_EN	FUNCTION		
0	0	Watchdog timer is disabled by default. Timer can be enabled or disabled by I <sup>2</sup> C writes.		
0	1	Watchdog timer is enabled by default. Timer can be enabled or disabled by I <sup>2</sup> C writes.		
1	0	Watchdog timer is disabled by default. Timer can be enabled by an I <sup>2</sup> C write, but only a SYSRST can reset the CNFG_WDT.WDT_EN value back to 0. Timer can not be disabled by direct I <sup>2</sup> C writes to CNFG_WDT.WDT_EN (write from 1 $\rightarrow$ 0 is ignored, write from 0 $\rightarrow$ 1 is accepted).		
1	1	Watchdog timer is enabled by default. Nothing can disable the timer.		

## **Detailed Description—Smart Power Selector Charger**

The linear Li+ charger implements power path with Maxim's Smart Power Selector. This allows separate input current limit and battery charge current settings. Batteries charge faster under the supervision of the Smart Power Selector because charge current is independently regulated and not shared with variable system loads. See the <u>Smart Power Selector</u> section for more information.

The programmable constant-current charge rate (7.5mA to 300mA) supports a wide range of battery capacities. The programmable input current limit (95mA to 475mA) supports a range of charge sources, including USB. The charger's programmable battery regulation voltage range (3.6V to 4.6V) supports a wide variety of cell chemistries. Small battery capacities are supported; the charger accurately terminates charging by detecting battery currents as low as 0.375mA.

Additionally, the robust charger input withstands overvoltages up to 28V. To enhance charger safety, an NTC thermistor provides temperature monitoring in accordance with the JEITA recommendations. See the <u>Adjustable Thermistor Temperature Monitors</u> section for more information.

## **Charger Symbol Reference Guide**

<u>Table 8</u> lists the names and functions of charger-specific signals and if they can be programmed through I<sup>2</sup>C serial communication. See the <u>Electrical Characteristics</u> and <u>Register Map</u> for more information.

## **Table 8. Charger Quick Symbol Reference Guide**

SYMBOL	NAME	I <sup>2</sup> C PROGRAMMABLE?
V <sub>CHGIN_OVP</sub>	CHGIN overvoltage threshold	No
V <sub>CHGIN_UVLO</sub>	CHGIN undervoltage-lockout threshold	No
V <sub>CHGIN-MIN</sub>	Minimum CHGIN voltage regulation setpoint	Yes, through CNFG_CHG_B.VCHGIN_MIN[2:0]
I <sub>CHGIN-LIM</sub>	CHGIN input current limit	Yes, through CNFG_CHG_B.ICHGIN_LIM[2:0]
V <sub>SYS-REG</sub>	SYS voltage regulation target	Yes, through CNFG_CHG_D.VSYS_REG[4:0]
V <sub>SYS-MIN</sub>	Minimum SYS voltage regulation setpoint	No, tracks V <sub>SYS-REG</sub>
V <sub>FAST-CHG</sub>	Fast-charge constant-voltage level	Yes, through CNFG_CHG_G.CHG_CV[5:0]
I <sub>FAST-CHG</sub>	Fast-charge constant-current level	Yes, through CNFG_CHG_G_E.CHG_CC[5:0]
I <sub>PQ</sub>	Prequalification current level	Yes, through CNFG_CHG_B.I_PQ
$V_{PQ}$	Prequalification voltage threshold	Yes, through CNFG_CHG_C.CHG_PQ[2:0]
I <sub>TERM</sub>	Termination current level	Yes, through CNFG_CHG_C.I_TERM[1:0]
T <sub>J-REG</sub>	Die temperature regulation setpoint	Yes, through CNFG_CHG_D.TJ_REG[2:0]
t <sub>PQ</sub>	Prequalification safety timer	No
t <sub>FC</sub>	Fast-charge safety timer	Yes, through CNFG_CHG_E.T_FAST_CHG[1:0]
t <sub>TO</sub>	Top-off timer	Yes, through CNFG_CHG_C.T_TOPOFF[2:0]

Figure 14 indicates the high-level functions of each control circuit within the linear charger.

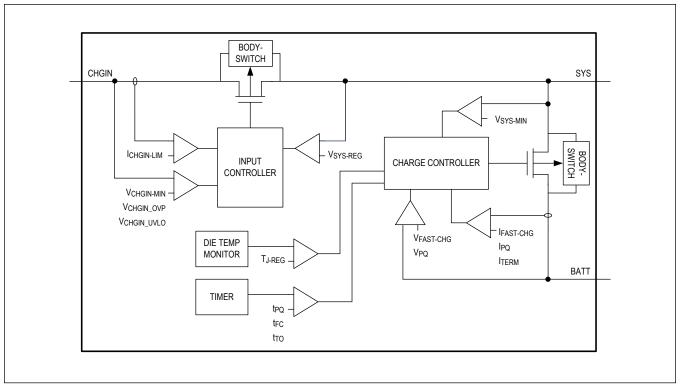


Figure 14. Charger Simplified Control Loops

#### **Smart Power Selector**

The Smart Power Selector seamlessly distributes power from the input (CHGIN) to the battery (BATT) and the system (SYS). The Smart Power Selector basic functions are:

- When the system load current is less than the input current limit, the battery is charged with residual power from the input.
- When a valid input source is connected, the system regulates to V<sub>SYS-REG</sub> to power system loads regardless of the battery's voltage (instant on).
- When the system load current exceeds the input current limit, the battery provides additional current to the system (supplement mode).
- When the battery is finished charging and an input source is present to power the system, the battery remains disconnected from the system.
- When the battery is connected and there is no input power, the system is powered from the battery.

#### **Input Current Limiter**

The input current limiter limits CHGIN current to not exceed I<sub>CHGIN-LIM</sub> (programmed by CNFG\_CHG\_B.ICHGIN\_LIM[2:0]). A maskable interrupt (INT\_CHG.CHGIN\_CTRL\_I) signals when the input current limit engages. The STAT\_CHG\_A.ICHGIN\_LIM\_STAT bit reflects the state of the current limiter loop.

The default value of  $I_{CHGIN-LIM}$  is factory-programmable to either 95mA or 475mA. The decoding of the CNFG\_CHG\_B.ICHGIN\_LIM[2:0] bitfield changes depending on the factory-programmed default value (see <u>Table 9</u>). The reset value of this bitfield is always 0b000 regardless of factory option.

**Table 9. Input Current Limit Factory Options** 

ICHGIN_LIM[2:0]	95mA Factory-Default	475mA Factory-Default
0b000	95mA	475mA
0b001	190mA	380mA
0b010	285mA	285mA
0b011	380mA	190mA
0b100 to 0b111	475mA	95mA

CHGIN is capable of withstanding a maximum of 28V with respect to ground. CHGIN suspends power delivery to the system and battery when  $V_{CHGIN}$  exceeds  $V_{CHGIN}$  OVP (7.5V, typ). The input circuit also suspends when  $V_{CHGIN}$  falls below  $V_{CHGIN}$  minus 500mV of hysteresis (3.5V, typ). While in OVP or UVLO, the charger remains off and the battery provides power to the system.

Power transfer to SYS is delayed by a 120ms debounce timer ( $t_{CHGIN-DB}$ ) after a valid DC source is connected to CHGIN. SYS does not begin regulating to  $V_{SYS-REG}$  until after the timer expires.

The STAT\_CHG\_B.CHGIN\_DTLS[1:0] bitfield continuously indicates the state of CHGINs voltage quality. A maskable interrupt (INT\_CHG.CHGIN\_I) asserts when STAT\_CHG\_B.CHGIN\_DTLS[1:0] changes.

### **Minimum Input Voltage Regulation**

In the event of a poor-quality charge source, the minimum input voltage regulation loop works to reduce input current if  $V_{CHGIN}$  falls below  $V_{CHGIN-MIN}$  (programmed by CNFG\_CHG\_B.VCHGIN\_MIN[2:0]). This is important because many commonly used charge adapters feature foldback protection mechanisms where the adapter completely shuts off if its output drops too low. The minimum input voltage regulation loop also prevents  $V_{CHGIN}$  from dropping below  $V_{CHGIN}$  UVLO if the cable between the charge source and the charger's input is long or highly resistive.

The input voltage regulation loop improves performance with current limited adapters. If the charger's input current limit is programmed above the current limit of the given adapter, the input voltage loop allows the input to regulate at the current limit of the adapter. The input voltage regulation loop also allows the charger to perform well with adapters that have poor transient load response times.

A maskable interrupt (INT\_CHG.CHGIN\_CTRL\_I) signals when the minimum input voltage regulation loop engages. The state of this loop is reflected by STAT\_CHG\_A.VCHGIN\_MIN\_STAT.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

## **Minimum System Voltage Regulation**

The minimum system voltage regulation loop ensures that the system rail remains close to the programmed SYS regulation voltage ( $V_{SYS-REG}$ ) regardless of system loading. The loop engages when the combined battery charge current and system load current causes the CHGIN input to current limit at  $I_{CHGIN-LIM}$ . When this happens, the minimum system voltage loop reduces charge current in an attempt to keep the input out of current limit, thereby keeping the system voltage above  $V_{SYS-MIN}$  ( $V_{SYS-REG}$  - 100mV, typ). If this loop reduces battery current to 0 and the system is in need of more current than the input can provide, then the Smart Power Selector overrides the minimum system voltage regulation loop and allows SYS to collapse to BATT for the battery to provide supplement current to the system. The Smart Power Selector automatically reenables the minimum system voltage loop when the supplement event has ended.

A maskable interrupt (INT\_CHG.SYS\_CTRL\_I) asserts to signal a change in STAT\_CHG\_A.VSYS\_MIN\_STAT. This status bit asserts when the minimum system voltage regulation loop is active.

#### **Die Temperature Regulation**

If the die temperature exceeds  $T_{J-REG}$  (programmed by CNFG\_CHG\_D.TJ\_REG[2:0]) the charger attempts to limit the temperature increase by reducing the battery charge current. The STAT\_CHG\_A.TJ\_REG\_STAT bit asserts whenever charge current is reduced due to this loop. The charger's current sourcing capability to SYS remains unaffected when STAT\_CHG\_A.TJ\_REG\_STAT is high. A maskable interrupt (INT\_CHG.TJ\_REG\_I) asserts to signal a change in STAT\_CHG\_A.TJ\_REG\_STAT. Use the INT\_CHG.TJ\_REG\_I interrupt to signal the system processor to reduce loads on SYS to reduce total system temperature.

### **Charger State Machine**

The battery charger follows a strict state-to-state progression to ensure that a battery is charged safely. The status bitfield STAT\_CHG\_B.CHG\_DTLS[3:0] reflects the charger's current operational state. A maskable interrupt (INT\_CHG.CHG\_I) is available to signal a change in STAT\_CHG\_B.CHG\_DTLS[3:0].

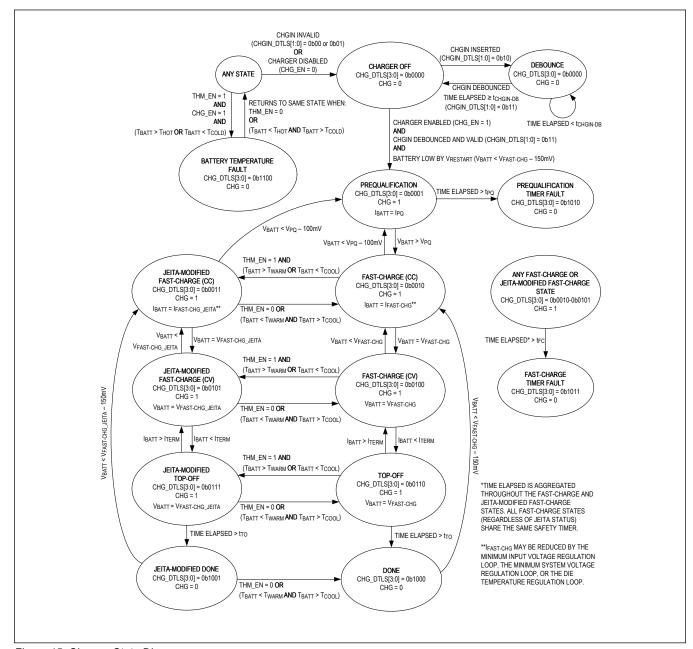


Figure 15. Charger State Diagram

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## **Charger-Off State**

The charger is off when CHGIN is invalid, the charger is disabled, or the battery is fresh.

CHGIN is invalid when the CHGIN input is invalid ( $V_{CHGIN} < V_{CHGIN\_UVLO}$  or  $V_{CHGIN\_OVP}$ ). While CHGIN is invalid, the battery is connected to the system. CHGIN voltage quality can be separately monitored by the STAT\_CHG\_B.CHGIN\_DTLS[1:0] status bitfield. See the <u>Register Map</u> section for details.

The charger is disabled when the charger enable bit is 0 (CNFG\_CHG\_B.CHG\_EN = 0). The battery is connected or disconnected to the system depending on the validity of  $V_{CHGIN}$  while CNFG\_CHG\_B.CHG\_EN = 0. See the <u>Smart Power Selector</u> section.

The battery is fresh when CHGIN is valid and the charger is enabled (CNFG\_CHG\_B.B.CHG\_EN = 1) and the battery is not low by V<sub>RESTART</sub> (V<sub>BATT</sub> > V<sub>FAST-CHG</sub> - V<sub>RESTART</sub>). The battery is disconnected from the system and not charged while the battery is fresh. The charger state machine exits this state and begins charging when the battery becomes low by V<sub>RESTART</sub> (150mV, typ). This condition is functionally similar to done state. See the <u>Done State</u> section.

### **Prequalification State**

The prequalification state is intended to assess a low-voltage battery's health by charging at a reduced rate. If the battery voltage is less than the  $V_{PQ}$  threshold, the charger is automatically in prequalification. If the cell voltage does not exceed  $V_{PQ}$  in 30 minutes ( $t_{PQ}$ ), the charger faults. The prequalification charge rate is a percentage of  $I_{FAST-CHG}$  and is programmable with  $CNFG\_CHG\_B.I\_PQ$ . The prequalification voltage threshold ( $V_{PQ}$ ) is programmable through  $CNFG\_CHG\_PQ[2:0]$ .

### **Fast-Charge States**

When the battery voltage is above  $V_{PQ}$ , the charger transitions to the fast-charge (CC) state. In this state, the charger delivers a constant current ( $I_{FAST-CHG}$ ) to the cell. The constant current level is programmable from 7.5mA to 300mA by CNFG CHG E.CHG CC[5:0].

When the cell voltage reaches  $V_{FAST-CHG}$ , the charger state machine transitions to fast-charge (CV).  $V_{FAST-CHG}$  is programmable with CNFG\_CHG\_CV[5:0] from 3.6V to 4.6V. The charger holds the battery's voltage constant at  $V_{FAST-CHG}$  while in the fast-charge (CV) state. As the battery approaches full, the current accepted by the battery reduces. When the charger detects that battery charge current has fallen below  $I_{TERM}$ , the charger state machine enters the top-off state.

A fast-charge safety timer starts when the state machine enters fast-charge (CC) or JEITA-modified fast-charge (CC) from a non-fast-charge state. The timer continues to run through all fast-charge states regardless of JEITA status. The timer length (t<sub>FC</sub>) is programmable from 3 hours to 7 hours in 2 hour increments with CNFG\_CHG\_E.T\_FAST\_CHG[1:0]. If it is desired to charge without a safety timer, program CNFG\_CHG\_E.T\_FAST\_CHG[1:0] with 0b00 to disable the feature. If the timer expires before the fast-charge states are exited, the charger faults. See the <u>Fast-Charge Timer Fault State</u> section for more information.

If the charge current falls below 20% of the programmed value during fast-charge (CC), the safety timer pauses. The timer also pauses for the duration of supplement mode events. The STAT\_CHG\_B.TIME\_SUS bit indicates the status of the fast-charge safety timer. See the *Register Map* section for more details.

### **Top-Off State**

Top-off state is entered when the battery charge current falls below  $I_{TERM}$  during the fast-charge (CV) state.  $I_{TERM}$  is a percentage of  $I_{FAST-CHG}$  and is programmable through CNFG\_CHG\_C.I\_TERM[1:0]. While in the top-off state, the battery charger continues to hold the battery's voltage at  $V_{FAST-CHG}$ . A programmable top-off timer starts when the charger state machine enters the top-off state. When the timer expires, the charger enters the done state. The top-off timer value ( $t_{TO}$ ) is programmable from 0 minutes to 35 minutes with CNFG\_CHG\_C.T\_TOPOFF[2:0]. If it is desired to stop charging as soon as battery current falls below  $I_{TERM}$ , program  $t_{TO}$  to 0 minutes.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

#### **Done State**

The charger enters the done state when the top-off timer expires. The battery remains disconnected from the system during done. The charger restarts if the battery voltage falls more than  $V_{RESTART}$  (150mV, typ) below the programmed  $V_{FAST-CHG}$  value.

#### **Pregualification Timer Fault State**

The prequalification timer fault state is entered when the battery's voltage fails to rise above  $V_{PQ}$  in  $t_{TO}$  (30 minutes, typ) from when the prequalification state was first entered. If a battery is too deeply discharged, damaged, or internally shorted, the prequalification timer fault state can occur. During the timer fault state, the charger stops delivering current to the battery and the battery remains disconnected from the system. To exit the prequalification timer fault state, toggle the charger enable (CNFG CHG B.CHG EN) bit or unplug and replug the external voltage source connected to CHGIN.

#### **Fast-Charge Timer Fault State**

The charger enters the fast-charge timer fault state if the fast-charge safety timer expires. While in this state, the charger stops delivering current to the battery and the battery remains disconnected from the system. To exit the fast-charge timer fault state, toggle the charger enable bit (CNFG\_CHG\_B.CHG\_EN) or unplug and replug the external voltage source connected to CHGIN.

#### **Battery Temperature Fault State**

If the thermistor monitoring circuit reports that the battery is either too hot or too cold to charge (as programmed by CNFG\_CHG\_A.THM\_HOT[1:0] and CNFG\_CHG\_A.THM\_COLD[1:0]), the state machine enters the battery temperature fault state. While in this state, the charger stops delivering current to the battery and the battery remains disconnected from the system. This state can only be entered if the thermistor is enabled (CNFG\_CHG\_F.THM\_EN = 1). Battery temperature fault state has priority over any other fault state, and can be exited when the thermistor is disabled (CNFG\_CHG\_F.THM\_EN = 0) or when the battery returns to an acceptable temperature. When this fault state is exited, the state machine returns to the last state it was in before battery temperature fault state was entered.

All active charger timers (fast-charge safety timer, prequalification timer, or top-off timer) are paused in this state. When the charger exits this state, the prequalification timer resumes while the fast-charge safety and top-off timers reset.

The STAT\_CHG\_A.THM\_DTLS[2:0] bitfield reports battery temperature status. See the <u>Adjustable Thermistor</u> Temperature Monitors and the Register Map sections for more information.

#### **JEITA-Modified States**

If the thermistor is enabled (CNFG\_CHG\_F.THM\_EN = 1), then the charger state machine is allowed to enter the JEITA-modified states. These states are entered if the charger's temperature monitors indicate that the battery temperature is either warm (greater than  $T_{WARM}$ ) or cool (lesser than  $T_{COOL}$ ). See the <u>Adjustable Thermistor Temperature Monitors</u> section for more information about setting the temperature thresholds.

The charger's current and voltage parameters change from  $I_{FAST-CHG}$  and  $V_{FAST-CHG}$  to  $I_{FAST-CHG}$  and  $V_{FAST-CHG}$  while in the JEITA-modified states. The JEITA modified parameters can be independently set to lower voltage and current values so that the battery can charge safely over a wide range of ambient temperatures. If the battery temperature returns to normal, or the thermistor is disabled (CNFG\_CHG\_.THM\_EN = 0), the charger exits the JEITA-modified states.

### **Typical Charge Profile**

A typical battery charge profile (and state progression) is illustrated in Figure 16.

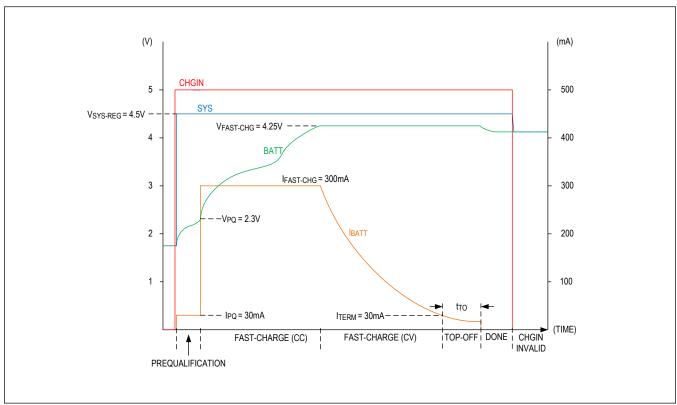


Figure 16. Example Battery Charge Profile

### **Charger Applications Information**

#### **Configuring a Valid System Voltage**

The Smart Power Selector begins to regulate SYS to  $V_{SYS-REG}$  when CHGIN is connected to a valid source. To ensure the charger's accuracy specified in the <u>Electrical Characteristics</u> table, the system voltage must always be programmed at least 200mV above the charger's constant-voltage level ( $V_{FAST-CHG}$ ). If this condition is not met, then the charger's internal configuration logic forces  $V_{FAST-CHG}$  to reduce to satisfy the 200mV requirement. If this happens, the charger asserts the INT\_CHG.SYS\_CNFG\_I interrupt to alert the user that a configuration error has been made and that the bits in CNFG\_CHG\_C.CHG\_CV[5:0] have changed to reduce  $V_{FAST-CHG}$ .

#### **CHGIN/SYS/BATT Capacitor Selection**

Bypass CHGIN to GND with a  $4.7\mu F$  ceramic capacitor to minimize inductive kick caused by long cables between the DC charge source and the product/IC. Larger values increase decoupling for the linear charger, but increase inrush current from the DC charge source when the product/IC is first connected to a source through a cable/plug. If the DC charging source is an upstream USB device, limit the maximum CHGIN input capacitance based on the appropriate USB specification (typically no more than  $10\mu F$ ).

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

Bypass SYS to GND with a  $22\mu\text{F}$  ceramic capacitor. This capacitor ensures stability of SYS while it is regulated from CHGIN. Larger values of SYS capacitance increase decoupling for all SYS loads. The effective value of the SYS capacitor must be greater than  $4\mu\text{F}$  and no more than  $100\mu\text{F}$ .

Bypass BATT to GND with a  $4.7\mu$ F ceramic capacitor. This capacitor stabilizes the BATT voltage regulation loop. The effective value of the BATT capacitor must be greater than  $1\mu$ F.

Ceramic capacitors with X5R or X7R dielectric are highly recommended due to their small size, low ESR, and small temperature coefficients. All ceramic capacitors derate with DC bias voltage (effective capacitance goes down as DC bias goes up). Generally, small case size capacitors derate heavily compared to larger case sizes (0603 case size performs better than 0402). Consider the effective capacitance value carefully by consulting the manufacturer's data sheet.

## **Detailed Description—Adjustable Thermistor Temperature Monitors**

The optional use of a negative temperature coefficient (NTC) thermistor (thermally coupled to the battery) enables the charger to operate safely over the JEITA temperature range. When the thermistor is enabled (CNFG\_CHG\_F.THM\_EN = 1), the charger continuously monitors the voltage at the THM pin in order to sense the temperature of the battery being charged.

See Figure 17 for a visual example of the following:

- If the battery temperature is higher than T<sub>COOL</sub> and lower than T<sub>WARM</sub>, the battery charges normally with the normal
  values for V<sub>FAST-CHG</sub> and I<sub>FAST-CHG</sub>. The charger state machine does not enter JEITA-modified states while the
  battery temperature is normal.
- If the battery temperature is either above T<sub>WARM</sub> but below T<sub>HOT</sub>, or, below T<sub>COOL</sub> but above T<sub>COLD</sub>, the battery charges with the JEITA-modified voltage and current values. These modified values, V<sub>FAST-CHG\_JEITA</sub> and I<sub>FAST-CHG\_JEITA</sub>, are programmable through CNFG\_CHG\_H.CHG\_CV\_JEITA[5:0] and CNFG\_CHG\_F.CHG\_CC\_JEITA[5:0], respectively. These values are independently programmable from the unmodified V<sub>FAST-CHG</sub> and I<sub>FAST-CHG</sub> values and can even be programmed to the same values if an automatic response to a warm or cool battery is not desired. The charger state machine enters JEITA-modified states while the battery temperature is outside of normal.
- If the battery temperature is either above T<sub>HOT</sub> or below T<sub>COLD</sub>, the charger follows the JEITA recommendation and
  pauses charging. The charger state machine enters battery temperature fault state while charging is paused due to
  extreme high or low temperatures.

The battery's temperature status is reflected by the STAT\_CHG\_A.THM\_DTLS[2:0] status bitfield. A maskable interrupt (INT\_CHG.THM\_I) signals a change in status. See the <u>Register Map</u> for more information. To completely disable the charger's automatic response to battery temperature, disable the feature by programming CNFG CHG F.THM EN = 0.

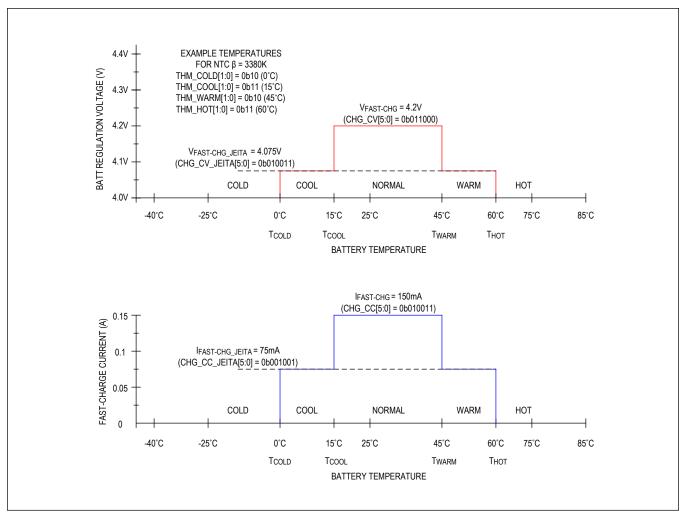


Figure 17. Safe-Charging Profile Example

The voltage thresholds corresponding to the JEITA temperature thresholds are independently programmable through CNFG\_CHG\_A.THM\_HOT[1:0], CNFG\_CHG\_A.THM\_WARM[1:0], CNFG\_CHG\_A.THM\_COOL[1:0], and CNFG\_CHG\_A.THM\_COLD[1:0]. Each threshold can be programmed to one of four voltage options spanning 15°C for an NTC beta of 3380K. See the *Configurable Temperature Thresholds* section and the *Register* for more information.

#### **Thermistor Bias**

An external ADC can optionally perform conversions on the THM and TBIAS pins to measure the battery's temperature. An on-chip analog multiplexer is used to route these nodes to the AMUX pin. The operation of the analog multiplexer does not interfere with the charger's temperature monitoring comparators or the charger's automatic JEITA response. See the <u>Analog Multiplexer</u> section for more information.

The NTC thermistor's bias source (TBIAS) follows the simple operation outlined below:

- If CHGIN is valid and the thermistor is enabled (CNFG\_CHG\_F.THM\_EN = 1), the thermistor is biased, so the charger can automatically respond to battery temperature changes.
- If the analog multiplexer connects THM or TBIAS to AMUX, then the thermistor is biased, so an external ADC can perform a meaningful temperature conversion.

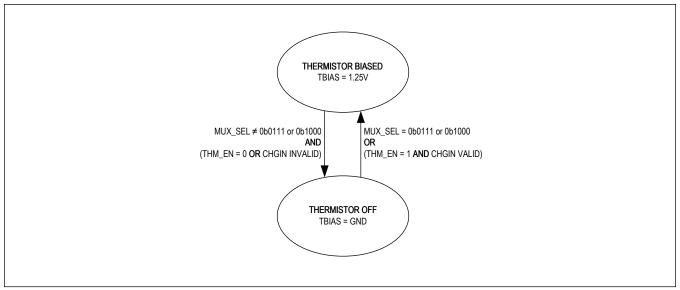


Figure 18. Thermistor Bias State Diagram

The AMUX pin is a buffered output. The operation of the analog multiplexer and external ADC does not collide with the function of the on-chip temperature monitors. Both functions may be used simultaneously with no ill effect.

### **Configurable Temperature Thresholds**

Temperature thresholds for different NTC thermistor beta values are listed in <u>Table 10</u>. The largest possible programmable temperature range can be realized by using an NTC with a beta of 3380K. Using a larger beta compresses the temperature range. The trip voltage thresholds are programmable with the CNFG\_CHG\_A.THM\_HOT[1:0], CNFG\_CHG\_A.THM\_WARM[1:0], CNFG\_CHG\_A.THM\_COOL[1:0], and CNFG\_CHG\_A.THM\_COLD[1:0] bitfields. All possible programmable trip voltages are listed in <u>Table 10</u>.

Table 10. Trip Temperatures vs. Trip Voltages for Different NTC β

TRIR VOLTACE (V)	TRIP TEMPERATURES (°C)					
TRIP VOLTAGE (V)	3380K	3435K	3940K	4050K	4100K	4250K
1.024	-10.0	-9.5	-5.6	-4.8	-4.5	-3.5
0.976	-5.0	-4.6	-1.1	-0.5	-0.2	0.6
0.923	0.0	0.3	3.3	3.8	4.1	4.8
0.867	5.0	5.3	7.7	8.1	8.3	8.9
0.807	10.0	10.2	12.0	12.4	12.5	12.9
0.747	15.0	15.1	16.4	16.6	16.7	17.0
0.511	35.0	34.8	33.5	33.3	33.2	32.9
0.459	40.0	39.8	37.8	37.4	37.3	36.8
0.411	45.0	44.7	42.0	41.5	41.3	40.7
0.367	50.0	49.6	46.2	45.6	45.3	44.6
0.327	55.0	54.5	50.4	49.7	49.3	48.4
0.291	60.0	59.4	54.6	53.7	53.3	52.2

These are theoretical values computed by a formula. Refer to the particular NTC's data sheet for more accurate measured data. In all cases, select the value of  $R_{BIAS}$  to be equal to the NTC's effective resistance at +25°C.

## **Applications Information**

#### Using Different Thermistor β

If an NTC with a beta larger than 3380K is used and the resulting available programmable temperature range is undesirably small, then two adjusting resistors can be used to expand the temperature range.  $R_S$  and  $R_P$  can be optionally added to the NTC thermistor circuit shown in <u>Figure 19</u> to expand the range of programmable temperature thresholds.

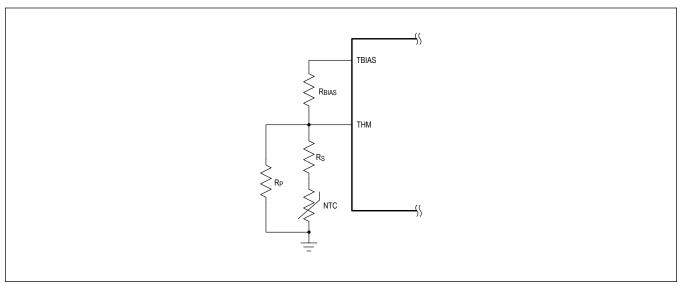


Figure 19. Thermistor Circuit with Adjusting Series and Parallel Resistors

Select values for R<sub>S</sub> and R<sub>P</sub> based on the information shown in Table 11.

Table 11. Example R<sub>S</sub> and R<sub>P</sub> Correcting Values for NTC β Above 3380K

PARAMETER	UNIT	TARGET NTC CASE	CAS	SE 1	CA	SE 2	CA	SE 3
NTC thermistor beta	K	3380	39	40	40	)50	42	250
25°C NTC resistance		10	1	0	2	17	1	00
R <sub>BIAS</sub>		10	1	0	2	17	1	00
Adjusting parallel resistor, R <sub>P</sub>		open	open	200	open	680	open	1300
Adjusting series resistor, R <sub>S</sub>	kΩ	short	short	0.62	short	3.3	short	9.1
R <sub>NTC</sub> at 1.024V <sub>COLD</sub> threshold	K22	45.24	45.24	578.5	212.6	306.1	452.4	684.8
R <sub>NTC</sub> at 0.867V <sub>COOL</sub> threshold		22.61	22.61	248.8	106.3	122.7	226.1	264.7
R <sub>NTC</sub> at 0.459V <sub>WARM</sub> threshold		5.81	5.81	5.36	27.3	25.1	58.1	51.7
R <sub>NTC</sub> at 0.291V <sub>HOT</sub> threshold		3.04	3.04	2.46	14.3	112.7	30.4	22.0
T <sub>ACTUAL</sub> at V <sub>COLD</sub> (-10°C expected)		-10.03	-5.56	-9.96	-4.82	-11.14	-3.55	-10.46
T <sub>ACTUAL</sub> at V <sub>COOL</sub> (5°C expected)	°C	4.98	7.66	5.76	8.10	5.33	8.86	5.94
T <sub>ACTUAL</sub> at V <sub>WARM</sub> (40°C expected)		40.02	37.79	39.76	37.43	39.40	36.82	39.48
T <sub>ACTUAL</sub> at V <sub>HOT</sub> (60°C expected)		60.04	54.56	60.37	53.68	60.02	52.21	60.4

#### **NTC Thermistor Selection**

Popular NTC thermistor options are listed in Table 12.

**Table 12. NTC Thermistors** 

MANUFACTURER	PART	β-CONSTANT (25°C/50°C)	R (Ω) AT 25°C	CASE SIZE
TDK	NTCG063JF223HTBX	3380K	22k	0201
Murata	NCP03XH103F05RL	3380K	10k	0201
Murata	NCP15XH103F03RC	3380K	10k	0402
TDK	NTCG103JX103DT1	3380K	10k	0402
Cantherm	CMFX3435103JNT	3435K	10k	0402
Murata	NCP15XV103J03RC	3900K	10k	0402
Panasonic	ERT-JZEP473J	4050K	47k	0201
Panasonic	ABNTC-0402-473J-4100F-T	4100K	47k	0402
Murata	NCP15WF104F03RC	4250K	100k	0402

## **Detailed Description—Analog Multiplexer**

An external ADC can be used to measure the chip's various signals for general functionality or on-the-fly power monitoring. The CNFG\_CHG\_I.MUX\_SEL[3:0] bitfield controls the internal analog multiplexer responsible for connecting the proper channel to the AMUX pin. Each measurable signal is listed in <u>Table 13</u> with its appropriate multiplexer channel.

The voltage on the AMUX pin is a buffered output that ranges from 0V to  $V_{FS}$  (1.25V, typ). The buffer has  $50\mu A$  of quiescent current consumption and is only active when a channel is selected (CNFG\_CHG\_I.MUX\_SEL[3:0]  $\neq$  0b0000). Disable the buffer by programming CNFG\_CHG\_I.MUX\_SEL[3:0] to 0b0000 when not actively converting the voltage on AMUX. The AMUX output is high-impedance while CNFG\_CHG\_I.MUX\_SEL[3:0] is 0b0000.

<u>Table 13</u> shows how to translate the voltage signal on the AMUX pin to the value of the parameter being measured. See the *Electrical Characteristics* table and the <u>Register Map</u> for more details.

**Table 13. AMUX Signal Transfer Functions** 

SIGNAL	MUX_SEL[3:0]	TRANSFER FUNCTION	FULL-SCALE SIGNAL MEANING (V <sub>AMUX</sub> = 1.25V)	ZERO- SCALE SIGNAL MEANING (V <sub>AMUX</sub> = 0V)
CHGIN pin voltage	0b0001	$V_{\text{CHGIN}} = \frac{V_{\text{AMUX}}}{G_{\text{VCHGIN}}}$	7.5V	0V
CHGIN pin current	0b0010	$I_{\text{CHGIN}} = \frac{V_{\text{AMUX}}}{G_{\text{ICHGIN}}}$	0.475A	0A
BATT pin voltage	0b0011	$V_{\text{BATT}} = \frac{V_{\text{AMUX}}}{G_{\text{VBATT}}}$	4.6V	0V
BATT pin charging current	0b0100	$I_{\text{BATT(CHG)}} = \frac{V_{\text{AMUX}}}{V_{\text{FS}}} \times I_{\text{FAST-CHG}}$	100% of I <sub>FAST-CHG</sub> (CHG_CC[5:0])	0% of IFAST-CHG
BATT pin discharge current	0b0101	$I_{\text{BATT(DISCHG)}} = \frac{\left(V_{\text{AMUX}} - V_{\text{NULL}}\right)}{\left(V_{\text{FS}} - V_{\text{NULL}}\right)} \times I_{\text{DISCHG}} - \text{SCALE}$	100% of I <sub>DISCHG</sub> -SCALE (IMON_DISCHG_SCALE[3:0])	0% of I <sub>DISCHG-</sub> SCALE

**Table 13. AMUX Signal Transfer Functions (continued)** 

SIGNAL	MUX_SEL[3:0]	TRANSFER FUNCTION	FULL-SCALE SIGNAL MEANING (V <sub>AMUX</sub> = 1.25V)	ZERO- SCALE SIGNAL MEANING (V <sub>AMUX</sub> = 0V)
BATT pin discharge current NULL	0b0110	$V_{\text{NULL}} = V_{\text{AMUX}}$	1.25V	0V
THM pin voltage	0b0111	V <sub>THM</sub> = V <sub>AMUX</sub>	1.25V	0V
TBIAS pin voltage	0b1000	V <sub>TBIAS</sub> = V <sub>AMUX</sub>	1.25V	0V
AGND pin voltage*	0b1001	V <sub>AGND</sub> = V <sub>AMUX</sub>	1.25V	0V
SYS pin voltage	0b1010	$V_{\text{SYS}} = \frac{V_{AMUX}}{G_{\text{VSYS}}}$	4.8V	0V

<sup>\*</sup>AGND pin voltage is accessed through a  $100\Omega$  (typ) pulldown resistor.

## **Measuring Battery Current**

Sampling current in the BATT pin is possible at any time or in any mode with an external ADC. For improved accuracy, the analog circuitry used for monitoring battery discharge current is different from the circuitry monitoring battery charge current. <u>Table 14</u> outlines how to determine the direction of battery current.

**Table 14. Battery Current Direction Decode** 

MEASUREMENT	CHARGING OR DISCHARGING INDICATORS			
	STAT_CHG_B.CHG	STAT_CHG_B.CHG_DTLS[3:0]	STAT_CHG_B.CHGIN_DTLS[1:0]	
Discharging Battery Current			0b00	
(Positive Battery Terminal	Don't care	Don't care	0b01	
Sourcing Current)			0b10	
Charging Battery Current				
(Positive Battery Terminal	1	0b0001 to 0b0111	0b11	
Sinking Current)				

#### **Method for Measuring Discharge Current**

- 1. Program the multiplexer to switch to the discharge NULL measurement by changing CNFG\_CHG\_I.MUX\_SEL[3:0] to 0b0110. A NULL conversion must always be performed first to cancel offsets.
- 2. Wait the appropriate channel switching time (0.3µs, typ).
- 3. Convert the voltage on the AMUX pin and store as V<sub>NULL</sub>.
- Program the multiplexer to switch to the battery discharge current measurement by changing CNFG\_CHG\_I.MUX\_SEL[3:0] to 0b0101. A nonnulling conversion should be done immediately after a NULL conversion.
- 5. Wait the appropriate channel switching time (0.3µs, typ).
- 6. Convert the voltage on the AMUX pin and use the following transfer function to determine the discharge current:

$$I_{\mathsf{BATT}(\mathsf{DISCHG})} = \frac{\left(V_{\mathsf{AMUX}} - V_{\mathsf{NULL}}\right)}{\left(V_{\mathsf{FS}} - V_{\mathsf{NULL}}\right)} \times I_{\mathsf{DISCHG}} - \mathsf{SCALE}$$

 $V_{FS}$  is 1.25V typical.  $I_{DISCHG-SCALE}$  is programmable through CNFG\_CHG\_I.IMON\_DISCHG\_SCALE[3:0]. The

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default value is 300mA. If smaller currents are anticipated, then I<sub>DISCHG-SCALE</sub> can be reduced for improved measurement accuracy.

### **Method for Measuring Charge Current**

- Program the multiplexer to switch to the charge current measurement by changing CNFG\_CHG\_I.MUX\_SEL[3:0] to 0b0100.
- 2. Wait the appropriate channel switching time (0.3µs, typ).
- 3. Convert the voltage on the AMUX pin and use the following transfer function to determine charging current.

$$I_{\text{BATT(CHG)}} = \frac{V_{\text{AMUX}}}{V_{\text{FS}}} \times I_{\text{FAST-CHG}}$$

 $V_{FS}$  is 1.25V typical.  $I_{FAST-CHG}$  the charger's fast-charge constant-current setting and is programmable through CNFG\_CHG\_E.CHG\_CC[5:0].

## **Detailed Description—SIMO Buck-Boost**

The device has a micropower single-inductor, multiple-output (SIMO) buck-boost DC-to-DC converter designed for applications that emphasize low supply current and small solution size. A single inductor is used to regulate three separate outputs, saving board space while delivering better total system efficiency than equivalent power solutions using one buck and linear regulators.

The buck-boost configuration utilizes the entire battery voltage range due to its ability to create output voltages that are above, below, or equal to the input voltage. Peak inductor current for each output is programmable to optimize the balance between efficiency, output ripple, EMI, PCB design, and load capability.

To further boost efficiency when the output voltage is always lower than the input, individual channels of the SIMO buck-boost converter can be configured to be in buck mode, reducing switching losses by toggling less switches compared to buck-boost mode. See the *Buck Mode* section for more details.

#### SIMO Features and Benefits

- Three Output Channels
- Ideal for Low-Power Designs
  - Delivers 500mA at 1.8V Output in Buck Mode and 3.7V Input
  - ±3% Accurate Output Voltage
- Small Solution Size
  - Multiple Outputs from a Single 1.5µH Inductor
- Flexible and Easy to Use
  - Buck and Buck-Boost Modes of Operation
  - · Glitchless Transitions Between Buck and Buck-Boost Modes
  - Programmable Peak Inductor Current
  - · Programmable On-Chip Active Discharge
- Long Battery Life
  - High Efficiency, > 90% at 1.8V Output in Buck Mode and 3.7V Input
  - Higher Total System Efficiency than Buck + LDOs Solution
  - · Low Quiescent Current, 1µA per Output
  - Low Input Operating Voltage, 2.7V (min)

### **SIMO Detailed Block Diagram**

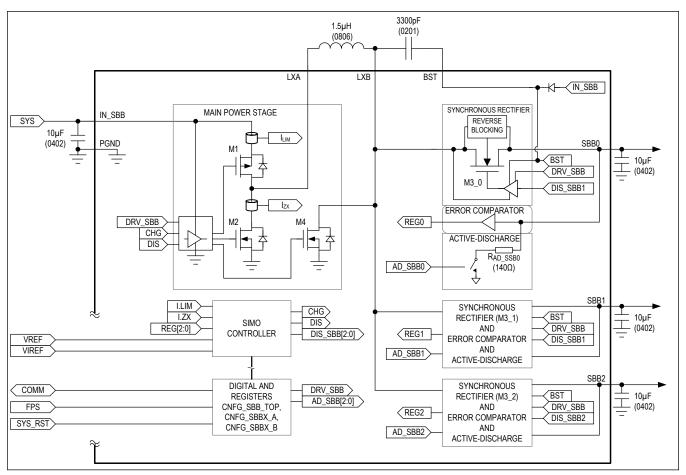


Figure 20. SIMO Detailed Block Diagram

#### SIMO Control Scheme

The SIMO buck-boost is designed to service multiple outputs simultaneously. A proprietary controller ensures that all outputs get serviced in a timely manner, even while multiple outputs are contending for the energy stored in the inductor. When no regulator needs service, the state machine rests in a low-power rest state.

When the controller determines that a regulator requires service, it charges the inductor (M1 + M4) until the peak current limit is reached  $(I_{LIM} = CNFG\_SBBx\_B.IP\_SBB[1:0])$ . The inductor energy then discharges  $(M2 + M3\_x)$  into the output until the current reaches zero  $(I_{ZX})$ . In the event that multiple output channels need servicing at the same time, the controller ensures that no output utilizes all of the switching cycles. Instead, cycles interleave between all the outputs that are demanding service, while outputs that do not need service are skipped.

#### **Drive Strength**

SIMO regulator's drive strength for its internal power MOSFETs is adjustable using the CNFG SBB TOP.DRV SBB[1:0] bit field. The ideal value is determined experimentally for each application. For a PCB layout comparable to the MAX77654 EV kit, 0x1 is the best setting and represents a balance between efficiency and EMI. Faster settings result in higher efficiency but generally require stricter layout rules or shielding to avoid additional EMI. Slower settings limit EMI in non-ideal settings (e.g., contained layout, antennae adjacent to the device, etc.). Change the drive strength only once during system initialization.

#### SIMO Soft-Start

The soft-start feature of the SIMO limits inrush current during startup. The soft-start feature is achieved by limiting the slew rate of the output voltage during startup (dV/dt<sub>SS</sub>).

More output capacitance results in higher input current surges during startup. The following set of equations and example describes the input current surge phenomenon during startup.

In buck-boost mode, the current into the output capacitor (I<sub>CSBB</sub>) during soft-start is:

$$I_{\text{CSBB}} = C_{\text{SBB}} \frac{\text{dV}}{\text{dt}_{\text{SS}}} \left( \text{Equation 1} \right)$$

where:

- C<sub>SRR</sub> is the capacitance on the output of the regulator
- dV/dt<sub>SS</sub> is the voltage change rate of the output

The input current (I<sub>IN</sub>) during soft-start is:

$$I_{\text{IN}} = \frac{\left(I_{\text{CSBB}} + I_{\text{LOAD}}\right) \frac{V_{\text{SBBx}}}{V_{\text{IN}}}}{\xi} \left| \text{Equation2} \right|$$

where:

- I<sub>CSBB</sub> is from the calculation above
- I<sub>I OAD</sub> is current consumed from the external load
- V<sub>SBBx</sub> is the output voltage
- V<sub>IN</sub> is the input voltage
- ξ is the efficiency of the regulator

For example, given the following conditions, the peak input current ( $I_{IN}$ ) during soft-start is ~66.55mA:

#### Given:

- V<sub>IN</sub> is 3.5V
- V<sub>SBB2</sub> is 3.3V
- C<sub>SBB2</sub> = 10μF
- $dV/dt_{SS} = 5mV/\mu s$
- $R_{LOAD2} = 330\Omega (I_{LOAD2} = 3.3V/330\Omega = 10mA)$
- ξ is 85%

#### Calculation:

- I<sub>CSBB</sub> = 10μF x 5mV/μs (from Equation 1)
- I<sub>CSBB</sub> = 50mA

• 
$$I_{IN} = \frac{(50\text{mA} + 10\text{mA})\frac{3.3V}{3.5V}}{0.85}$$
 (from Equation 1)

I<sub>IN</sub> ~ 66.55mA

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

### **SIMO Registers**

Each SIMO buck-boost channel has a dedicated register to program its target output voltage (CNFG\_SBBx\_A.TV\_SBBx[6:0]) and its peak current limit (CNFG\_SBBx\_B.IP\_SBBx[1:0]). Additional controls are available for enabling/disabling the active-discharge resistors (CNFG\_SBBx\_B.ADE\_SBBx), buck mode (CNFG\_SBBx\_B.OP\_MODE) as well as enabling/disabling the SIMO buck-boost channels (CNFG\_SBBx\_B.EN\_SBBx[2:0]). For a full description of bits, registers, default values, and reset conditions, see the *Register Map*.

### **SIMO Active Discharge Resistance**

Each SIMO buck-boost channel has an active-discharge resistor ( $R_{AD\_SBBx}$ ) that is automatically enabled/disabled based on a CNFG\_SBBx\_B.ADE\_SBBx bit and the status of the SIMO regulator. The active discharge feature may be enabled (CNFG\_SBBx\_B.ADE\_SBBx = 1) or disabled (CNFG\_SBBx\_B.ADE\_SBBx = 0) independently for each SIMO channel. Enabling the active discharge feature helps ensure a complete and timely power down of all system peripherals. If the active-discharge resistor is enabled by default, then the active-discharge resistor is on whenever  $V_{SYS}$  is below  $V_{SYSUVLO}$  and above  $V_{POR}$ .

These resistors discharge the output when CNFG\_SBBx\_B.ADE\_SBBx = 1, and their respective SIMO channel is off. If the regulator is forced on through CNFG\_SBBx\_B.EN\_SBBx[2:0] = 0b110 or 0b111, then the resistors do not discharge the output even if the regulator is disabled by the main-bias.

Note that when  $V_{SYS}$  is less than 1.0V, the NMOS transistors that control the active-discharge resistors lose their gate drive and become open.

#### **SIMO Buck Mode**

If the input voltage at IN\_SBB never falls below the output voltage of one or more SIMO converter channels, individual channels can be configured to be in buck mode with the CNFG\_SBBx\_B.OP\_MODE bit. In buck mode, when an output needs service, switch M3\_x remains closed and M4 remains open (see <u>Figure 20</u>). Only M1 and M2 are toggled as in a traditional buck converter. Efficiency is boosted due to three major factors:

- Reduced switching loss: Buck mode toggles only two switches versus the four in buck-boost mode. Therefore, there
  are less switching events during which power is consumed.
- Lower inductor core losses: Inductor current changes from 0A to peak current. The larger the change in current the inductor experiences, the more energy is lost in the inductor core in the form of heat. In buck mode, the peak current can be reduced since less inductor current is needed to support a load. Less inductor current is needed because of direct energy transfer. Direct energy transfer occurs while the inductor is charged, when the input (IN\_SBB) is connected directly to the output (SBBx) through the inductor. Therefore, the input not only provides energy to charge the inductor, energy is also supplied to the output capacitor and load devices. Therefore, less current is needed to charge the inductor, which is used to charge the output capacitor in the next switching state.
- Less frequent charging cycles: In buck mode, the inductor is constantly connected to the serviced output during a
  switching cycle. In comparison, in buck-boost mode, the inductor is connected to the serviced output only when the
  inductor discharges. Thus, with the same peak inductor current limit, buck mode is capable of supplying higher load
  current than buck-boost mode. In addition, with the same load current and peak current limit, the switching frequency
  can be reduced with buck mode.

Maintain a minimum headroom of 0.7V between IN\_SBB and SBBx in buck mode because inductor charge time (dt =  $L \times I_{P\_SBBx}/(V_{IN\_SBB} - V_{SBBx})$ ) increases as the difference between the IN\_SBB and SBBx voltages shrinks. As the inductor current takes longer to reach its peak, the output voltage may take too long to reach its target voltage, and the MAX77654 may trigger a fault flag.

## **Applications Information**

#### **SIMO Available Output Current**

The available output current on a given SIMO channel is a function of the input voltage, output voltage, the peak current limit setting, and the output current of the other SIMO channels. Maxim offers a calculator (see the <u>Support Material</u> section) that outlines the available capacity for specific conditions. <u>Table 15</u> is an extraction from the calculator.

**Table 15. SIMO Available Output Current for Common Applications** 

PARAMETERS	EXAMPLE 1	EXAMPLE 2	EXAMPLE 3	EXAMPLE 4
V <sub>IN_MIN</sub>	2.7V	2.7V	3.2V	3.4V
R <sub>L_DCR</sub>	0.1Ω	0.1Ω	0.1Ω	0.12Ω
SBB0	1.0V at 100mA	1.0V at 80mA	1.2V at 50mA	1.2V at 20mA
SBB1	1.2V at 75mA	1.2V at 50mA	1.8V at 100mA	1.8V at 80mA
SBB2	1.8V at 50mA	1.8V at 40mA	3.3V at 30mA	3.3V at 10mA
Operating Mode	Buck	Buck	Buck/Buck-Boost	Buck/Buck-Boost
I <sub>P_SBB0</sub>	0.5A	0.5A	0.5A	0.5A
I <sub>P_SBB1</sub>	0.75A	0.5A	0.5A	0.5A
I <sub>P_SBB2</sub>	0.5A	0.5A	0.75A	0.5A
Utilized Capacity	78%	67%	76%	47%

<sup>\*</sup>ESR<sub>C IN</sub> = ESR<sub>C OUT</sub> =  $5m\Omega$ , L =  $1.5\mu$ H

#### **Inductor Selection**

Choose an inductance from 1.0µH to 2.2µH; 1.5µH inductors work best for most designs. Larger inductances transfer more energy to the output for each cycle and typically result in larger output voltage ripple and better efficiency. See the <u>Output Capacitor Selection</u> section for more information on how to size your output capacitor in order to control ripple.

Choose the inductor saturation current to be greater than or equal to the maximum peak current limit setting that is used for all of the SIMO buck-boost channels ( $I_{P\_SBBx}$ ). For example, if SBB0 is set for 0.5A, SBB1 is set for 0.75A, and SBB2 is set for 1.0A, then choose the saturation current to be greater than or equal to 1.0A.

Choose the RMS current rating of the inductor (typically the current at which the temperature rises appreciably) based on the expected load currents for the system. For systems where the expected load currents are not well known, be conservative and choose the RMS current to be greater than or equal to half the higher maximum peak current limit setting [ $I_{RMS} \ge MAX(I_{P\_SBB0}, I_{P\_SBB1}, I_{P\_SBB2})/\sqrt{3}$ ]. This is a conservative choice because the SIMO buck-boost regulator implements a discontinuous conduction mode (DCM) control scheme, which returns the inductor current to zero each cycle.

Consider the DC-resistance (DCR), AC-resistance (ACR), and solution size of the inductor. Typically, smaller sized inductors have larger DC-resistance and larger AC-resistance that reduces efficiency and the available output current. Note that many inductor manufacturers have inductor families which contain different versions of core material in order

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to balance trade-offs between DCR, ACR (i.e., core losses), and component cost. For this SIMO regulator, inductors with the lowest ACR in the 1.0MHz to 2.0MHz region tend to provide the best efficiency.

#### **Input Capacitor Selection**

Choose the input bypass capacitance ( $C_{IN\_SBB}$ ) to be 10 $\mu$ F. Larger values of  $C_{IN\_SBB}$  improve the decoupling for the SIMO regulator.

 $C_{IN\_SBB}$  reduces the current peaks drawn from the battery or input power source during SIMO regulator operation and reduces switching noise in the system. The ESR/ESL of the input capacitor should be very low (i.e., ESR  $\leq 5m\Omega$  and ESL  $\leq 500$ pH) for frequencies up to 2MHz. Ceramic capacitors with X5R or X7R dielectric are highly recommended due to their small size, low ESR, and small temperature coefficients.

To fully utilize the available input voltage range of the SIMO (5.5V, max), use a capacitor with a voltage rating of 6.3V at minimum.

#### **Boost Capacitor Selection**

Choose the boost capacitance ( $C_{BST}$ ) to be 3.3nF. Smaller values of  $C_{BST}$  (< 1nF) result in insufficient gate drive for M3. Larger values of  $C_{BST}$  (> 10nF) have the potential to degrade the startup performance. Ceramic capacitors with 0201 or 0402 case size are recommended.

#### **Output Capacitor Selection**

Choose each output bypass capacitance ( $C_{SBBx}$ ) based on the target output voltage ripple ( $\Delta V_{SBBx}$ ): typical values are 22µF. Larger values of  $C_{SBBx}$  improve the output voltage ripple but increase the input surge currents during soft-start and output voltage changes. The output voltage ripple is a function of the inductance (L), the output voltage ( $V_{SBBx}$ ), and the peak current limit setting ( $I_{PSBx}$ ). See Equation 3 to estimate required, effective capacitance.

$$C_{\text{SBBx}} = {}^{I_{\text{P}}}_{\text{SBBx}}^{2*L} / {}^{2*V_{\text{SBBx}}^* \Delta V_{\text{SBBx}}(\text{Equation3})}$$

Maxim also offers a calculator (see the <u>Support Materials</u> section) to aid in the selection of the output capacitance. Note that most designs concern themselves with having enough capacitance on the output but there is also a maximum capacitance limitation that is calculated within the SIMO calculator; take care not to exceed the maximum capacitance.

 $C_{SBBx}$  is required to keep the output voltage ripple small. The impedance of the output capacitor (ESR, ESL) should be very low (i.e.,  $ESR \le 5m\Omega$  and  $ESL \le 500pH$ ) for frequencies up to 2MHz. Ceramic capacitors with X5R or X7R dielectric are highly recommended due to their small size, low ESR, and small temperature coefficients.

A capacitor's effective capacitance decreases with increased DC bias voltage. This effect is more pronounced as capacitor case sizes decrease. Due to this characteristic, it is possible for an 0603 case size capacitor to perform well, while an 0402 case size capacitor of the same value performs poorly. The SIMO regulator is stable with low output capacitance ( $1\mu$ F) but the output voltage ripple would be large; consider the effective output capacitance value after initial tolerance, bias voltage, aging, and temperature derating.

#### **Example Component Selection**

Pick input/output capacitors and the inductor for the given requirements:

V<sub>IN SBB. typical</sub> = 3.7V

### **Table 16. Design Requirements**

	SBB0	SBB1	SBB2
Output Voltage	3.3V	1.8V	1.2V
Maximum Load Current	50mA	60mA	80mA
Maximum Voltage Ripple	50mV	30mV	30mV

#### Inductor, Peak Current Limit, and Input Capacitor

For the best efficiency, a  $2.2\mu H$  inductor is chosen. For this example, assume the DFE201612E-2R2M inductor from Murata is used. This particular inductor has  $116m\Omega$  of DCR.

Since the load current is low, first choose the inductor current peak to be 0.333A for all outputs. Next, enter these values into Maxim's SIMO calculator as mentioned previously.

Complete	Value	Value Unit Per Channel	Day Channal Combal	Per	Per Channel Value		
Symbol	value	Unit	Per Channel Symbol	SBB0	SBB1	SBB2	Uni
			Input Section				
V <sub>IN</sub>	3.7000	V	V <sub>OUT</sub>	3.300	1.800	1.200	V
L	2.20	μН	I <sub>OUT</sub>	50.0	60.0	80.0	mΑ
r <sub>L_DCR</sub>	116	mΩ	C <sub>OUT</sub> Effective	8.1	13.8	16.8	μF
			r <sub>C_ESR</sub>	5	5	5	mΩ
T <sub>OPERATING</sub>	25	°C	Channel Enabled?	Yes	Yes	Yes	
			Other Inputs				
Device	MAX77654		I <sub>L_Peak</sub>	0.333	0.333	0.333	Α
			Operating Mode	Buck-Boost	Buck	Buck	
			Calculation Result	S			
			Inductor Utilization				
Total Utilization	141.5%		Utilization	57.7%	35.7%	48.1%	
			Current and Power				

Figure 21. Component Selection—High Utilization

As shown in <u>Figure 21</u>, the utilization is over 100%, which leads to output voltage droop. To lower utilization, increase the inductor peak current limits. For this example, 1A is used for SBB0 and 0.5A for SBB1 and SBB2. <u>Figure 22</u> shows utilization less than 80%. Using 0.5A for the inductor peak current limit has the added benefit of increased efficiency.

Compleal	Value	11	Day Channal Combal	Per	Channel V	alue	11
Symbol	Value	Unit	Per Channel Symbol	SBB0	SBB1	SBB2	Ur
			Input Section				
V <sub>IN</sub>	3.7000	V	V <sub>OUT</sub>	3.300	1.800	1.200	V
L	2.20	μН	I <sub>OUT</sub>	50.0	60.0	80.0	mΑ
r <sub>L_DCR</sub>	116	mΩ	C <sub>OUT</sub> Effective	8.1	13.8	16.8	μF
			r <sub>C_ESR</sub>	5	5	5	mΩ
T <sub>OPERATING</sub>	25	°C	Channel Enabled?	Yes	Yes	Yes	
			Other Inputs				
Device	MAX77654		I <sub>L_Peak</sub>	1.000	0.500	0.500	Α
			Operating Mode	Buck-Boost	Buck	Buck	
			Calculation Result	:s			
			Inductor Utilization				
Total Utilization	75.6%		Utilization	19.9%	23.7%	32.0%	
			Current and Power				

Figure 22. Component Selection—Final Current Peak Limits

To support the selected peak currents, choose 22µF for the input capacitor.

#### **Output Capacitors**

Using Equation 3 and the selected inductor current peak limits, the minimum output capacitances required are:

$$\begin{split} &C_{\text{SBB0\_min}} = \frac{I_{\text{P\_SBB0}}^2 x L}{2x V_{\text{SBB0}} x \Delta V_{\text{SBB0}}} = \frac{1^2 x 2.2 x 10^{-6} A^2 x H}{2x 3.3 x 0.05 V^2} = 6.67 \mu \text{F} \\ &C_{\text{SBB1\_min}} = \frac{I_{\text{P\_SBB1}}^2 x L}{2x V_{\text{SBB1}} x \Delta V_{\text{SBB1}}} = \frac{0.5^2 x 2.2 x 10^{-6} A^2 x H}{2x 1.8 x 0.03 V^2} = 5.09 \mu \text{F} \\ &C_{\text{SBB2\_min}} = \frac{I_{\text{P\_SBB2}}^2 x L}{2x V_{\text{SBB2}} x \Delta V_{\text{SBB2}}} = \frac{0.5^2 x 2.2 x 10^{-6} A^2 x H}{2x 1.2 x 0.03 V^2} = 7.64 \mu \text{F} \end{split}$$

For this example, the  $22\mu F$  GRM188R61A226ME15 is chosen for all three outputs. The effective capacitance after derating is the following:

 $C_{\text{SBB0}} = 8.113 \mu\text{F}$ 

 $C_{SBB1} = 13.828 \mu F$ 

 $C_{SBB2} = 16.793 \mu F$ 

Go back to the calculator and enter the capacitance for each channel. <u>Figure 23</u> shows the expected ripples, which fit the requirements.

Complete	Value	I I a la	Day Channal Combal	Per	Channel V	alue	11:
Symbol	Value	Unit	Per Channel Symbol	SBB0	SBB1	SBB2	Uni
			Input Section				
V <sub>IN</sub>	3.7000	V	V <sub>OUT</sub>	3.300	1.800	1.200	٧
L	2.20	μН	I <sub>OUT</sub>	50.0	60.0	80.0	mA
r <sub>L_DCR</sub>	116	mΩ	C <sub>OUT</sub> Effective	8.1	13.8	16.8	μF
			r <sub>C_ESR</sub>	5	5	5	mΩ
T <sub>OPERATING</sub>	25	°C	Channel Enabled?	Yes	Yes	Yes	
			Other Inputs				
Device	MAX77654		I <sub>L_Peak</sub>	1.000	0.500	0.500	Α
			Operating Mode	Buck-Boost	Buck	Buck	
			Calculation Result	s			
			Inductor Utilization				
Total Utilization	75.6%		Utilization	19.9%	23.7%	32.0%	
			Current and Power				
		_	Output Voltage Rippl				
			V <sub>OUT_ripple_no_load</sub>	42.5	23.8	21.0	mV <sub>p</sub>
				1.3% 35.3	1.3%	1.8%	m)/
			V <sub>OUT_ripple_w_load</sub>	1.1%	1.1%	15.7 1.3%	

Figure 23. Component Selection—Expected Ripple

#### **Summary**

- L = 2.2µH
- C<sub>IN SBB</sub> = 22μF
- Total Switching Utilization = 76%

### **Table 17. Summary of Design for Component Selection Example**

	SBB0	SBB1	SBB2
I <sub>P_SBBx</sub>	1A	0.5A	0.5A
C <sub>SBBx</sub> (nominal)	22µF	22µF	22μF
$\Delta V_{SBBx}$	35.3mV	19.4mV	15.7mV

Real applications should also consider the minimum input voltage since the battery discharges. The following is a summary using the same components but an input voltage of 3.0V instead. The switching utilization increased to 77.1%, still below 80%.

- L = 2.2µH
- <u>C<sub>IN\_SBB</sub></u> = 22μF
- Total Switching Utilization = 77.1%

**Table 18. Summary of Design with Lower Input Voltage** 

	SBB0	SBB1	SBB2
I <sub>P_SBBx</sub>	1A	0.5A	0.5A
C <sub>SBBx</sub> (nominal)	22µF	22µF	22µF
ΔV <sub>SBBx</sub>	35.3mV	26.9mV	18.6mV

#### **SIMO Switching Frequency**

The SIMO buck-boost regulator uses a pulse frequency modulation (PFM) control scheme. The switching frequency for each output is a function of the operating mode, input voltage, output voltage, load current, and inductance. Output capacitance is a minor factor in SIMO switching frequency. Maxim offers a SIMO calculator (see the <u>Support Material</u> section) to estimate expected switching frequency.

At no load, switching frequencies can be as low as 10Hz. For the 3.7V input to 1.2V output channel from the <u>Example Component Selection</u> section, the switching frequency is about 327kHz.

Table 19 lists how different factors increase or decrease switching frequency.

### **Table 19. Switching Frequency Control**

FACTOR	INCREASING FREQUENCY	DECREASING FREQUENCY
Inductor Current Peak Limit	Lower peak limit	Higher peak limit
Operating Mode	Buck-boost mode	Buck mode
Inductor	Decrease inductance	Increase inductance
Output Capacitor	Decrease capacitance	Increase capacitance
Input Voltage	Higher voltage	Lower voltage
Output Voltage	Higher voltage	Lower voltage
Load Current	Higher current	Lower current

#### **Unused Outputs**

Do not leave unused outputs unconnected. If an output left unconnected is accidentally enabled, the charged inductor experiences an open circuit, and the output voltage soars above the absolute maximum rating, damaging the device. If an output is not used, do one of the following:

- 1. Disable the output (CNFG\_SBBx\_B.EN\_SBBx[2:0] = 0x4 or 0x5) and connect the output to ground. If an unused output is default enabled or can be accidentally enabled, do one of the following recommendations instead.
- 2. Bypass the unused output with a 1µF capacitor to ground.
- 3. Connect the unused output to IN\_SBB or a different output channel if the unused output is programmed to a lower voltage. Since the output voltage is higher than the unused output, the regulator does not service the unused output even if it is unintentionally enabled.
  - 1. Note that some OTP options have the active-discharge resistors enabled by default. Connecting an unused output to IN\_SBB is not recommended if the active discharge is enabled by default. If connecting the unused output to a different channel, disable the active-discharge resistor (CNFG\_SBBx\_B.ADE\_SBBx = 0) of the unused channel.

#### **PCB Layout Guide**

#### **Capacitors**

Place decoupling capacitors as close as possible to the IC such that connections from capacitor pads to pin and from capacitor pads to ground pins are short. Keeping the connections short lowers parasitic inductance and resistance, improving performance and shrinking the physical size of hot loops.

If connections to the capacitors are through vias, use multiple vias to minimize parasitics. Also, connect loads to the capacitor pads rather than the device pins.

Most critical are the capacitors for the switching regulator: input capacitor at IN SBB and output capacitors at SBBx.

#### Input Capacitor at IN\_SBB

Minimize the parasitic inductance from PGND to input capacitor to IN\_SBB to reduce ringing on the LXA voltage.

#### **Output Capacitors at SBBx**

The output capacitors experience large changes in current as the regulator charges (buck mode) and discharges (both modes) the inductor. In buck mode, the capacitor current ramps up at the same rate as mentioned in the previous section. In buck-boost mode, the capacitor current ramps up very quickly. In both modes, the capacitor current ramps down at a rate of  $\frac{dI_{C_SBBX}}{dt} = \frac{V_{SBBX}}{L}$  from inductor peak current. Since the ramp down can occur in less than 1µs, and the current increases rapidly for buck-boost mode, minimize parasitic inductance from SBBx to output capacitor to PGND.

#### Inductor

Keep the inductor close to the IC to reduce trace resistance; however, prioritize any regulator input/output capacitors over the inductor. Use the appropriate trace width from LXA to inductor to LXB to support the peak inductor current. Likewise, if there are vias in the path, use an appropriate amount of vias to support the peak current.

#### **Ground Connections**

As the switching regulator charges and discharges the inductor, current flows from PGND to the input capacitor ground, from output capacitor ground to PGND, or from output capacitor ground to input capacitor ground. Therefore, use a wide, continuous copper plane to connect PGND to the capacitor grounds.

When connecting the GND and PGND pins together, ensure noise from the power ground does not enter the analog ground (where GND is connected). For example, assuming the ground pins are connected through a solid ground plane on an internal layer, one via connecting GND to the internal ground plane may be sufficient to protect GND from most of the noise in the power-ground plane. Likewise, if there are other higher current or noisy circuitry near this device, avoid connecting the GND pin directly to their grounds.

For more guidelines on proper grounding, visit: <a href="https://www.maximintegrated.com/en/design/partners-and-technology/design-technology/ground-layout-board-designers.html">https://www.maximintegrated.com/en/design/partners-and-technology/design-technology/ground-layout-board-designers.html</a>.

### **Example PCB Layout**

Figure 24 shows an example layout of the top layer.

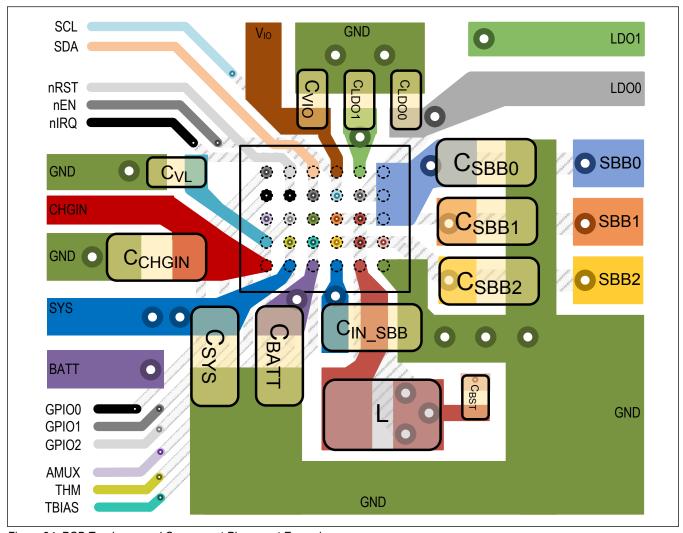


Figure 24. PCB Top-Layer and Component Placement Example

### Detailed Description—Low Dropout Linear Regulator (LDO)/Load Switch (LSW)

The device includes two on-chip low-dropout linear regulators (LDO0/1) that can also be configured as load switches. These LDOs are optimized to have low-quiescent current. The input voltage range (V<sub>IN\_LDOx</sub>) allows it to be powered directly from the main energy source such as a Li-Poly battery or from an intermediate regulator. Each linear regulator delivers up to 100mA.

#### **Features and Benefits**

- 2x 100mA LDO
- LDO Input Voltage Range: 1.71V to 5.5V
  LSW Input Voltage Range: 1.3V to 5.5V
- Adjustable Output Voltage
- 100mV Maximum Dropout Voltage at ECT Conditions
- Programmable On-Chip Active Discharge

#### **LDO/LSW Simplified Block Diagram**

Each LDO/LSW block has one input (IN\_LDOx) and one output (LDOx) and several ports that exchange information with the rest of the device (V<sub>REF</sub>, EN\_LDOx, ADE\_LDOx). V<sub>REF</sub> comes from the main bias circuits. CNFG\_LDOx\_B.EN\_LDOx and CNFG\_LDOx\_B.ADE\_LDOx are register bits for controlling the enable and active-discharge feature, respectively. See the *Register Map* for more information.

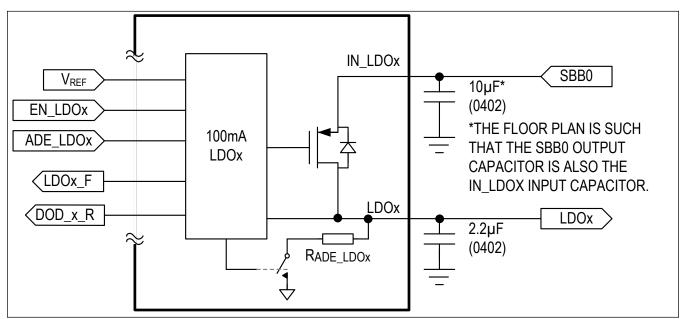


Figure 25. LDO Simplified Block Diagram

#### LDO/LSW Active-Discharge Resistor

Each LDO/LSW block has an active-discharge resistor ( $R_{AD\_LDOx}$ ) that is enabled if CNFG\_LDO\_B.ADE\_LDOx = 1 and LDOx is disabled. Enabling the active discharge feature helps ensure a complete and timely power down of the resource. During power up, if  $V_{SYS} > V_{POR}$  and CNFG\_LDO\_B.ADE\_LDOx = 1, the active-discharge resistor is enabled.

#### **LDO/LSW Soft-Start**

The soft-start feature limits inrush current during startup, and is achieved by limiting the slew rate of the output voltage during startup (dV<sub>OUT LDOx</sub>/dt<sub>SS</sub>).

More output capacitance results in higher input current surges during startup. The equation and example describes the input current surge phenomenon during startup.

The input current (I<sub>IN LDOx</sub>) during soft-start is:

$$I_{\mathsf{IN\_LDOx}} = C_{\mathsf{LDOx}} \frac{\mathsf{dV}_{\mathsf{OUT\_LDOx}}}{\mathsf{dt}_{\mathsf{SS}}} + I_{\mathsf{OUT\_LDOx}}$$

where:

- C<sub>LDOx</sub> is the capacitance on the output of the regulator
- dV<sub>OUT LDOx</sub>/dt<sub>SS</sub> is the voltage change rate of the output

For example, given the following conditions, the input current ( $I_{IN\ LDOx}$ ) during soft start is 13.08mA:

Given:

- C<sub>LDOx</sub> = 2.2μF
- $dV_{OUT\_LDOx}/dt_{SS} = 1.4 \text{mV/}\mu\text{s}$
- LDOx programmed to 1.85V
- $R_{LDOx} = 185\Omega (I_{OUT LDOx} = 1.85V/185\Omega = 10mA)$

Calculation:

- $I_{IN} = 2.2 \mu F \times 1.4 \text{mV/} \mu \text{s} + 10 \text{mA}$
- I<sub>IN</sub> = 13.08mA

#### **Load Switch Configuration**

Both LDO0 and LDO1 can be configured as load switches with the CNFG\_LDOx\_B.LDOx\_MD bit. As shown in <u>Figure 26</u>, the transition from LDO to LSW mode is controlled by a defined slew rate until dropout is detected. Once dropout is detected, the load switch is fully closed and the dropout interrupt flag (INT GLBL.DODx R) is set.

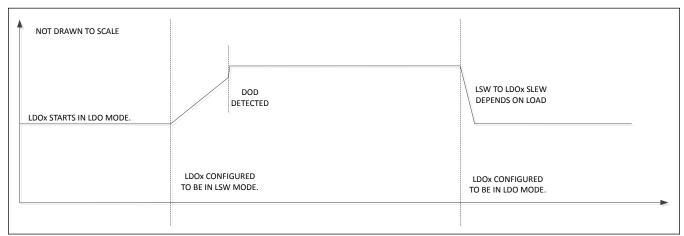


Figure 26. LDO to LSW Transition Waveform

## Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

### **Applications Information**

#### **Input Capacitor Selection**

Make sure the input bypass capacitance ( $C_{IN\_LDOx}$ ) is at least 2.2 $\mu$ F. Larger values of  $C_{IN\_LDOx}$  improve the decoupling for LDOx. The floor plan of the device is such that SBB0 is adjacent to IN\_LDOx and if the SIMO channel 0 output powers the input of LDOx, then its output capacitor ( $C_{SBB0}$ ) can also serve as  $C_{IN\_LDOx}$  such that only one capacitor is required.

 $C_{IN\_LDO_X}$  reduces the current peaks drawn from the battery or input power source during operation. The impedance of the input capacitor (ESR, ESL) should be very low (i.e., ESR  $\leq 50 m\Omega$  and ESL  $\leq 5 nH$ ) for frequencies up to 0.5MHz. Ceramic capacitors with X5R or X7R dielectric are highly recommended due to their small size, low ESR, and small temperature coefficients.

#### **Output Capacitor Selection**

For both LDO and LSW modes, choose the output bypass capacitance (C<sub>LDOx</sub>) to be 1µF.

In LDO mode, larger values of  $C_{LDO_X}$  improve output PSRR but increase input surge currents during soft-start and output voltage changes. The effective output capacitance should not exceed  $2.8\mu F$  to maintain stability.

While in LDO mode,  $C_{LDOX}$  is required to keep stability. The series inductance of the output capacitor and its series resistance should be low (i.e., ESR  $\leq$  10m $\Omega$  and ESL  $\leq$  1nH) for frequencies up to 0.5MHz. Ceramic capacitors with X5R or X7R dielectric are highly recommended due to their small size, low ESR, and small temperature coefficients.

A capacitor's effective capacitance decreases with increased DC bias voltage. This effect is more pronounced with smaller capacitor case sizes. Due to this characteristic, 0603 case size capacitors tend to perform well while 0402 case size capacitors of the same value perform poorly.

# Detailed Description—I<sup>2</sup>C Serial Communication

#### **General Description**

The IC features a revision 3.0 I<sup>2</sup>C-compatible, 2-wire serial interface consisting of a bidirectional serial data line (SDA) and a serial clock line (SCL). This device acts as a slave-only device, relying on the master to generate a clock signal. SCL clock rates from 0Hz to 3.4MHz are supported.

 $I^2C$  is an open-drain bus and therefore SDA and SCL require pullups. Optional resistors (24 $\Omega$ ) in series with SDA and SCL protect the device inputs from high-voltage spikes on the bus lines. Series resistors also minimize crosstalk and undershoot on bus signals.

Figure 27 shows the functional diagram for the  $I^2C$  based communications controller. For additional information on  $I^2C$ , refer to the " $I^2C$  Bus Specification and User Manual" which is available for free through the internet.

#### **Features**

- I<sup>2</sup>C Revision 3.0 Compatible Serial Communications Channel
- 0Hz to 100kHz (Standard Mode)
- 0Hz to 400kHz (Fast Mode)
- 0Hz to 1MHz (Fast-Mode Plus)
- 0Hz to 3.4MHz (High-Speed Mode)
- Does not utilize I<sup>2</sup>C Clock Stretching

### I<sup>2</sup>C Simplified Block Diagram

There are three pins (aside from GND) for the  $I^2C$ -compatible interface.  $V_{IO}$  determines the logic level, SCL is the clock line, and SDA is the data line. Note that the interface does **not** have the ability to drive the SCL line.

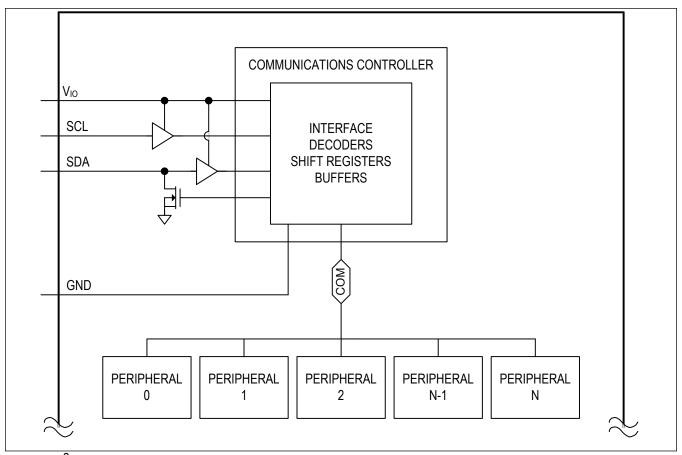


Figure 27. I<sup>2</sup>C Simplified Block Diagram

### I<sup>2</sup>C System Configuration

The  $I^2C$ -compatible interface is a multimaster bus. The maximum number of devices that can attach to the bus is only limited by bus capacitance.

A device on the I<sup>2</sup>C bus that sends data to the bus is called a transmitter. A device that receives data from the bus is called a receiver. The device that initiates a data transfer and generates the SCL clock signals to control the data transfer is a master. Any device that is being addressed by the master is considered a slave. The I<sup>2</sup>C-compatible interface operates as a slave on the I<sup>2</sup>C bus with transmit and receive capabilities.

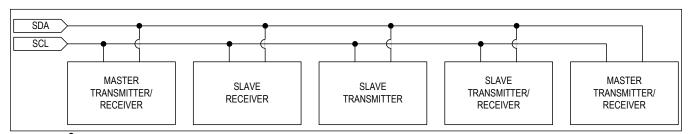


Figure 28. I<sup>2</sup>C System Configuration

#### I<sup>2</sup>C Interface Power

The I<sup>2</sup>C interface derives its power from  $V_{IO}$ . Typically a power input such as  $V_{IO}$  would require a local 0.1µF ceramic bypass capacitor to ground. However, in highly integrated power distribution systems, a dedicated capacitor might not be necessary. If the impedance between  $V_{IO}$  and the next closest capacitor ( $\geq 0.1$ µF) is less than 100m $\Omega$  in series with 10nH, then a local capacitor is not needed. Otherwise, bypass  $V_{IO}$  to GND with a 0.1µF ceramic capacitor.

 $V_{IO}$  accepts voltages from 1.7V to 3.6V ( $V_{IO}$ ). Cycling  $V_{IO}$  does not reset the I<sup>2</sup>C registers. When  $V_{IO}$  is less than  $V_{IOUVLO}$  and  $V_{SYS}$  is less than  $V_{SYSUVLO}$ , SDA and SCL are high-impedance.

#### I<sup>2</sup>C Data Transfer

One data bit is transferred during each SCL clock cycle. The data on SDA must remain stable during the high period of the SCL clock pulse. Changes in SDA while SCL is high are control signals. See the <u>I<sup>2</sup>C Start and Stop Conditions</u> section. Each transmit sequence is framed by a START (S) condition and a STOP (P) condition. Each data packet is nine bits long: eight bits of data followed by the acknowledge bit. Data is transferred with the MSB first.

### I<sup>2</sup>C Start and Stop Conditions

When the serial interface is inactive, SDA and SCL idle high. A master device initiates communication by issuing a START condition. A START condition is a high-to-low transition on SDA with SCL high. A STOP condition is a low-to-high transition on SDA, while SCL is high. See <u>Figure 29</u>.

A START condition from the master signals the beginning of a transmission to the device. The master terminates transmission by issuing a not-acknowledge followed by a STOP condition (see the <u>l</u><sup>2</sup><u>C Acknowledge Bit</u> section for information on not-acknowledge). The STOP condition frees the bus. To issue a series of commands to the slave, the master can issue repeated start (Sr) commands instead of a STOP command to maintain control of the bus. In general a repeated start command is functionally equivalent to a regular start command.

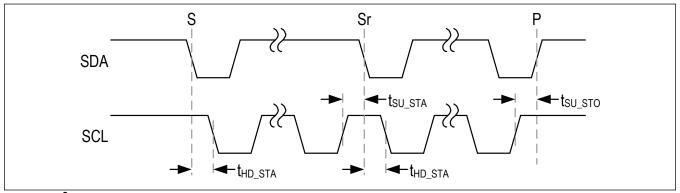


Figure 29. I<sup>2</sup>C Start and Stop Conditions

### I<sup>2</sup>C Acknowledge Bit

Both the I<sup>2</sup>C bus master and slave devices generate acknowledge bits when receiving data. The acknowledge bit is the last bit of each nine bit data packet. To generate an acknowledge (A), the receiving device must pull SDA low before the rising edge of the acknowledge-related clock pulse (ninth pulse) and keep it low during the high period of the clock pulse. See <u>Figure 30</u>. To generate a not-acknowledge (nA), the receiving device allows SDA to be pulled high before the rising edge of the acknowledge-related clock pulse and leaves it high during the high period of the clock pulse.

Monitoring the acknowledge bits allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if a receiving device is busy or if a system fault has occurred. In the event of an unsuccessful data transfer, the bus master should reattempt communication at a later time.

This device issues an ACK for all register addresses in the possible address space even if the particular register does not exist.

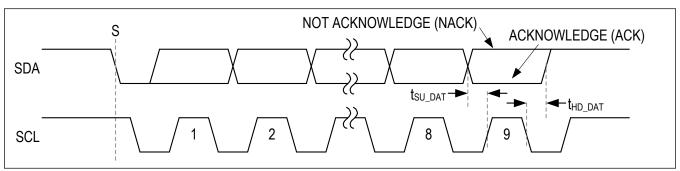


Figure 30. Acknowledge Bit

#### I<sup>2</sup>C Slave Address

The I $^2$ C controller implements 7-bit slave addressing. An I $^2$ C bus master initiates communication with the slave by issuing a START condition followed by the slave address. See <u>Figure 31</u>. The OTP address is factory-programmable for one of two options. See <u>Table 20</u>. All slave addresses not mentioned in <u>Table 20</u> are not acknowledged.

### Table 20. I<sup>2</sup>C Slave Address Options

ADDRESS	7-BIT SLAVE ADDRESS	8-BIT WRITE ADDRESS	8-BIT READ ADDRESS
Main Address (ADDR = 1)*	0x48, 0b 100 1000	0x90, 0b 1001 0000	0x91, 0b 1001 0001
Main Address (ADDR = 0)*	0x40, 0b 100 0000	0x80, 0b 1000 0000	0x81, 0b 1000 0001
Test Mode**	0x49, 0b 100 1001	0x92, 0b 1001 0010	0x93, 0b 1001 0011

<sup>\*</sup>Perform all reads and writes on the main address. ADDR is a factory one-time programmable (OTP) option, allowing for address changes in the event of a bus conflict. *Contact Maxim* for more information.

<sup>\*\*</sup>When test mode is unlocked, the additional address is acknowledged. Test mode details are confidential. If possible, leave the test mode address unallocated to allow for the rare event that debugging needs to be performed in cooperation with Maxim.

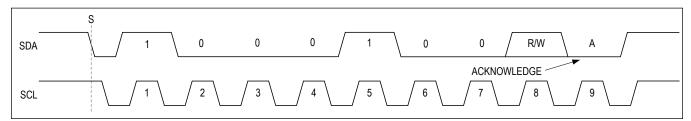


Figure 31. Slave Address Example

### I<sup>2</sup>C Clock Stretching

In general, the clock signal generation for the  $I^2C$  bus is the responsibility of the master device. The  $I^2C$  specification allows slow slave devices to alter the clock signal by holding down the clock line. The process in which a slave device holds down the clock line is typically called clock stretching. The IC does not use any form of clock stretching to hold down the clock line.

#### I<sup>2</sup>C General Call Address

This device does not implement the I<sup>2</sup>C specifications general call address and does not acknowledge the general call address (0b0000\_0000).

#### I<sup>2</sup>C Device ID

This device does not support the I<sup>2</sup>C Device ID feature.

### I<sup>2</sup>C Communication Speed

This device is compatible with all four communication speed ranges as defined by the Revision 3.0 I<sup>2</sup>C specification:

- 0Hz to 100kHz (Standard Mode)
- 0Hz to 400kHz (Fast Mode)
- 0Hz to 1MHz (Fast-Mode Plus)
- 0Hz to 3.4MHz (High-Speed Mode)

Operating in standard mode, fast mode, and fast-mode plus does not require any special protocols. The main consideration when changing bus speed through this range is the combination of the bus capacitance and pullup resistors. Larger values of bus capacitance and pullup resistance increase the time constant (C x R), slowing bus operation. Therefore, when increasing bus speeds, the pullup resistance must be decreased to maintain a reasonable time constant. Refer to the *Pullup Resistor Sizing* section of the I<sup>2</sup>C bus specification and user manual (available for free on the internet) for detailed guidance on the pullup resistor selection. In general for bus capacitances of 200pF, a 100kHz bus needs  $5.6k\Omega$  pullup resistors, a 400kHz bus needs about  $1.5k\Omega$  pullup resistors, and a 1MHz bus needs  $680\Omega$  pullup resistors. Remember that, while the open-drain bus is low, the pullup resistor is dissipating power, and lower value pullup resistors dissipate more power (V<sup>2</sup>/R).

Operating in high-speed mode requires some special considerations. For a full list of considerations, refer to the publicly available I<sup>2</sup>C bus specification and user manual. Major considerations with respect to this part are:

- The I<sup>2</sup>C bus master uses current source pullups to shorten the signal rise.
- The I<sup>2</sup>C slave must use a different set of input filters on its SDA and SCL lines to accommodate for the higher bus.
- The communication protocols need to utilize the high-speed master code.

At power-up and after each stop condition, the bus input filters are set for standard mode, fast mode, and fast-mode plus (i.e., 0Hz to 1MHz). To switch the input filters for high-speed mode, use the high-speed master code protocols that are described in the  $\ell^2$ C Communication Protocols section.

#### I<sup>2</sup>C Communication Protocols

Both writing to and reading from registers are supported as described in the following subsections.

#### Writing to a Single Register

<u>Figure 32</u> shows the protocol for the  $I^2C$  master device to write one byte of data to this device. This protocol is the same as the SMBus specification's write byte protocol.

The write byte protocol is as follows:

- 1. The master sends a start command (S).
- 2. The master sends the 7-bit slave address followed by a write bit (R/W = 0).
- 3. The addressed slave asserts an acknowledge (A) by pulling SDA low.
- 4. The master sends an 8-bit register pointer.
- 5. The slave acknowledges the register pointer.
- 6. The master sends a data byte.
- 7. The slave updates with the new data.
- 8. The slave acknowledges or not acknowledges the data byte. The next rising edge on SDA loads the data byte into its target register and the data becomes active.
- 9. The master sends a stop condition (P) or a repeated start condition (Sr). Issuing a P ensures that the bus input filters are set for 1MHz or slower operation. Issuing an Sr leaves the bus input filters in their current state.

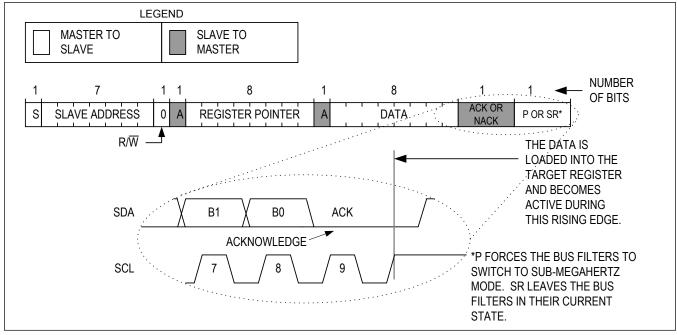


Figure 32. Writing to a Single Register with the Write Byte Protocol

## Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

#### Writing Multiple Bytes to Sequential Registers

<u>Figure 33</u> shows the protocol for writing to sequential registers. This protocol is similar to the write byte protocol, except the master continues to write after it receives the first byte of data. When the master is done writing, it issues a stop or repeated start.

The writing to sequential registers protocol is as follows:

- 1. The master sends a start command (S).
- 2. The master sends the 7-bit slave address followed by a write bit (R/W = 0).
- 3. The addressed slave asserts an acknowledge (A) by pulling SDA low.
- 4. The master sends an 8-bit register pointer.
- 5. The slave acknowledges the register pointer.
- 6. The master sends a data byte.
- 7. The slave acknowledges the data byte. The next rising edge on SDA loads the data byte into its target register and the data becomes active.
- 8. Steps 6 to 7 are repeated as many times as the master requires.
- 9. During the last acknowledge related clock pulse, the master can issue an acknowledge or a not acknowledge.
- 10. The master sends a stop condition (P) or a repeated start condition (Sr). Issuing a P ensures that the bus input filters are set for 1MHz or slower operation. Issuing an Sr leaves the bus input filters in their current state.

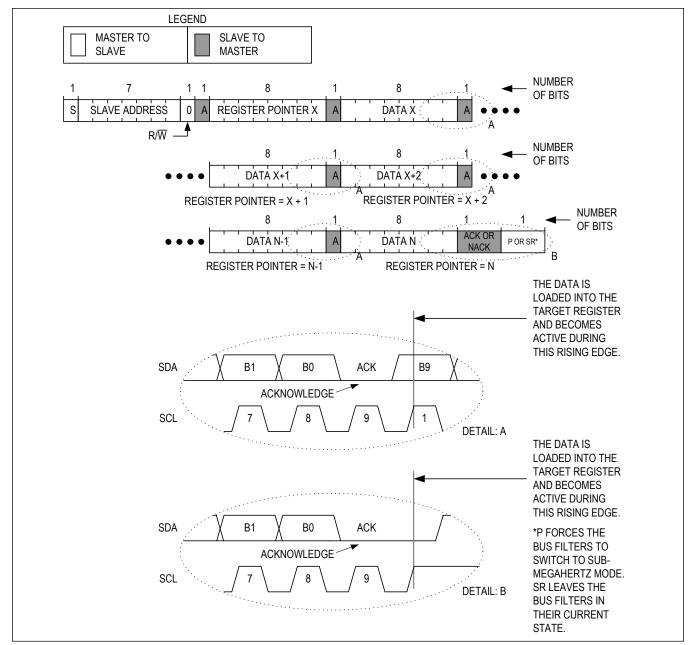


Figure 33. Writing to Sequential Registers X to N

#### Reading from a Single Register

Figure 34 shows the protocol for the  $I^2C$  master device to read one byte of data. This protocol is the same as the SMBus specification's read byte protocol.

The read byte protocol is as follows:

- 1. The master sends a start command (S).
- 2. The master sends the 7-bit slave address followed by a write bit (R/W = 0).
- 3. The addressed slave asserts an acknowledge (A) by pulling SDA low.
- 4. The master sends an 8-bit register pointer.
- 5. The slave acknowledges the register pointer.
- 6. The master sends a repeated start command (Sr).
- 7. The master sends the 7-bit slave address followed by a read bit (R/W = 1).
- 8. The addressed slave asserts an acknowledge by pulling SDA low.
- 9. The addressed slave places 8-bits of data on the bus from the location specified by the register pointer.
- 10. The master issues a not acknowledge (nA).
- 11. The master sends a stop condition (P) or a repeated start condition (Sr). Issuing a P ensures that the bus input filters are set for 1MHz or slower operation. Issuing an Sr leaves the bus input filters in their current state.

Note that when this device receives a stop, the register pointer is not modified. Therefore, if the master re-reads the same register, it can immediately send another read command, omitting the command to send a register pointer.

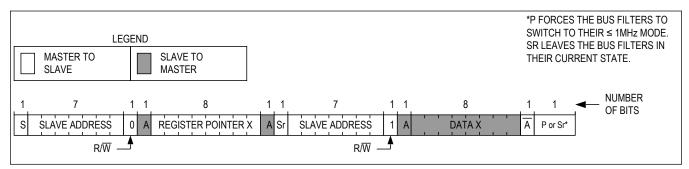


Figure 34. Reading from a Single Register with the Read Byte Protocol

#### **Reading from Sequential Registers**

<u>Figure 35</u> shows the protocol for reading from sequential registers. This protocol is similar to the read byte protocol except the master issues an acknowledge to signal the slave that it wants more data: when the master has all the data it requires it issues a not acknowledge (nA) and a stop (P) to end the transmission. The continuous read from sequential registers protocol is as follows:

- 1. The master sends a start command (S).
- 2. The master sends the 7-bit slave address followed by a write bit (R/W = 0).
- 3. The addressed slave asserts an acknowledge (A) by pulling SDA low.
- 4. The master sends an 8-bit register pointer.
- 5. The slave acknowledges the register pointer.
- 6. The master sends a repeated start command (Sr).
- 7. The master sends the 7-bit slave address followed by a read bit (R/W = 1).
- 8. The addressed slave asserts an acknowledge by pulling SDA low.
- 9. The addressed slave places 8-bits of data on the bus from the location specified by the register pointer.
- 10. The master issues an acknowledge (A) signaling the slave that it wishes to receive more data.
- 11. Steps 9 to 10 are repeated as many times as the master requires. Following the last byte of data, the master must issue a not acknowledge (nA) to signal that it wishes to stop receiving data.
- 12. The master sends a stop condition (P) or a repeated start condition (Sr). Issuing a stop (P) ensures that the bus input filters are set for 1MHz or slower operation. Issuing an Sr leaves the bus input filters in their current state.

Note that when this device receives a stop it does not modify its register pointer. Therefore, if the master re-reads the same register, it can immediately send another read command, omitting the command to send a register pointer.

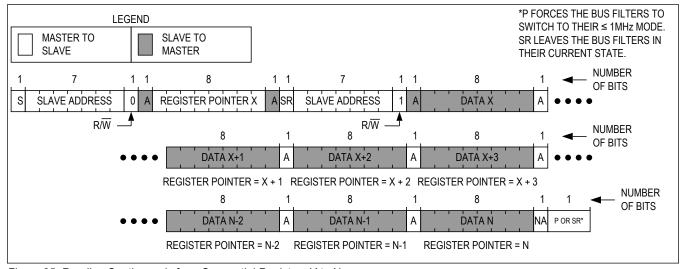


Figure 35. Reading Continuously from Sequential Registers X to N

#### Engaging HS-Mode for Operation up to 3.4MHz

<u>Figure 36</u> shows the protocol for engaging HS-mode operation. HS-mode operation allows for a bus operating speed up to 3.4MHz. The engaging HS-mode protocol is as follows:

- 1. Begin the protocol while operating at a bus speed of 1MHz or lower.
- 2. The master sends a start command (S).
- 3. The master sends the 8-bit master code of 0b0000 1XXX where 0bXXX are don't care bits.
- 4. The addressed slave issues a not acknowledge (nA).
- 5. The master may now increase its bus speed up to 3.4MHz and issue any read/write operation.

The master may continue to issue high-speed read/write operations until a stop (P) is issued. To continue operations in high-speed mode, use repeated start (Sr)

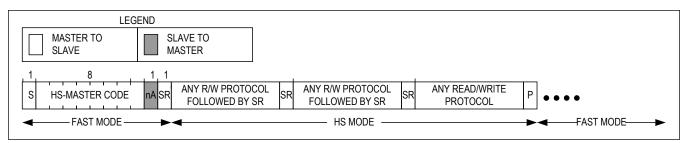


Figure 36. Engaging HS Mode

## **Register Map**

### **MAX77654**

ADDRESS	NAME	MSB							LSB
Global						<b>'</b>		1	
0x00	INT_GLBL0[7:0]	DOD0_R	DOD1_R	TJAL2_R	TJAL1_R	nEN_R	nEN_F	GPI0_R	GPI0_F
0x04	INT_GLBL1[7:0]	RSVD	LDO1_F	LDO0_F	SBB_TO	GPI2_R	GPI2_F	GPI1_R	GPI1_F
0x05	ERCFLAG[7:0]	WDT_R ST	WDT_O FF	SFT_CR ST_F	SFT_OF F_F	MRST	SYSUVL O	SYSOVL O	TOVLD
0x06	STAT_GLBL[7:0]	DIDM	вок	DOD0_S	DOD1_S	TJAL2_S	TJAL1_S	STAT_E N	STAT_IR Q
0x08	INTM_GLBL1[7:0]	RSVD	LDO1_M	LDO0_M	SBB_TO _M	GPI2_R M	GPI2_F M	GPI1_R M	GPI1_F M
0x09	INTM_GLBL0[7:0]	DOD0_R M	DOD1_R M	TJAL2_R M	TJAL1_R M	nEN_RM	nEN_FM	GPI0_R M	GPI0_F M
0x10	CNFG_GLBL[7:0]	PU_DIS	T_MRST	SBIA_LP M	SBIA_E N	nEN_MO DE	DBEN_n EN	SFT_C	ΓRL[1:0]
0x11	CNFG_GPIO0[7:0]	RSVD	_	ALT_GPI O0	DBEN_G PI	DO	DRV	DI	DIR
0x12	CNFG_GPIO1[7:0]	RSV	D[1:0]	ALT_GPI O1	DBEN_G PI	DO	DRV	DI	DIR
0x13	CNFG_GPIO2[7:0]	RSV	D[1:0]	ALT_GPI O2	DBEN_G PI	DO	DRV	DI	DIR
0x14	CID[7:0]	CID	_	_	_		CID	[3:0]	
0x17	CNFG_WDT[7:0]	RSV	D[1:0]	WDT_F	PER[1:0]	WDT_M ODE	WDT_CL R	WDT_E N	WDT_LO CK
			0	VERLAP					
Charger									
0x01	INT_CHG[7:0]	RSVD	SYS_CN FG_I	SYS_CT RL_I	CHGIN_ CTRL_I	TJ_REG _I	CHGIN_I	CHG_I	THM_I
0x02	STAT_CHG_A[7:0]	RSVD	VCHGIN _MIN_S TAT	ICHGIN_ LIM_STA T	VSYS_M IN_STAT	TJ_REG _STAT	TH	HM_DTLS[2	:0]
0x03	STAT_CHG_B[7:0]		CHG_D	TLS[3:0]		CHGIN_[	OTLS[1:0]	CHG	TIME_S US
0x07	INT_M_CHG[7:0]	RSVD	SYS_CN FG_M	SYS_CT RL_M	CHGIN_ CTRL_M	TJ_REG _M	CHGIN_ M	CHG_M	тнм_м
0x20	CNFG_CHG_A[7:0]	THM_F	OT[1:0]	THM_W	ARM[1:0]	THM_C	OOL[1:0]	THM_C	OLD[1:0]
0x21	CNFG_CHG_B[7:0]	VC	HGIN_MIN[	2:0]	IC	HGIN_LIM[2	2:0]	I_PQ	CHG_EN
0x22	CNFG_CHG_C[7:0]	(	CHG_PQ[2:0	0]	I_TER	M[1:0]	T_	TOPOFF[2	:0]
0x23	CNFG_CHG_D[7:0]		TJ_REG[2:0]			VS	SYS_REG[4	:0]	
0x24	CNFG_CHG_E[7:0]		CHG_CC[5:0]				T_FAST_	CHG[1:0]	
0x25	CNFG_CHG_F[7:0]			CHG_CC_	JEITA[5:0]			THM_EN	_
0x26	CNFG_CHG_G[7:0]			CHG_0	CV[5:0]			USBS	RSVD
0x27	CNFG_CHG_H[7:0]			CHG_CV_	JEITA[5:0]			RSVI	D[1:0]
0x28	CNFG_CHG_I[7:0]	IM	ON_DISCH	G_SCALE[3	3:0]		MUX_S	SEL[3:0]	

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

ADDRESS	NAME	MSB							LSB
SBB	SBB								
0x29	CNFG_SBB0_A[7:0]	-			Т	V_SBB0[6:0	0]		
0x2A	CNFG_SBB0_B[7:0]	RSVD	OP_MO DE	IP_SB	B0[1:0]	ADE_SB B0	E	N_SBB0[2:	0]
0x2B	CNFG_SBB1_A[7:0]	-			Т	V_SBB1[6:0	0]		
0x2C	CNFG_SBB1_B[7:0]	RSVD	OP_MO DE	IP_SB	B1[1:0]	ADE_SB B1	E	N_SBB1[2:	[[
0x2D	CNFG_SBB2_A[7:0]	_			Т	V_SBB2[6:0	0]		
0x2E	CNFG_SBB2_B[7:0]	RSVD	OP_MO DE         IP_SBB2[1:0]         ADE_SB B2         EN_SBB2[2:0]			0]			
0x2F	CNFG_SBB_TOP[7:0]	ICHGIN_ LIM_DE F	_	ı	_	_	_	DRV_S	BB[1:0]
LDO									
0x38	CNFG_LDO0_A[7:0]	RSVD			Т	V_LDO0[6:0	0]		
0x39	CNFG_LDO0_B[7:0]	_	- LD00_M ADE_LD EN_LD00[2:0]			[0]			
0x3A	CNFG_LDO1_A[7:0]	RSVD	TV_LDO1[6:0]						
0x3B	CNFG_LDO1_B[7:0]	_	_	_	LDO1_M D	ADE_LD O1	E	N_LDO1[2:	0]

### **Register Details**

### INT\_GLBL0 (0x00)

BIT	7	6	5	4	3	2	1	0
Field	DOD0_R	DOD1_R	TJAL2_R	TJAL1_R	nEN_R	nEN_F	GPI0_R	GPI0_F
Reset	0b0							
Access Type	Read Clears All							

BITFIELD	BITS	DESCRIPTION	DECODE
DOD0_R	7	LDO Dropout Detector Rising Interrupt	0 = The LDO has not detected dropout since the last time this bit was read. 1 = The LDO has detected dropout since the last time this bit was read.
DOD1_R	6	LDO Dropout Detector Rising Interrupt	0 = The LDO has not detected dropout since the last time this bit was read. 1 = The LDO has detected dropout since the last time this bit was read.
TJAL2_R	5	Thermal Alarm 2 Rising Interrupt	0 = The junction temperature has not risen above TJAL2 since the last time this bit was read. 1 = The junction temperature has risen above TJAL2 since the last time this bit was read.
TJAL1_R	4	Thermal Alarm 1 Rising Interrupt	0 = The junction temperature has not risen above TJAL1 since the last time this bit was read. 1 = The junction temperature has risen above TJAL1 since the last time this bit was read.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
nEN_R	3	nEN Rising Interrupt	0 = No nEN rising edges have occurred since the last time this bit was read. 1 = A nEN rising edge has occurred since the last time this bit was read.
nEN_F	2	nEN Falling Interrupt	0 = No nEN falling edges have occurred since the last time this bit was read. 1 = A nEN falling edge occurred since the last time this bit was read.
GPI0_R	1	GPI Rising Interrupt  Note that "GPI" refers to the GPIO programmed to be an input.	0 = No GPI rising edges have occurred since the last time this bit was read. 1 = A GPI rising edge has occurred since the last time this bit was read.
GPI0_F	0	GPI Falling Interrupt  Note that the GPI is the GPIO programmed to be an input.	0 = No GPI falling edges have occurred since the last time this bit was read. 1 = A GPI falling edge has occurred since the last time this bit was read.

### INT\_GLBL1 (0x04)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	LDO1_F	LDO0_F	SBB_TO	GPI2_R	GPI2_F	GPI1_R	GPI1_F
Reset	0b000	0b0						
Access Type	Read Clears All							

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
LDO1_F	6	LDO1 Fault Interrupt	0 = No fault has occurred on LDO1 since the last time this bit was read. 1 = LDO1 has fallen out of regulation since the last time this bit was read.
LDO0_F	5	LDO0 Fault Interrupt	0 = No fault has occurred on LDO0 since the last time this bit was read. 1 = LDO0 has fallen out of regulation since the last time this bit was read.
SBB_TO	4	SBB Timeout	0 = NO SBB timeout occurred since the last time this bit was read.     1 = SBB timeout occurred since the last time this bit was read.
GPI2_R	3	GPI Rising Interrupt  Note that "GPI" refers to the GPIO programmed to be an input.	0 = No GPI rising edges have occurred since the last time this bit was read. 1 = A GPI rising edge has occurred since the last time this bit was read.
GPI2_F	GPI Falling Interrupt		0 = No GPI falling edges have occurred since the last time this bit was read. 1 = A GPI falling edge has occurred since the last time this bit was read.
GPI1_R	1	GPI Rising Interrupt  Note that "GPI" refers to the GPIO programmed to be an input.	0 = No GPI rising edges have occurred since the last time this bit was read. 1 = A GPI rising edge has occurred since the last time this bit was read.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
GPI1_F	0	GPI Falling Interrupt  Note that the GPI is the GPIO programmed to be an input.	<ul> <li>0 = No GPI falling edges have occurred since the last time this bit was read.</li> <li>1 = A GPI falling edge has occurred since the last time this bit was read.</li> </ul>

### ERCFLAG (0x05)

BIT	7	6	5	4	3	2	1	0
Field	WDT_RST	WDT_OFF	SFT_CRST _F	SFT_OFF_ F	MRST	SYSUVLO	SYSOVLO	TOVLD
Reset	0b0							
Access Type	Read Clears All							

BITFIELD	BITS	DESCRIPTION	DECODE
WDT_RST	7	Watchdog Timer Reset Flag. This bit sets when the watchdog timer expires and causes a power-reset (WDT_MODE = 1).	0 = Watchdog timer has not caused a power-reset since the last time this bit was read. 1 = Watchdog timer has expired and caused a power-reset since the last time this bit was read.
WDT_OFF	6	Watchdog Timer OFF Flag. This bit sets when the watchdog timer expires and causes a power-off (WDT_MODE = 0).	0 = Watchdog timer has not caused a power-off since the last time this bit was read. 1 = Watchdog timer has expired and caused a power-off since the last time this bit was read.
SFT_CRST_ F	5	Software Cold Reset Flag	0 = The software cold reset has not occurred since the last read of this register. 1 = The software cold reset has occurred since the last read of this register. This indicates that software has set SFT_CTRL[1:0] = 0b01.
SFT_OFF_F	4	Software OFF Flag	0 = The SFT_OFF function has not occurred since the last read of this register. 1 = The SFT_OFF function has occurred since the last read of this register. This indicates that software has set SFT_CTRL[1:0] = 0b10.
MRST	3	Manual Reset Timer	<ul> <li>0 = A manual reset has not occurred since the last read of this register.</li> <li>1 = A manual reset has occurred since the last read of this register.</li> </ul>
SYSUVLO	2	SYS Domain Undervoltage Lockout	0 = The SYS domain undervoltage lockout has not occurred since the last read of this register. 1 = The SYS domain undervoltage lockout has occurred since the last read of this register. This indicates that the SYS domain voltage fell below VSYSUVLO (~2.4V)
SYSOVLO	1	SYS Domain Overvoltage Lockout	0 = The SYS domain overvoltage lockout has not occurred since the last read of this register. 1 = The SYS domain overvoltage lockout has occurred since the last read of this register. This indicates that the SYS domain voltage rose below VSYSOVLO (~5.85V)

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
TOVLD	0	Thermal Overload	0 = Thermal overload has not occurred since the last read of this register. 1 = Thermal overload has occurred since the last read of this register. This indicates that the junction temperature has exceeded 165°C.

### STAT GLBL (0x06)

BIT	7	6	5	4	3	2	1	0
Field	DIDM	BOK	DOD0_S	DOD1_S	TJAL2_S	TJAL1_S	STAT_EN	STAT_IRQ
Reset	OTP	0b1	0b0	0b0	0b0	0b0	0b0	0b0
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION	DECODE
DIDM	7	Device Identification Bits for Metal Options	0 = MAX77654 1 = Reserved
вок	6	BOK Interrupt Status	0 = Main bias is not ready. 1 = Main bias enabled and ready.
DOD0_S	5	LDO0 Dropout Detector Rising Status	0 = LDO0 is not in dropout. 1 = LDO0 is in dropout.
DOD1_S	4	LDO1 Dropout Detector Rising Status	0 = LDO1 is not in dropout. 1 = LDO1 is in dropout.
TJAL2_S	3	Thermal Alarm 2 Status	0 = The junction temperature is less than TJA2. 1 = The junction temperature is greater than TJAL2.
TJAL1_S	2	Thermal Alarm 1 Status	0 = The junction temperature is less than TJAL1. 1 = The junction temperature is greater than TJAL1.
STAT_EN	1	Debounced Status for the nEN Input	0 = nEN is not active (logic high). 1 = nEN is active (logic low).
STAT_IRQ	0	Software Version of the nIRQ MOSFET Gate Drive	0 = Unmasked gate drive is logic low. 1 = Unmasked gate drive is logic high.

#### INTM\_GLBL1 (0x08)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	LDO1_M	LDO0_M	SBB_TO_M	GPI2_RM	GPI2_FM	GPI1_RM	GPI1_FM
Reset	0b0	0b1						
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
LDO1_M	6	LDO1 Fault Interrupt Mask	0 = Unmasked. If LDO1_F goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to LDO1_F.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
LDO0_M	5	LDO0 Fault Interrupt Mask	0 = Unmasked. If LDO0_F goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to LDO0_F.
SBB_TO_M	4	SBB Timeout Mask	0 = Unmasked. If SBB_TO goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to SBB_TO.
GPI2_RM	3	GPI Rising Interrupt Mask	0 = Unmasked. If GPI_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to GPI_R.
GPI2_FM	2	GPI Falling Interrupt Mask	0 = Unmasked. If GPI_F goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to GPI_F.
GPI1_RM	1	GPI Rising Interrupt Mask	0 = Unmasked. If GPI_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to GPI_R.
GPI1_FM	0	GPI Falling Interrupt Mask	0 = Unmasked. If GPI_F goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to GPI_F.

### INTM GLBL0 (0x09)

BIT	7	6	5	4	3	2	1	0
Field	DOD0_RM	DOD1_RM	TJAL2_RM	TJAL1_RM	nEN_RM	nEN_FM	GPI0_RM	GPI0_FM
Reset	0b1							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION	DECODE
DOD0_RM	7	LDO Dropout Detector Rising Interrupt Mask	0 = Unmasked. If DOD0_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to DOD0_R.
DOD1_RM	6	LDO Dropout Detector Rising Interrupt Mask	0 = Unmasked. If DOD1_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to DOD1_R.
TJAL2_RM	5	Thermal Alarm 2 Rising Interrupt Mask	0 = Unmasked. If TJAL2_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to TJAL2_R.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
TJAL1_RM	4	Thermal Alarm 1 Rising Interrupt Mask	0 = Unmasked. If TJAL1_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to TJAL1_R.
nEN_RM	3	nEN Rising Interrupt Mask	0 = Unmasked. If nEN_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to nEN_R.
nEN_FM	2	nEN Falling Interrupt Mask	0 = Unmasked. If nEN_F goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to nEN_F.
GPI0_RM	1	GPI Rising Interrupt Mask	0 = Unmasked. If GPI_R goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to GPI_R.
GPI0_FM	0	GPI Falling Interrupt Mask	0 = Unmasked. If GPI_F goes from 0 to 1, then nIRQ goes low. nIRQ goes high when all interrupt bits are cleared. 1 = Masked. nIRQ does not go low due to GPI_F.

### CNFG\_GLBL (0x10)

BIT	7	6	5	4	3	2	1	0
Field	PU_DIS	T_MRST	SBIA_LPM	SBIA_EN	nEN_MODE	DBEN_nEN	SFT_C1	ΓRL[1:0]
Reset	0b0	OTP	OTP	0b0	OTP	OTP	0b	00
Access Type	Write, Read	Write,	Read					

BITFIELD	BITS	DESCRIPTION	DECODE
PU_DIS	7	nEN Internal Pullup Resistor	0 = Strong internal nEN pullup (200kΩ) 1 = Weak internal nEN pullup (10MΩ)
T_MRST	6	Sets the Manual Reset Time (t <sub>MRST</sub> )	0 = 8s 1 = 16s
SBIA_LPM	5	Main Bias Low-Power Mode Software Request	0 = Main bias requested to be in normal-power mode by software.     1 = Main bias request to be in low-power mode by software.
SBIA_EN	4	Main Bias Enable Software Request	0 = Main bias not enabled by software. Note that the main bias can be enabled by the on/off controller. 1 = Main bias force enabled by software.
nEN_MODE	3	nEN Input (ON-KEY) Default Configuration Mode	0 = Push-button mode 1 = Slide-switch mode
DBEN_nEN	2	Debounce Timer Enable for the nEN Pin	0 = 500μs Debounce 1 = 30ms Debounce

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
SFT_CTRL	1:0	Software Reset Functions  Note that the SFT_CRST and SFT_OFF commands initiate the power-down sequence flow as described in the data sheet. This power-down sequence flow has delay elements that add up to 205.24ms (60ms delay + 10.24ms nRST assert delay + 4x2.56ms power-down slot delays + 125ms output discharge delay). If issuing the SFT_CRST and/or SFT_OFF functions in software, wait for more than 300ms before trying to issue any additional commands through I <sup>2</sup> C.	0b00 = No action 0b01 = Software cold reset (SFT_CRST). The device powers down, resets, and then powers up again. 0b10 = Software off (SFT_OFF). The device powers down, resets, and then remains off and waiting for a wake-up event. 0b11 = Factory-ship mode enter (FSM). The IC powers down, configuration registers reset, and the internal BATT to SYS switch opens. The device remains this way until a factory-ship mode exit event occurs.

### CNFG\_GPIO0 (0x11)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	_	ALT_GPIO0	DBEN_GPI	DO	DRV	DI	DIR
Reset	0b0	_	OTP	0b0	0b0	0b0	0b0	0b1
Access Type	Write, Read	_	Write, Read	Write, Read	Write, Read	Write, Read	Read Only	Write, Read

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
ALT_GPIO0	5	Alternate Mode Enable for GPIO0	0 = Standard GPIO. 1 = Flexible power sequencer active-high output for SBB2.
DBEN_GPI	4	General Purpose Input Debounce Timer Enable	0 = No debounce 1 = 30ms Debounce
DO	3	General Purpose Output Data Output	This bit is a don't care when DIR = 1 (configured as input).  When set for GPO (DIR = 0): 0 = GPIO is output logic low. 1 = GPIO is output logic high when set as pushpull output (DRV = 1). GPIO is high-impedance when set as an open-drain output (DRV = 0).
DRV	2	General Purpose Output Driver Type	This bit is a don't care when DIR = 1 (configured as input).  When set for GPO (DIR = 0): 0 = Open-drain 1 = Push-pull
DI	1	GPIO Digital Input Value. Irrespective of whether the GPIO is set for GPI (DIR = 1) or GPO (DIR = 0), DI reflects the state of the GPIO.	0 = Input logic low 1 = Input logic high
DIR	0	GPIO Direction	0 = General purpose output (GPO) 1 = General purpose input (GPI)

#### CNFG\_GPIO1 (0x12)

BIT	7	6	5	4	3	2	1	0
Field	RSVD[1:0]		ALT_GPIO1	DBEN_GPI	DO	DRV	DI	DIR
Reset	0b00		OTP	0b0	0b0	0b0	0b0	0b1
Access Type	Write, Read		Write, Read	Write, Read	Write, Read	Write, Read	Read Only	Write, Read

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7:6	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
ALT_GPIO1	5	Alternate Mode Enable for GPIO1	0 = Standard GPIO 1 = SBB2 Enable
DBEN_GPI	4	General Purpose Input Debounce Timer Enable	0 = No debounce 1 = 30ms Debounce
DO	3	General Purpose Output Data Output	This bit is a don't care when DIR = 1 (configured as input).  When set for GPO (DIR = 0): 0 = GPIO is output logic low. 1 = GPIO is output logic high when set as pushpull output (DRV = 1). GPIO is high-impedance when set as an open-drain output (DRV = 0).
DRV	2	General Purpose Output Driver Type	This bit is a don't care when DIR = 1 (configured as input).  When set for GPO (DIR = 0): 0 = Open-drain 1 = Push-pull
DI	1	GPIO Digital Input Value. Irrespective of whether the GPIO is set for GPI (DIR = 1) or GPO (DIR = 0), DI reflects the state of the GPIO.	0 = Input logic low 1 = Input logic high
DIR	0	GPIO Direction	0 = General purpose output (GPO) 1 = General purpose input (GPI)

### CNFG\_GPIO2 (0x13)

BIT	7	6	5	4	3	2	1	0
Field	RSVD[1:0]		ALT_GPIO2	DBEN_GPI	DO	DRV	DI	DIR
Reset	0b00		OTP	0b0	0b0	0b0	0b0	0b1
Access Type	Write, Read		Write, Read	Write, Read	Write, Read	Write, Read	Read Only	Write, Read

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7:6	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
ALT_GPIO2	5	Alternate Mode Enable for GPIO2.	0 = Standard GPIO 1 = Bias LPM mode enable
DBEN_GPI	4	General Purpose Input Debounce Timer Enable	0 = No debounce 1 = 30ms Debounce

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
DO	3	General Purpose Output Data Output	This bit is a don't care when DIR = 1 (configured as input).  When set for GPO (DIR = 0): 0 = GPIO is output logic low. 1 = GPIO is output logic high when set as pushpull output (DRV = 1). GPIO is high-impedance when set as an open-drain output (DRV = 0).
DRV	2	General Purpose Output Driver Type	This bit is a don't care when DIR = 1 (configured as input).  When set for GPO (DIR = 0): 0 = Open-drain 1 = Push-pull
DI	1	GPIO Digital Input Value. Irrespective of whether the GPIO is set for GPI (DIR = 1) or GPO (DIR = 0), DI reflects the state of the GPIO.	0 = Input logic low 1 = Input logic high
DIR	0	GPIO Direction	0 = General purpose output (GPO) 1 = General purpose input (GPI)

### CID (0x14)

BIT	7	6	5	4	3	2	1	0
Field	CID	_	_	_	CID[3:0]			
Reset	OTP	-	_	_	ОТР			
Access Type	Read Only	_	_	_	Read Only			

BITFIELD	BITS	DESCRIPTION
CID	7	Bit 4 of the Chip Identification Code The chip identification code refers to a set of reset values in the register map, or the "OTP configuration."
CID	3:0	Bits 0 to 3 of the Chip Identification Code The chip identification code refers to a set of reset values in the register map, or the "OTP configuration."

## CNFG\_WDT (0x17)

BIT	7	6	5	4	3	2	1	0
Field	RSVD[1:0]		WDT_PER[1:0]		WDT_MOD E	WDT_CLR	WDT_EN	WDT_LOC K
Reset	0b	00	0b11		0b0	0b0	OTP	OTP
Access Type	Write,	Read	Write, Read		Write, Read	Write, Read	Write, Read	Read Only

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7:6	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
WDT_PER	5:4	Watchdog Timer Period. Sets t <sub>WD</sub> . Watchdog timer is reset to the programmed value as soon as this bitfield is changed.	0b00 = 16 seconds 0b01 = 32 seconds 0b10 = 64 seconds 0b11 = 128 seconds

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
WDT_MODE	3	Watchdog Timer Expired Action. Determines what the IC does after the watchdog timer expires.	0 = Watchdog timer expire causes power-off. 1 = Watchdog timer expire causes power-reset.
WDT_CLR	2	Watchdog Timer Clear Control. Set this bit to feed (reset) the watchdog timer.	0 = Watchdog timer period is not reset. 1 = Watchdog timer is reset back to t <sub>WD</sub> .
WDT_EN	1	Watchdog Timer Enable. Write protected depending on WDT_LOCK.	0 = Watchdog timer is not enabled. 1 = Watchdog timer is enabled. The timer expires if not reset by setting WDT_CLR.
WDT_LOCK	0	Factory-Set Safety Bit for the Watchdog Timer. Determines if the timer can be disabled through WDT_EN or not.	0 = Watchdog timer can be enabled and disabled with WDT_EN. 1 = Watchdog timer can not be disabled with WDT_EN. However, WDT_EN can still be used to enable the watchdog timer.

### INT\_CHG (0x01)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	SYS_CNFG _I	SYS_CTRL _I	CHGIN_CT RL_I	TJ_REG_I	CHGIN_I	CHG_I	THM_I
Reset	0b0							
Access Type	Read Clears All							

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
SYS_CNFG_	6	System Voltage Configuration Error Interrupt	0 = The bit combination in CHG_CV has not been forced to change since the last time this bit was read. 1 = The bit combination in CHG_CV has been forced to change to ensure V <sub>SYS-REG</sub> = V <sub>FAST-CHG</sub> + 200mV since the last time this bit was read.
SYS_CTRL_I	5	Minimum System Voltage Regulation-Loop Related Interrupt. This interrupt signals a change in the status bit VSYS_MIN_STAT.	0 = The minimum system voltage regulation loop has not engaged since the last time this bit was read.     1 = The minimum system voltage regulation loop has engaged since the last time this bit was read.
CHGIN_CTR L_I	4	CHGIN Control-Loop Related Interrupt. This bit asserts when the input reaches current limit (I <sub>CHGIN-LIM</sub> ) or V <sub>CHGIN</sub> falls below V <sub>CHGIN_MIN</sub> .	0 = Neither the VCHGIN_MIN_STAT nor the ICHGIN_LIM_STAT bits have changed since the last time this bit was read. 1 = The VCHGIN_MIN_STAT or ICHGIN_LIM_STAT bits have changed since the last time this bit was read.
TJ_REG_I	3	Die Junction Temperature Regulation Interrupt. This bit asserts when the die temperature (T <sub>J</sub> ) exceeds T <sub>J-REG</sub> . This interrupt signals a change in the status bit TJ_REG_STAT.	0 = The die temperature has not exceeded T <sub>J-REG</sub> since the last time this bit was read. 1 = The die temperature has exceeded T <sub>J-REG</sub> since the last time this bit was read.
CHGIN_I	2	CHGIN Related Interrupt	0 = The bits in CHGIN_DTLS[1:0] have not changed since the last time this bit was read. 1 = The bits in CHGIN_DTLS[1:0] have changed since the last time this bit was read.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_I	1	Charger Related Interrupt	0 = The bits in CHG_DTLS[3:0] have not changed since the last time this bit was read. 1 = The bits in CHG_DTLS[3:0] have changed since the last time this bit was read.
тнм_і	0	Thermistor Related Interrupt	0 = The bits in THM_DTLS[2:0] have not changed since the last time this bit was read. 1 = The bits in THM_DTLS[2:0] have changed since the last time this bit was read.

### STAT\_CHG\_A (0x02)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	VCHGIN_M IN_STAT	ICHGIN_LI M_STAT	VSYS_MIN _STAT	TJ_REG_S TAT	THM_DTLS[2:0]		
Reset	0b0	0b0	0b0	0b0	0b0	0b000		
Access Type	Read Only	Read Only	Read Only	Read Only	Read Only		Read Only	

BITFIELD	BITS	DESCRIPTION	DECODE		
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.			
VCHGIN_MI N_STAT	6	Minimum Input Voltage Regulation Loop Status	<ul> <li>0 = The minimum CHGIN voltage regulation loop is not engaged.</li> <li>1 = The minimum CHGIN voltage regulation loop has engaged to regulate V<sub>CHGIN</sub> ≥ V<sub>CHGIN-MIN</sub>.</li> </ul>		
ICHGIN_LIM _STAT	5	Input Current Limit Loop Status	0 = The CHGIN current limit loop is not engaged. 1 = The CHGIN current limit loop has engaged to regulate I <sub>CHGIN</sub> ≤ I <sub>CHGIN-LIM</sub> .		
VSYS_MIN_ STAT	4	Minimum System Voltage Regulation Loop Status	<ul> <li>0 = The minimum system voltage regulation loop is not enganged.</li> <li>1 = The minimum system voltage regulation loop is engaged to regulate V<sub>SYS</sub> ≥ V<sub>SYS-MIN</sub>.</li> </ul>		
TJ_REG_ST AT	3	Maximum Junction Temperature Regulation Loop Status	0 = The maximum junction temperature regulation loop is not engaged. 1 = The maximum junction temperature regulation loop has engaged to regulate the junction temperature to less than T <sub>J-REG</sub> .		
THM_DTLS	2:0	Battery Temperature Details. Valid only when CHGIN_DTLS[1:0] = 0b11.	0b000 = Thermistor is disabled (THM_EN = 0). 0b001 = Battery is cold as programmed by THM_COLD[1:0]. If thermistor and charger are enabled while the battery is cold, a battery temperature fault occurs. 0b010 = Battery is cool as programmed by THM_COOL[1:0]. 0b011 = Battery is warm as programmed by THM_WARM[1:0]. 0b100 = Battery is hot as programmed by THM_HOT[1:0]. If thermistor and charger are enabled while the battery is hot, a battery temperature fault occurs. 0b101 = Battery is in the normal temperature region. 0b110 to 0b111 = Reserved.		

#### STAT\_CHG\_B (0x03)

BIT	7	6	5	4	3	2	1	0
Field		CHG_D	TLS[3:0]		CHGIN_[	OTLS[1:0]	CHG	TIME_SUS
Reset		0:	<b>k</b> 0		0b	00	0b0	0b0
Access Type		Read Only				Only	Read Only	Read Only

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_DTLS	7:4	Charger Details	0b0000 = Off 0b0001 = Prequalification mode. 0b0010 = Fast-charge constant-current (CC) mode. 0b0011 = JEITA modified fast-charge constant- current mode. 0b0100 = Fast-charge constant-voltage (CV) mode. 0b0101 = JEITA modified fast-charge constant- voltage mode. 0b0110 = Top-off mode. 0b0111 = JEITA modified top-off mode. 0b1000 = Done 0b1001 = JEITA modified done (done was entered through the JEITA-modified fast-charge states). 0b1010 = Prequalification timer fault. 0b1011 = Fast-charge timer fault. 0b1100 = Battery temperature fault. 0b1101 to 0b1111 = Reserved.
CHGIN_DTL S	3:2	CHGIN Status Detail	0b00 = The CHGIN input voltage is below the UVLO threshold (V <sub>CHGIN</sub> < V <sub>UVLO</sub> ). 0b01 = The CHGIN input voltage is above the OVP threshold (V <sub>CHGIN</sub> > V <sub>OVP</sub> ). 0b10 = The CHGIN input is being debounced (no power accepted from CHGIN during debounce). 0b11 = The CHGIN input is okay and debounced.
CHG	1	Quick Charger Status	0 = Charging is not happening. 1 = Charging is happening.
TIME_SUS	0	Time Suspend Indicator	0 = The charger's timers are either not active, or not suspended. 1 = The charger's active timer is suspended due to one of three reasons: charge current dropped below 20% of I <sub>FAST-CHG</sub> while the charger state machine is in FAST CHARGE CC mode, the charger is in SUPPLEMENT mode, or the charger state machine is in BATTERY TEMPERATURE FAULT mode.

### **INT M CHG (0x07)**

BIT	7	6	5	4	3	2	1	0
Field	RSVD	SYS_CNFG _M	SYS_CTRL _M	CHGIN_CT RL_M	TJ_REG_M	CHGIN_M	CHG_M	THM_M
Reset	0b1	0b1	0b1	0b1	0b1	0b1	0b1	0b1
Access Type	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
SYS_CNFG_ M	6	Setting this bit prevents the SYS_CNFG_I bit from causing hardware IRQs.	0 = SYS_CNFG_I is not masked. 1 = SYS_CNFG_I is masked.
SYS_CTRL_ M	5	Setting this bit prevents the SYS_CTRL_I bit from causing hardware IRQs.	0 = SYS_CTRL_I is not masked. 1 = SYS_CTRL_I is masked.
CHGIN_CTR L_M	4	Setting this bit prevents the CHGIN_CTRL_I bit from causing hardware IRQs.	0 = CHGIN_CTRL_I is not masked. 1 = CHGIN_CTRL_I is masked.
TJ_REG_M	3	Setting this bit prevents the TJREG_I bit from causing hardware IRQs.	0 = TJREG_I is not masked. 1 = TJREG_I is masked.
CHGIN_M	2	Setting this bit prevents the CHGIN_I bit from causing hardware IRQs.	0 = CHGIN_I is not masked. 1 = CHGIN_I is masked.
СНG_M	1	Setting this bit prevents the CHG_I bit from causing hardware IRQs.	0 = CHG_I is not masked. 1 = CHG_I is masked.
тнм_м	0	Setting this bit prevents the THM_I bit from causing hardware IRQs.	0 = THM_I is not masked. 1 = THM_I is masked.

#### CNFG CHG A (0x20)

BIT	7	6	5	4	3	2	1	0
Field	THM_HOT[1:0]		THM_WARM[1:0]		THM_COOL[1:0]		THM_COLD[1:0]	
Reset	0b00		0b00		0b11		0b11	
Access Type	Write, Read		Write, Read		Write, Read		Write,	Read

BITFIELD	BITS	DESCRIPTION	DECODE
тнм_нот	7:6	Sets the V <sub>HOT</sub> JEITA Temperature Threshold	$\begin{array}{l} 0b00 = V_{HOT} = 0.411V \; (45^{\circ}\text{C for } \beta = 3380\text{K}) \\ 0b01 = V_{HOT} = 0.367V \; (50^{\circ}\text{C for } \beta = 3380\text{K}) \\ 0b10 = V_{HOT} = 0.327V \; (55^{\circ}\text{C for } \beta = 3380\text{K}) \\ 0b11 = V_{HOT} = 0.291V \; (60^{\circ}\text{C for } \beta = 3380\text{K}) \\ \end{array}$
THM_WARM	5:4	Sets the V <sub>WARM</sub> JEITA Temperature Threshold	0b00 = $V_{WARM}$ = 0.511V (35°C for $\beta$ = 3380K) 0b01 = $V_{WARM}$ = 0.459V (40°C for $\beta$ = 3380K) 0b10 = $V_{WARM}$ = 0.411V (45°C for $\beta$ = 3380K) 0b11 = $V_{WARM}$ = 0.367V (50°C for $\beta$ = 3380K)
THM_COOL	3:2	Sets the V <sub>COOL</sub> JEITA Temperature Threshold	$\begin{array}{l} 0b00 = V_{COOL} = 0.923V \; (0^{\circ}\text{C for } \beta = 3380\text{K}) \\ 0b01 = V_{COOL} = 0.867V \; (5^{\circ}\text{C for } \beta = 3380\text{K}) \\ 0b10 = V_{COOL} = 0.807V \; (10^{\circ}\text{C for } \beta = 3380\text{K}) \\ 0b11 = V_{COOL} = 0.747V \; (15^{\circ}\text{C for } \beta = 3380\text{K}) \end{array}$
THM_COLD	1:0	Sets the V <sub>COLD</sub> JEITA Temperature Threshold	0b00 = $V_{COLD}$ = 1.024V (-10°C for $\beta$ = 3380K) 0b01 = $V_{COLD}$ = 0.976V (-5°C for $\beta$ = 3380K) 0b10 = $V_{COLD}$ = 0.923V (0°C for $\beta$ = 3380K) 0b11 = $V_{COLD}$ = 0.867V (5°C for $\beta$ = 3380K)

### CNFG\_CHG\_B (0x21)

BIT	7	6	5	4	3	2	1	0
Field	VCHGIN_MIN[2:0]			ICHGIN_LIM[2:0]			I_PQ	CHG_EN
Reset	0b000			0b000			0b0	OTP
Access Type		Write, Read		Write, Read			Write, Read	Write, Read

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
VCHGIN_MI N	7:5	Minimum CHGIN Regulation Voltage (VCHGIN-MIN)	0b000 = 4.0V 0b001 = 4.1V 0b010 = 4.2V 0b011 = 4.3V 0b100 = 4.4V 0b101 = 4.5V 0b110 = 4.6V 0b111 = 4.7V
ICHGIN_LIM	4:2	CHGIN Input Current Limit (I <sub>CHGIN-LIM</sub> )	When CNFG_SBB_TOP.ICHGIN_LIM_DEF = 0: 0b000 = 95mA 0b001 = 190mA 0b010 = 285mA 0b011 = 380mA 0b100 = 475mA 0b101 to 0b111 = Reserved. Defaults to 0b100. When CNFG_SBB_TOP.ICHGIN_LIM_DEF = 1, the above list is reversed.
I_PQ	1	Sets the prequalification charge current (I <sub>PQ</sub> ) as a percentage of I <sub>FAST-CHG</sub> .	0 = 10% 1 = 20%
CHG_EN	0	Charger Enable	0 = The battery charger is disabled. 1 = The battery charger is enabled.

### CNFG\_CHG\_C (0x22)

BIT	7	6	5	4	3	2	1	0
Field	CHG_PQ[2:0]			I_TER	M[1:0]	T_TOPOFF[2:0]		
Reset	0b111			0b	11	0b000		
Access Type		Write, Read		Write,	Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_PQ	7:5	Battery Prequalification Voltage Threshold (V <sub>PQ</sub> )	0b000 = 2.3V 0b001 = 2.4V 0b010 = 2.5V 0b011 = 2.6V 0b100 = 2.7V 0b101 = 2.8V 0b110 = 2.9V 0b111 = 3.0V
I_TERM	4:3	Charger Termination Current (I <sub>TERM</sub> ). I_TERM[1:0] sets the charger termination current as a percentage of the fast-charge current I <sub>FAST-CHG</sub> .	00 = 5% 01 = 7.5% 10 = 10% 11 = 15%
T_TOPOFF	2:0	Top-Off Timer Value (t <sub>TO</sub> )	0b000 = 0 minutes 0b001 = 5 minutes 0b010 = 10 minutes 0b011 = 15 minutes 0b100 = 20 minutes 0b101 = 25 minutes 0b110 = 30 minutes 0b111 = 35 minutes

#### CNFG\_CHG\_D (0x23)

BIT	7	6	5	4	3	2	1	0		
Field		TJ_REG[2:0]		VSYS_REG[4:0]						
Reset		0b000		0b10000						
Access Type		Write, Read				Write, Read				

BITFIELD	BITS	DESCRIPTION	DECODE
TJ_REG	7:5	Sets the die junction temperature regulation point, T <sub>J-REG</sub> .	0b000 = 60°C 0b001 = 70°C 0b010 = 80°C 0b011 = 90°C 0b100 to 0b111 = 100°C
VSYS_REG	4:0	System Voltage Regulation (V <sub>SYS-REG</sub> )  This 5-bit configuration is a linear transfer function that starts at 4.1V and ends at 4.8V, with 25mV increments.	0x0 = 4.100V 0x1 = 4.125V 0x2 = 4.150V 
		Program V <sub>SYS_REG</sub> to at least 200mV above the higher of V <sub>FAST-CHG</sub> and V <sub>FAST-CHG</sub> - JEITA·	0x1B = 4.775V 0x1C - 0x1F = 4.800V

#### CNFG CHG E (0x24)

BIT	7	6	5	4	3	2	1	0
Field			T_FAST_CHG[1:0]					
Reset		0b000001 0b01						
Access Type			Write,	Read			Write,	Read

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_CC	7:2	Sets the fast-charge constant current value, IFAST-CHG- This 6-bit configuration is a linear transfer function that starts at 7.5mA and ends at 300mA, with 7.5mA increments.	0x0 = 7.5mA 0x1 = 15.0mA 0x2 = 22.5mA  0x26 = 292.5mA 0x27 to 0x3F = 300.0mA
T_FAST_CH G	1:0	Sets the fast-charge safety timer, t <sub>FC</sub> .	0b00 = Timer disabled 0b01 = 3 hours 0b10 = 5 hours 0b11 = 7 hours

### CNFG CHG F (0x25)

BIT	7	6	5	4	3	2	1	0	
Field		THM_EN	_						
Reset		0b000001							
Access Type			Write,	Read			Write, Read	_	

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_CC_JE ITA	7:2	Sets I <sub>FAST-CHG-JEITA</sub> for when the battery is either cool or warm as defined by the V <sub>COOL</sub> and V <sub>WARM</sub> temperature thresholds. This register is a don't care if the battery temperature is normal.  This 6-bit configuration is a linear transfer function that starts at 7.5mA and ends at 300mA, with 7.5mA increments.	0x0 = 7.5mA 0x1 = 15.0mA 0x2 = 22.5mA  0x26 = 292.5mA 0x27 to 0x3F = 300.0mA
		Journal, With 7.3HA increments.	0 = Thermistor is disabled.
THM_EN	1	Thermistor Enable Bit	1 = Thermistor is enabled.
			Note that the thermistor is powered by the charger input.

### CNFG CHG G (0x26)

BIT	7	6	5	4	3	2	1	0
Field		USBS	RSVD					
Reset			0b0	0b0				
Access Type			Write,	Read			Write, Read	Write, Read

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_CV	7:2	Sets fast-charge battery regulation voltage, VFAST-CHG-  This 6-bit configuration is a linear transfer function that starts at 3.6V and ends at 4.6V, with 25mV increments.  Program V <sub>SYS_REG</sub> to at least 200mV above the higher of V <sub>FAST-CHG</sub> and V <sub>FAST-CHG-JEITA</sub> .	0x0 = 3.600V 0x1 = 3.625V 0x2 = 3.650V  0x27 = 4.575V 0x28 to 0x3F = 4.600V
USBS	1	Setting this bit places CHGIN in USB suspend mode.	0 = CHGIN is not suspended and may draw current from an adapter source. 1 = CHGIN is suspended and may not draw current from an adapter source.  Note: USBS = 1 results in CHGIN_I interrupt AND CHGIN_DTLS[1:0] = 0b00.
RSVD	0	Reserved. Unutilized bit. Write to 0. Reads are don't care.	

### CNFG CHG H (0x27)

BIT	7	6	5	4	3	2	1	0
Field		RSVD[1:0]						
Reset	0b000000 0b00							
Access Type		Write, Read						Read

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
CHG_CV_JE ITA	7:2	Sets the modified V <sub>FAST-CHG-JEITA</sub> for when the battery is either cool or warm as defined by the V <sub>COOL</sub> and V <sub>WARM</sub> temperature thresholds. This register is a don't care if the battery temperature is normal.  This 6-bit configuration is a linear transfer function that starts at 3.6V and ends at 4.6V, with 25mV increments.  Program V <sub>SYS_REG</sub> to at least 200mV above the higher of V <sub>FAST-CHG</sub> and V <sub>FAST-CHG-JEITA</sub> .	0x0 = 3.600V 0x1 = 3.625V 0x2 = 3.650V  0x27 = 4.575V 0x28 to 0x3F = 4.600V
RSVD	1:0	Reserved. Unutilized bit. Write to 0. Reads are don't care.	

### CNFG\_CHG\_I (0x28)

BIT	7	6	5	4	3	2	1	0	
Field		IMON_DISCH	G_SCALE[3:0]		MUX_SEL[3:0]				
Reset		0>	¢ <b>F</b>		0x0				
Access Type		Write,	Read			Write,	Read		

BITFIELD	BITS	DESCRIPTION	DECODE
IMON_DISC HG_SCALE	7:4	Selects the battery discharge current full- scale current value.	0x0 = 8.2mA 0x1 = 40.5mA 0x2 = 72.3mA 0x3 = 103.4mA 0x4 = 134.1mA 0x5 = 164.1mA 0x6 = 193.7mA 0x7 = 222.7mA 0x8 = 251.2mA 0x9 = 279.3mA 0xA to 0xF = 300.0mA
MUX_SEL	3:0	Selects the analog channel to connect to AMUX:  Note that the multiplexer consumes current unless it is in the 0b0000 state. When measurements are not needed, make sure to configure MUX_SEL[3:0] = 0b0000.  Also note that for AMUX to operate, the on/off controller must be in the "Resource On" state.	0b0000 = Multiplexer is disabled and AMUX is high-impedance. 0b0001 = CHGIN voltage monitor. 0b0010 = CHGIN current monitor. 0b0011 = BATT voltage monitor. 0b0100 = BATT charge current monitor. Valid only while battery charging is happening (CHG = 1). 0b0101 = BATT discharge current monitor normal measurement. 0b0110 = BATT discharge current monitor nulling measurement. 0b0111 = THM voltage monitor. 0b1000 = TBIAS voltage monitor. 0b1001 = AGND voltage monitor (through 100Ω pulldown resistor). 0b1010 to 0b1111 = SYS voltage monitor.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

#### CNFG\_SBB0\_A (0x29)

BIT	7	6	5	4	3	2	1	0	
Field	_		TV_SBB0[6:0]						
Reset	_		OTP						
Access Type	_				Write, Read				

BITFIELD	BITS	DESCRIPTION	DECODE
TV_SBB0	6:0	SIMO Buck-Boost Channel 0 Target Output Voltage This 7-bit configuration is a linear transfer function that starts at 0.8V, ends at 5.5V, with 50mV increments.	0x00 = 0.800V 0x01 = 0.850V 0x02 = 0.900V 0x03 = 0.950V 0x04 = 1.000V 0x05 = 1.050V 0x06 = 1.100V 0x5C = 5.400V 0x5D = 5.450V 0x5E = 5.500V 0x5F to 0x7F = Reserved

### CNFG SBB0 B (0x2A)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	OP_MODE	IP_SBB0[1:0]		ADE_SBB0	EN_SBB0[2:0]		
Reset	0b0	OTP	0	OTP		OTP		
Access Type	Write, Read	Write, Read	Write,	Read	Write, Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
OP_MODE	6	Operation Mode of SBB0	0 = Buck-boost mode 1 = Buck mode
IP_SBB0	5:4	SIMO Buck-Boost Channel 0 Peak Current Limit	0b00 = 1.000A 0b01 = 0.750A 0b10 = 0.500A 0b11 = 0.333A
ADE_SBB0	3	SIMO Buck-Boost Channel 0 Active- Discharge Enable	0 = The active discharge function is disabled. When SBB0 is disabled, its discharge rate is a function of the output capacitance and the external load.  1 = The active discharge function is enabled. When SBB0 is disabled, an internal resistor (R <sub>AD SBB0</sub> ) is activated from SBB0 to PGND to help the output voltage discharge. The output voltage discharge rate is a function of the output capacitance, the external loading, and the internal R <sub>AD SBB0</sub> load.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
EN_SBB0	2:0	Enable Control for SIMO Buck-Boost Channel 0, selecting either an FPS slot the channel powers-up and powers-down in or whether the channel is forced on or off.	0b000 = FPS slot 0 0b001 = FPS slot 1 0b010 = FPS slot 2 0b011 = FPS slot 3 0b100 = Off irrespective of FPS 0b101 = Same as 0b100 0b110 = On irrespective of FPS 0b111 = Same as 0b110

### CNFG\_SBB1\_A (0x2B)

BIT	7	6	5	4	3	2	1	0
Field	_		TV_SBB1[6:0]					
Reset	_		OTP					
Access Type	_		Write, Read					

BITFIELD	BITS	DESCRIPTION	DECODE
TV_SBB1	6:0	SIMO Buck-Boost Channel 1 Target Output Voltage This 7-bit configuration is a linear transfer function that starts at 0.8V, ends at 5.5V, with 50mV increments.	0x00 = 0.800V 0x01 = 0.850V 0x02 = 0.900V 0x03 = 0.950V 0x04 = 1.000V 0x05 = 1.050V 0x06 = 1.100V  0x5C = 5.400V 0x5D = 5.450V 0x5E = 5.500V 0x5F to 0x7F = Reserved

#### CNFG SBB1 B (0x2C)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	OP_MODE	IP_SBB1[1:0]		ADE_SBB1	EN_SBB1[2:0]		
Reset	0b0	OTP	OTP		OTP		OTP	
Access Type	Write, Read	Write, Read	Write, Read		Write, Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
OP_MODE	6	Operation Mode of SBB1	0 = Buck-boost mode 1 = Buck mode
IP_SBB1	5:4	SIMO Buck-Boost Channel 1 Peak Current Limit	0b00 = 1.000A 0b01 = 0.750A 0b10 = 0.500A 0b11 = 0.333A

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
ADE_SBB1	3	SIMO Buck-Boost Channel 1 Active- Discharge Enable	0 = The active discharge function is disabled. When SBB1 is disabled, its discharge rate is a function of the output capacitance and the external load.  1 = The active discharge function is enabled. When SBB1 is disabled, an internal resistor (R <sub>AD_SBB1</sub> ) is activated from SBB1 to PGND to help the output voltage discharge. The output voltage discharge rate is a function of the output capacitance, the external loading, and the internal R <sub>AD_SBB1</sub> load.
EN_SBB1	2:0	Enable control for SIMO buck-boost channel 1, selecting either an FPS slot the channel powers-up and powers-down in or whether the channel is forced on or off.	0b000 = FPS slot 0 0b001 = FPS slot 1 0b010 = FPS slot 2 0b011 = FPS slot 3 0b100 = Off irrespective of FPS 0b101 = Same as 0b100 0b110 = On irrespective of FPS 0b111 = Same as 0b110

#### CNFG\_SBB2\_A (0x2D)

BIT	7	6	5	4	3	2	1	0
Field	_		TV_SBB2[6:0]					
Reset	_		OTP					
Access Type	-		Write, Read					

BITFIELD	BITS	DESCRIPTION	DECODE
TV_SBB2	6:0	SIMO Buck-Boost Channel 2 Target Output Voltage This 7-bit configuration is a linear transfer function that starts at 0.8V, ends at 5.5V, with 50mV increments.	0x00 = 0.800V 0x01 = 0.850V 0x02 = 0.900V 0x03 = 0.950V 0x04 = 1.000V 0x05 = 1.050V 0x06 = 1.100V 0x5C = 5.400V 0x5D = 5.450V 0x5E = 5.500V 0x5F to 0x7F = Reserved

#### CNFG SBB2 B (0x2E)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	OP_MODE	IP_SBI	B2[1:0]	ADE_SBB2		EN_SBB2[2:0]	
Reset	0b0	OTP	OTP		OTP		OTP	
Access Type	Write, Read	Write, Read	Write, Read		Write, Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	
OP_MODE	6	Operation Mode of SBB2	0 = Buck-boost mode 1 = Buck mode

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE	
IP_SBB2	5:4	SIMO Buck-Boost Channel 2 Peak Current Limit	0b00 = 1.000A 0b01 = 0.750A 0b10 = 0.500A 0b11 = 0.333A	
ADE_SBB2	3	SIMO Buck-Boost Channel 2 Active- Discharge Enable	0 = The active discharge function is disabled. When SBB2 is disabled, its discharge rate is a function of the output capacitance and the external load.  1 = The active discharge function is enabled. When SBB2 is disabled, an internal resistor (R <sub>AD SBB2</sub> ) is activated from SBB2 to PGND to help the output voltage discharge. The output voltage discharge rate is a function of the output capacitance, the external loading, and the internal R <sub>AD SBB2</sub> load.	
EN_SBB2	2:0	Enable control for SIMO buck-boost channel 2, selecting either an FPS slot the channel powers-up and powers-down in or whether the channel is forced on or off.	0b000 = FPS slot 0 0b001 = FPS slot 1 0b010 = FPS slot 2 0b011 = FPS slot 3 0b100 = Off irrespective of FPS 0b101 = Same as 0b100 0b110 = On irrespective of FPS 0b111 = Same as 0b110	

### CNFG SBB TOP (0x2F)

BIT	7	6	5	4	3	2	1	0
Field	ICHGIN_LI M_DEF	-	_	_	_	_	DRV_SBB[1:0]	
Reset	OTP	ı	_	-	-	_	0>	0
Access Type	Read Only	_	_	_	_	_	Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
ICHGIN_LIM _DEF	7	Changes how CNFG_CHG_B.ICHGIN_LIM is interpreted. This bit is for information only and cannot be changed.	See CNFG_CHG_B.ICHGIN_LIM for more details.
DRV_SBB	1:0	SIMO Buck-Boost (all channels) Drive Strength Trim. See the <i>Drive Strength</i> section for more details.	0b00 = Fastest transition time 0b01 = A little slower than 0b00 0b10 = A little slower than 0b01 0b11 = A little slower than 0b10

### CNFG LDO0 A (0x38)

BIT	7	6	5	4	3	2	1	0
Field	RSVD		TV_LDO0[6:0]					
Reset	0b0		OTP					
Access Type	Write, Read		Write, Read					

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
TV_LDO0	6:0	LDO Target Output Voltage This 7-bit configuration is a linear transfer function that starts at 0.8V and ends at 3.975V, with 25mV increments.	0x00 = 0.800V 0x01 = 0.825V 0x02 = 0.850V 0x03 = 0.875V 0x04 = 0.900V 0x05 = 0.925V 0x06 = 0.950V  0x7D = 3.925V 0x7E = 3.950V 0x7F = 3.975V

### CNFG\_LDO0\_B (0x39)

BIT	7	6	5	4	3	2	1	0
Field	_	_	_	LDO0_MD	ADE_LDO0		EN_LDO0[2:0]	
Reset	_	_	_	OTP	OTP		OTP	
Access Type	-	_	_	Write, Read	Write, Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
LDO0_MD	4	Operation Mode of LDO0	0 = Low dropout linear regulator (LDO) mode 1 = Load switch (LSW) mode
ADE_LDO0	3	LDO0 Active-Discharge Enable	0 = The active discharge function is disabled. When LDO0 is disabled, its discharge rate is a function of the output capacitance and the external load.  1 = The active discharge function is enabled. When LDO0 is disabled, an internal resistor (R <sub>AD LDO0</sub> ) is activated from LDO0 to GND to help the output voltage discharge. The output voltage discharge rate is a function of the output capacitance, the external loading, and the internal R <sub>AD LDO0</sub> load.
EN_LDO0	2:0	Enable Control for LDO0, selecting either an FPS slot the channel powers-up and powers-down in or whether the channel is forced on or off.	0b000 = FPS slot 0 0b001 = FPS slot 1 0b010 = FPS slot 2 0b011 = FPS slot 3 0b100 = Off irrespective of FPS 0b101 = Same as 0b100 0b110 = On irrespective of FPS 0b111 = Same as 0b110

### CNFG\_LDO1\_A (0x3A)

BIT	7	6	5	4	3	2	1	0
Field	RSVD	TV_LDO1[6:0]						
Reset	0b0		OTP					
Access Type	Write, Read		Write, Read					

BITFIELD	BITS	DESCRIPTION	DECODE
RSVD	7	Reserved. Unutilized bit. Write to 0. Reads are don't care.	

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

BITFIELD	BITS	DESCRIPTION	DECODE
TV_LDO1	6:0	LDO Target Output Voltage This 7-bit configuration is a linear transfer function that starts at 0.8V and ends at 3.975V, with 25mV increments.	0x00 = 0.800V 0x01 = 0.825V 0x02 = 0.850V 0x03 = 0.875V 0x04 = 0.900V 0x05 = 0.925V 0x06 = 0.950V  0x7D = 3.925V 0x7E = 3.950V 0x7F = 3.975V

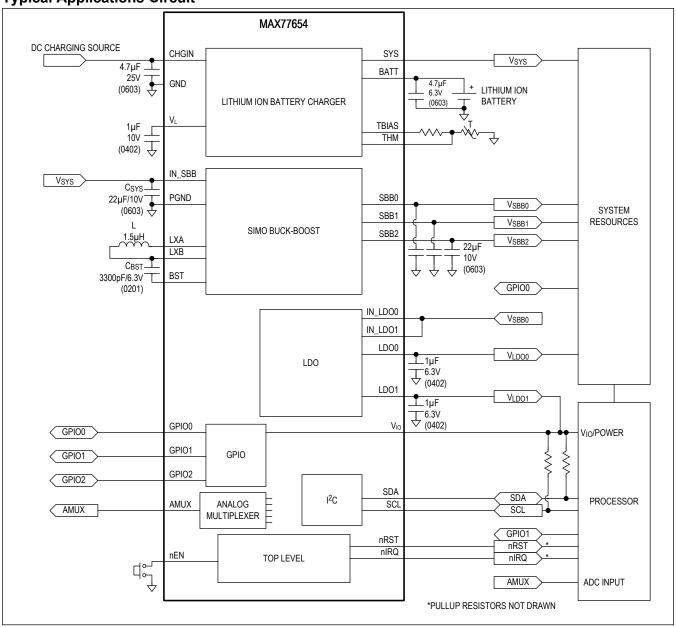
### CNFG\_LDO1\_B (0x3B)

BIT	7	6	5	4	3	2	1	0
Field	_	_	_	LDO1_MD	ADE_LDO1		EN_LDO1[2:0]	
Reset	_	_	_	OTP	OTP		OTP	
Access Type	-	_	_	Write, Read	Write, Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
LDO1_MD	4	Operation Mode of LDO1	0 = Low dropout linear regulator (LDO) mode 1 = Load switch (LSW) mode
ADE_LDO1	3	LDO1 Active-Discharge Enable	0 = The active discharge function is disabled. When LDO1 is disabled, its discharge rate is a function of the output capacitance and the external load.  1 = The active discharge function is enabled. When LDO1 is disabled, an internal resistor (R <sub>AD LDO1</sub> ) is activated from LDO1 to GND to help the output voltage discharge. The output voltage discharge rate is a function of the output capacitance, the external loading, and the internal R <sub>AD_LDO1</sub> load.
EN_LDO1	2:0	Enable control for LDO1, selecting either an FPS slot the channel powers-up and powers-down in or whether the channel is forced on or off.	0b000 = FPS slot 0 0b001 = FPS slot 1 0b010 = FPS slot 2 0b011 = FPS slot 3 0b100 = Off irrespective of FPS 0b101 = Same as 0b100 0b110 = On irrespective of FPS 0b111 = Same as 0b110

### **Typical Application Circuits**

### **Typical Applications Circuit**



# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE	OPTIONS
MAX77654ENV+T*	-40°C to +85°C	30 WLP	
MAX77654AENV+T	-40°C to +85°C	30 WLP	Table 3
MAX77654BENV+T	-40°C to +85°C	30 WLP	Table 3
MAX77654CENV+T**	-40°C to +85°C	30 WLP	Table 3
MAX77654DENV+T	-40°C to +85°C	30 WLP	Table 3
MAX77654FENV+T	-40°C to +85°C	30 WLP	Table 3
MAX77654MENV+T	-40°C to +85°C	30 WLP	Table 3
MAX77654NENV+T	-40°C to +85°C	30 WLP	Table 3
MAX77654ENVN+T*	-40°C to +85°C	30 WLP	
MAX77654AENVN+T	-40°C to +85°C	30 WLP	Table 3

<sup>+</sup>Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

<sup>\*</sup>Custom samples only. Not for production or stock. Contact factory for more information.

<sup>\*\*</sup>Future product—<u>contact factory</u> for availability.

# Ultra-Low Power PMIC Featuring Single-Inductor, 3-Output Buck-Boost, 2-LDOs, Power-Path Charger for Small Li+, and Ship Mode

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	
0	5/19	Initial release	_
1	7/19	Updated part decode in Table 3 and Ordering Information table	34, 35, 114
2	2/20	Fixed typographical errors, updated <i>Absolute Maximum Ratings, Electrical Characteristics</i> tables, <i>Typical Operating Characteristics</i> 6, 32, 42, 45, <i>Pin Description</i> table, Table 3, <i>Support Material</i> section, Figure 2, <i>Detailed Description—Global Resources</i> section, Figure 3, <i>nEN Internal Pullup Resistors to V<sub>CCINT</sub></i> section, Figure 4, <i>SIMO Features and Benefits</i> section, <i>SIMO Buck Mode</i> section, Table 15, <i>Inductor Selection</i> section, Figures 21, 22, and 23, <i>Summary</i> section, and <i>Ordering Information</i> table	9–14, 19, 21–23, 26, 27, 30, 31, 34–39, 66, 68–70, 72–74, 76, 81, 113
3	7/20	Removed solution size estimate from Benefits and Features section	1
4	7/20	Updated Table 3	34, 35
5	9/20	Updated Figure 7, Figure 8, the SIMO Soft-Start section, and Figures 34, 35, and 36	45, 46, 68, 89–91
6	8/21	Updated Table 3, Register Details section, and Ordering Information table	
7	8/21	Updated Ordering Information table	118
8	9/21	Updated Ordering Information table	118

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